

# A New Twist on Topology: The Rise of “Moiré Materials”

Sid Parameswaran



Saturday Morning of Theoretical Physics, February 8, 2025

# The story so far...



Topology has profoundly changed  
our view of phases of matter

Topology has led us to ideas such as “anyons”,  
which might even be *useful* for quantum computing\*



\* not investment advice

A lot of this work — especially the theory — was done already in the 1990s and 2000s

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(why is there so much *more* activity in this area than in **2015**?)

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I'll explain recent progress in terms of 3 key ingredients

**topology**

**correlations**

**tunability**



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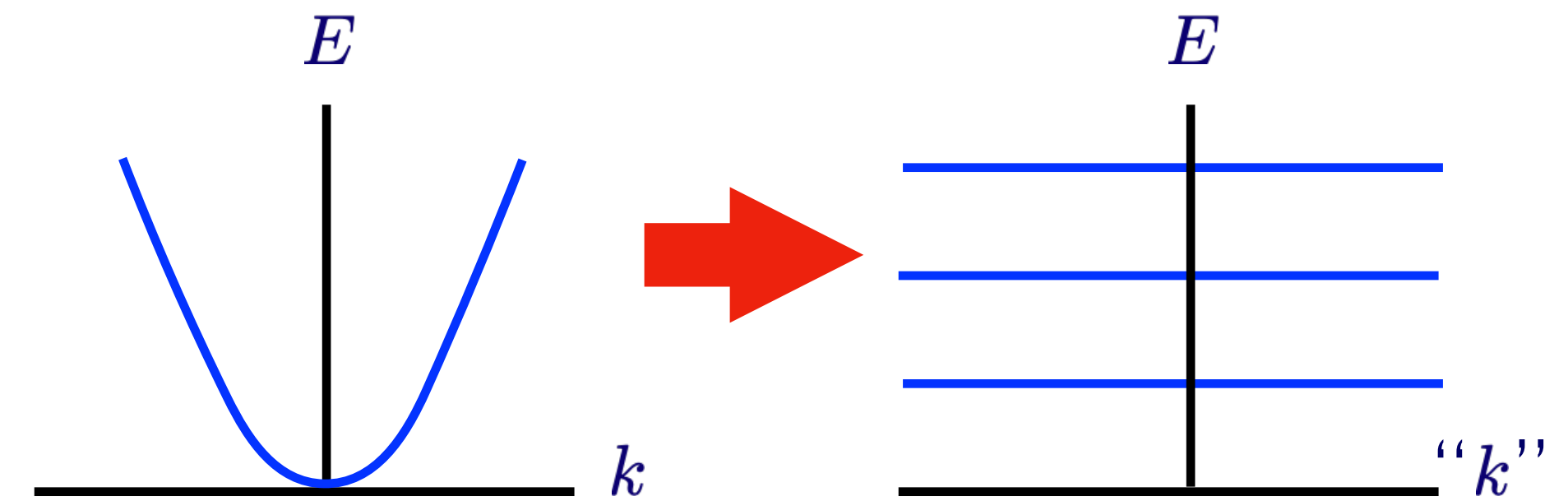
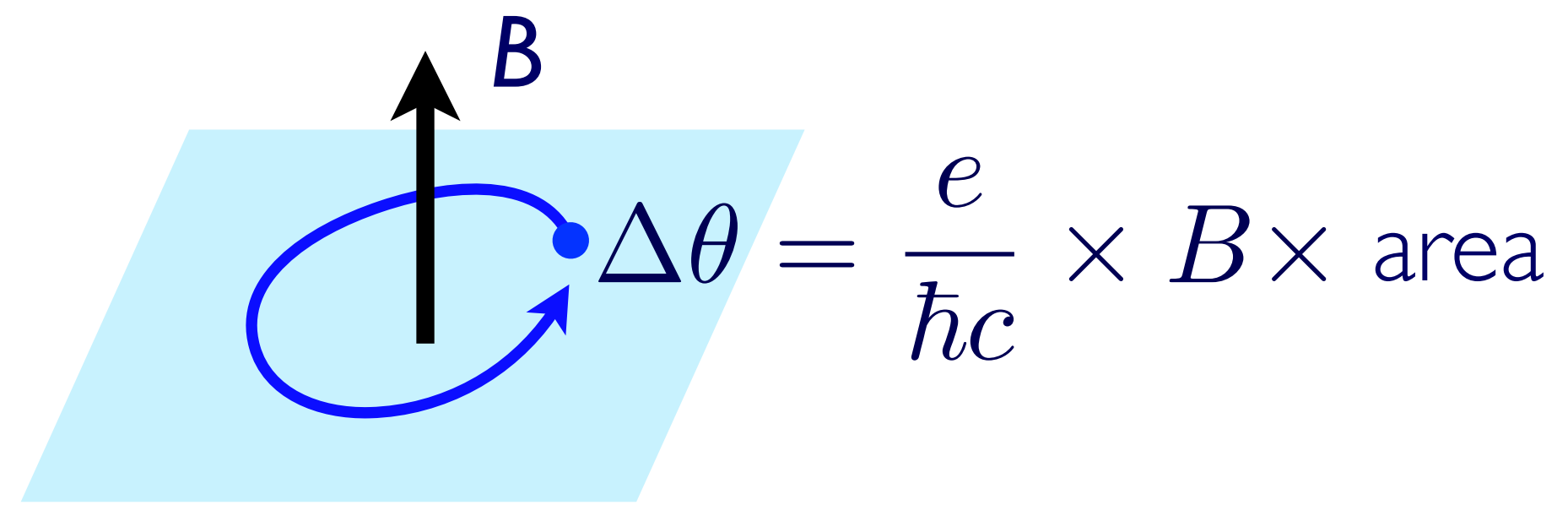
**correlations**

**tunability**

- How does the “original” quantum Hall effect embody these 3 ingredients?
  - Why are they challenging to achieve in other systems?
    - How did physicists manage to do this?

# 2D Electrons in a Magnetic Field

- Circular orbit + Aharonov-Bohm phase — kinetic energy frozen into flat “Landau levels”



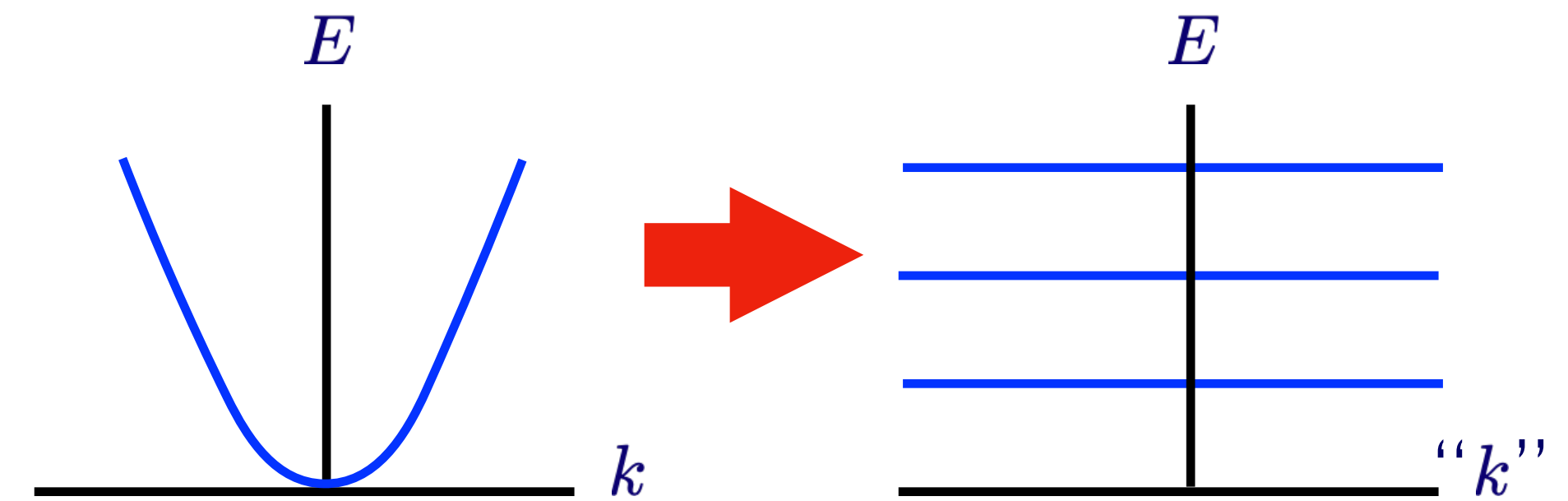
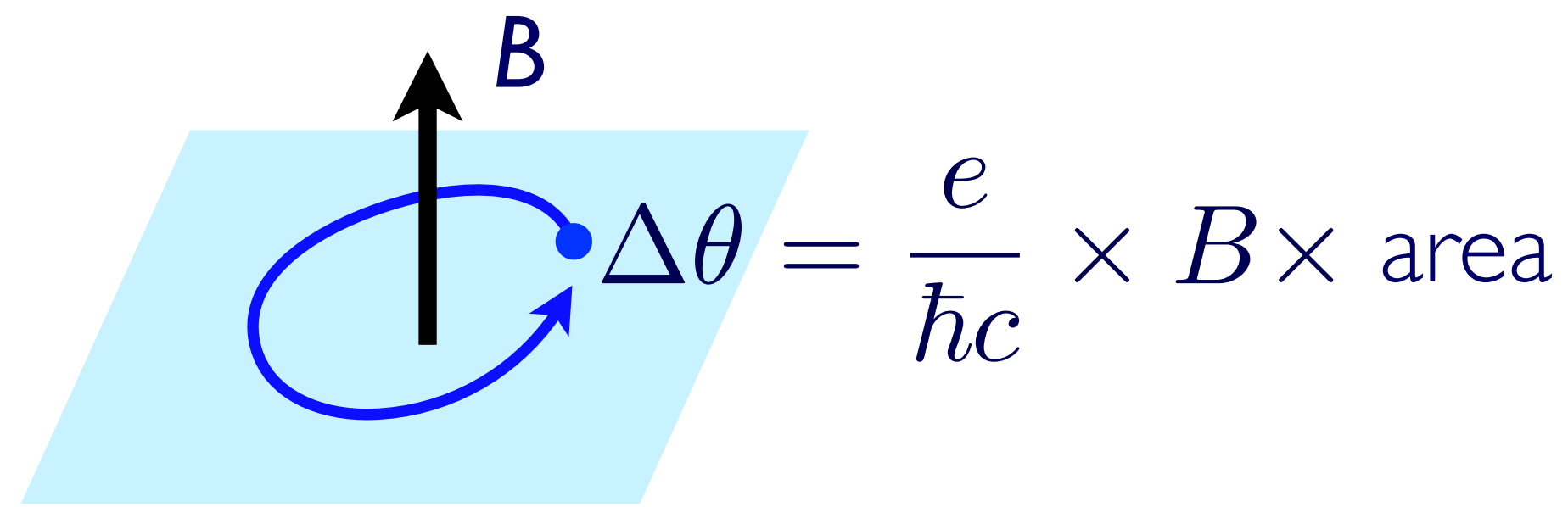
$\Delta\theta = 2\pi$  defines new “unit cell”  $\sim$  area occupied by single *quantum of flux*  $\Phi_0 = hc/e$

also defines *magnetic length*

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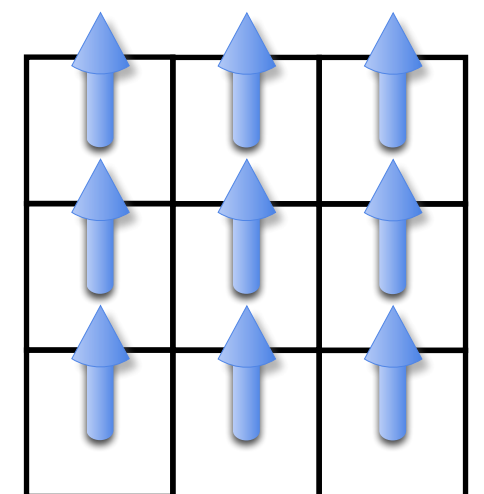
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Sample with magnetic field  $B$  and area  $A$  has  $N_\Phi = BA/\Phi_0$  “unit cells”

Each Landau level: 1 electronic state per “unit cell”  $\implies$  extensive degeneracy



# Integer vs. Fractional Quantum Hall Effect

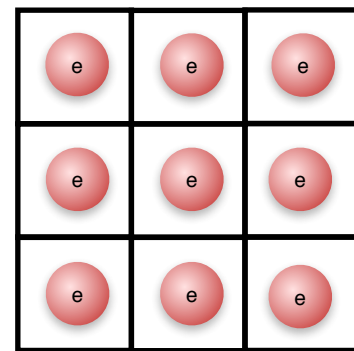
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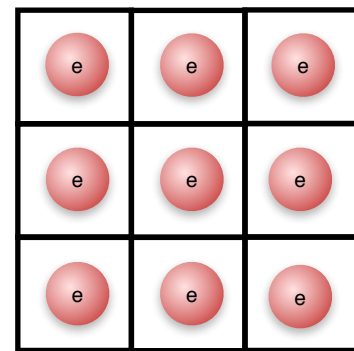




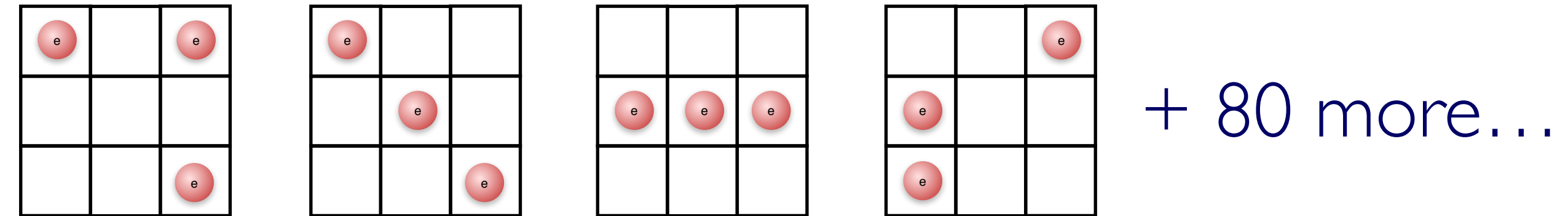
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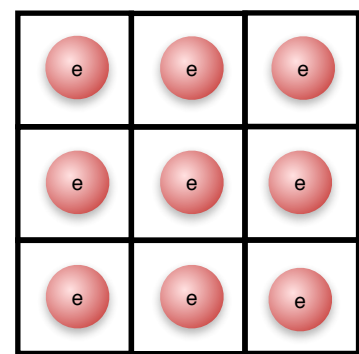
**fractional  $\nu$ :** interactions "pick" ground state (degenerate perturbation theory!)



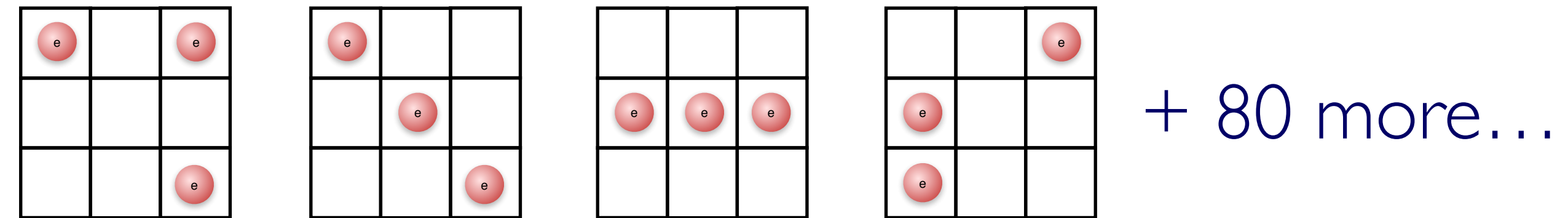
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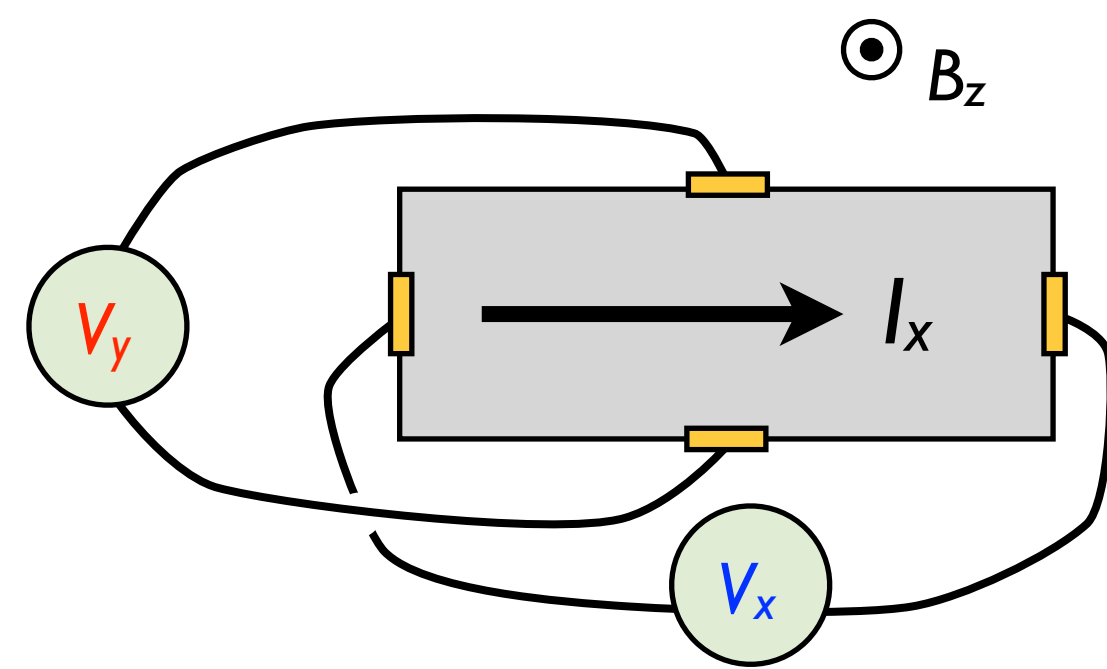
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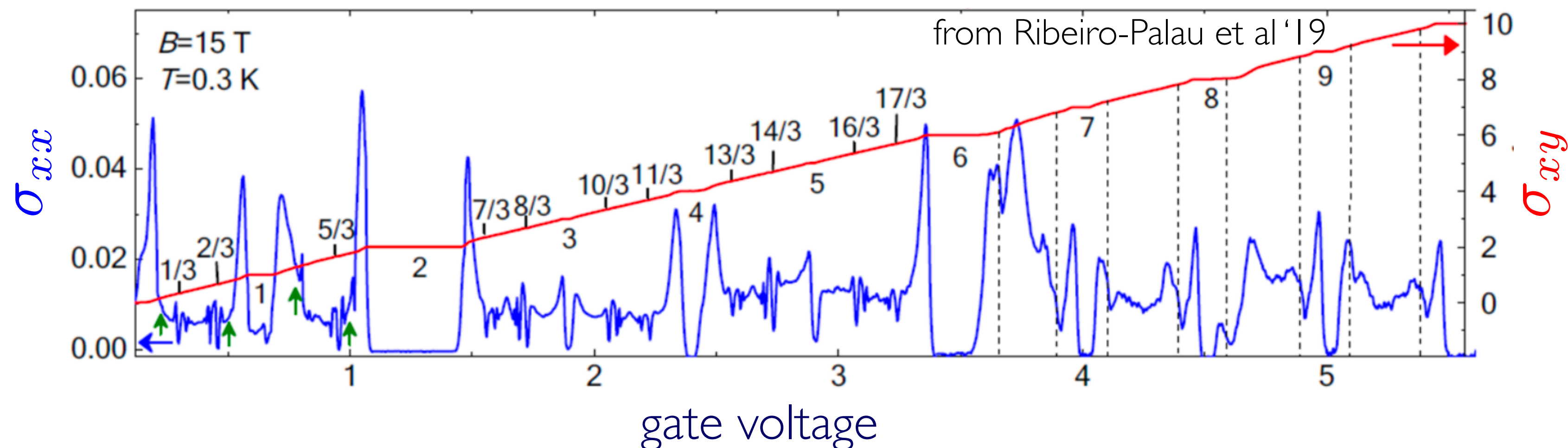
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- **Quantum Hall Effect:** insulators w/ quantized response for integer or fractional  $\nu$



(cf Shivaji Sondhi's Talk)

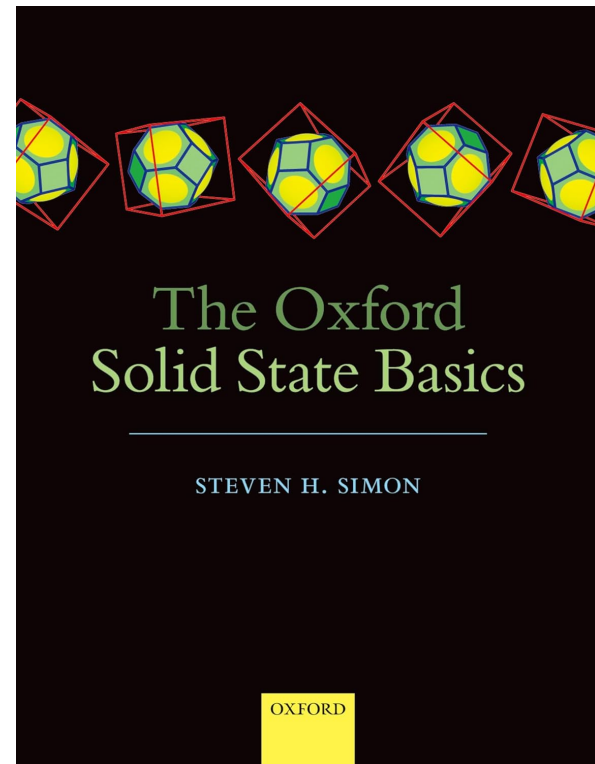


Ingredient #1: Topology

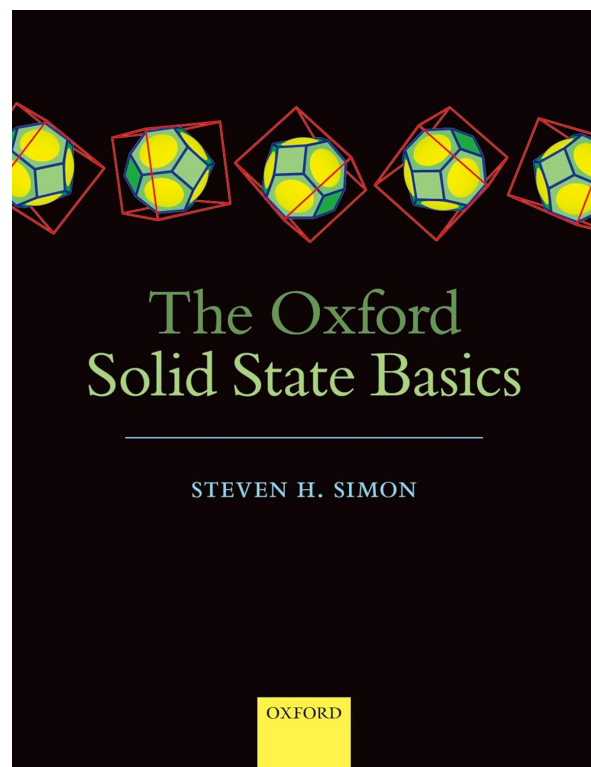
# Back to B6!

Electrons in solids: Schrödinger equation in periodic potential

$$\left( \frac{\mathbf{p}^2}{2M} + V(\mathbf{r}) \right) \psi(\mathbf{r}) = E\psi(\mathbf{r}) \quad V(\mathbf{r} + \mathbf{R}) = V(\mathbf{r}) \quad \mathbf{R} \in \text{lattice}$$



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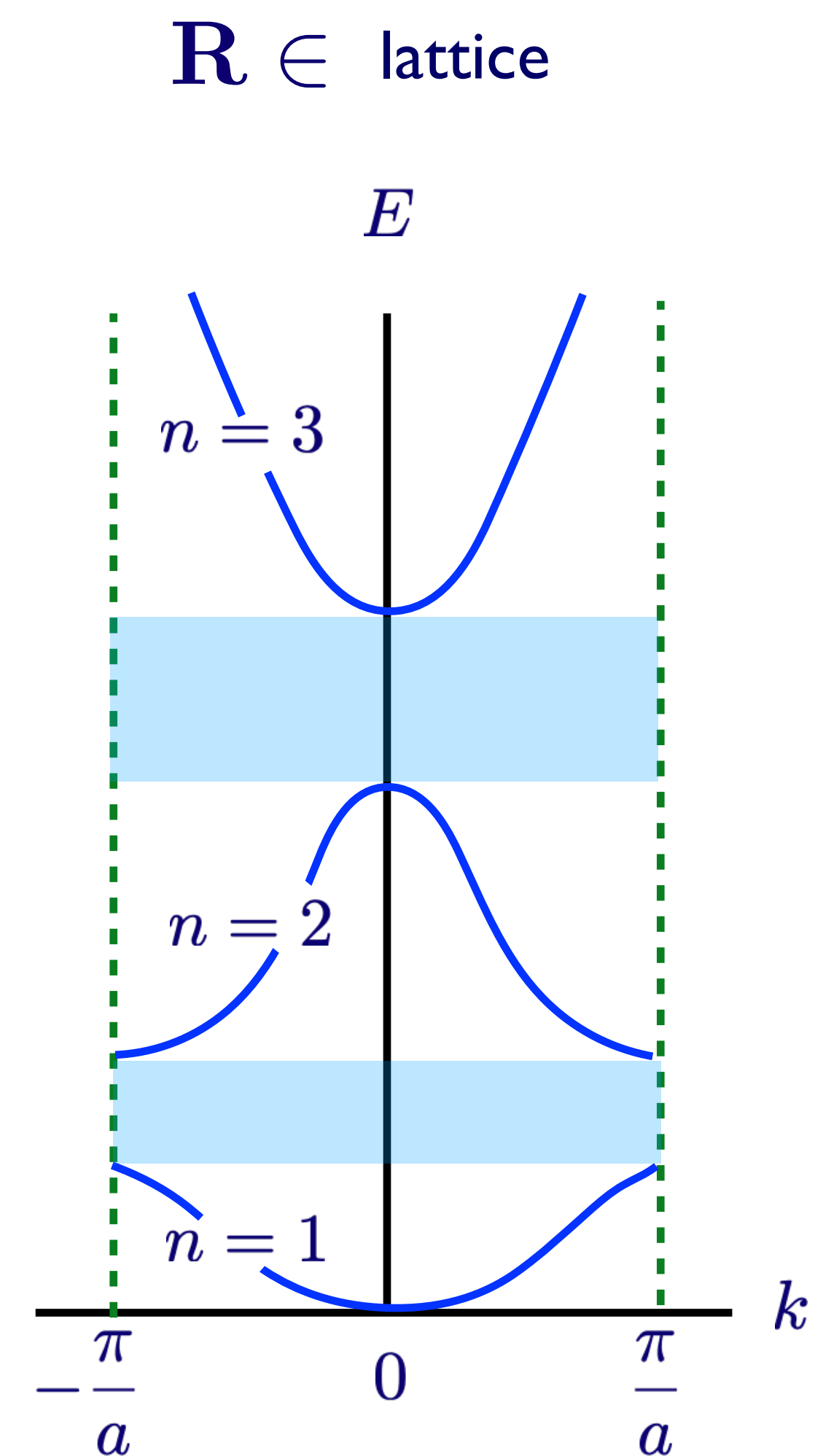
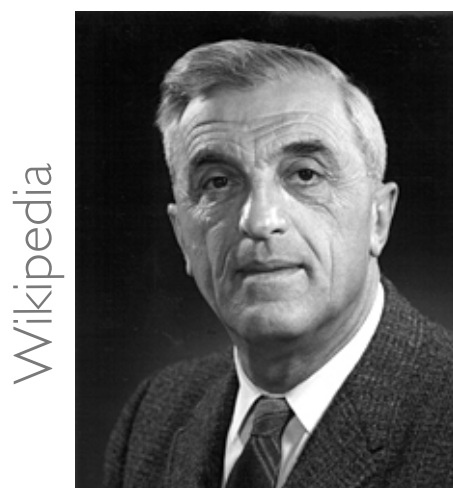
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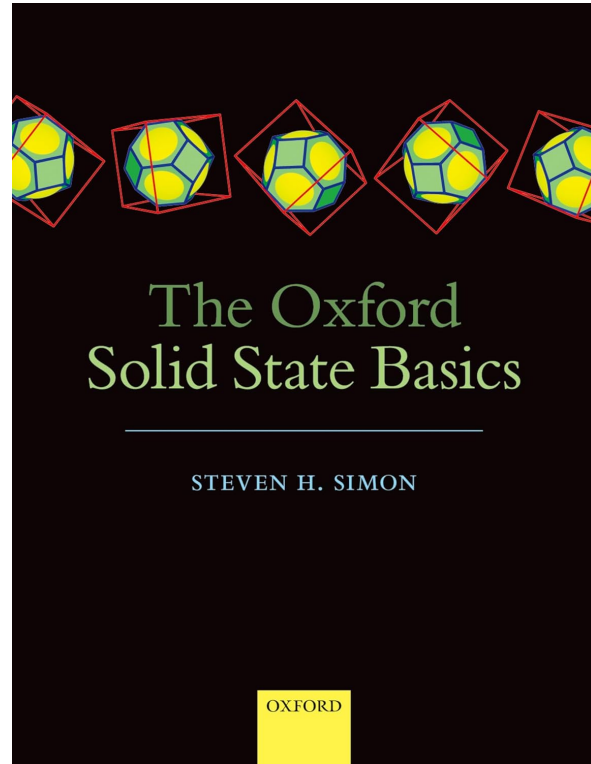
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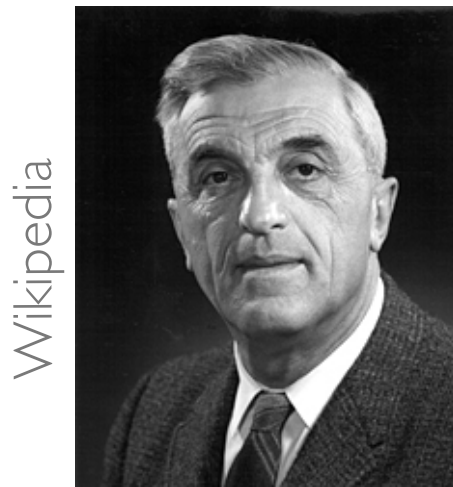
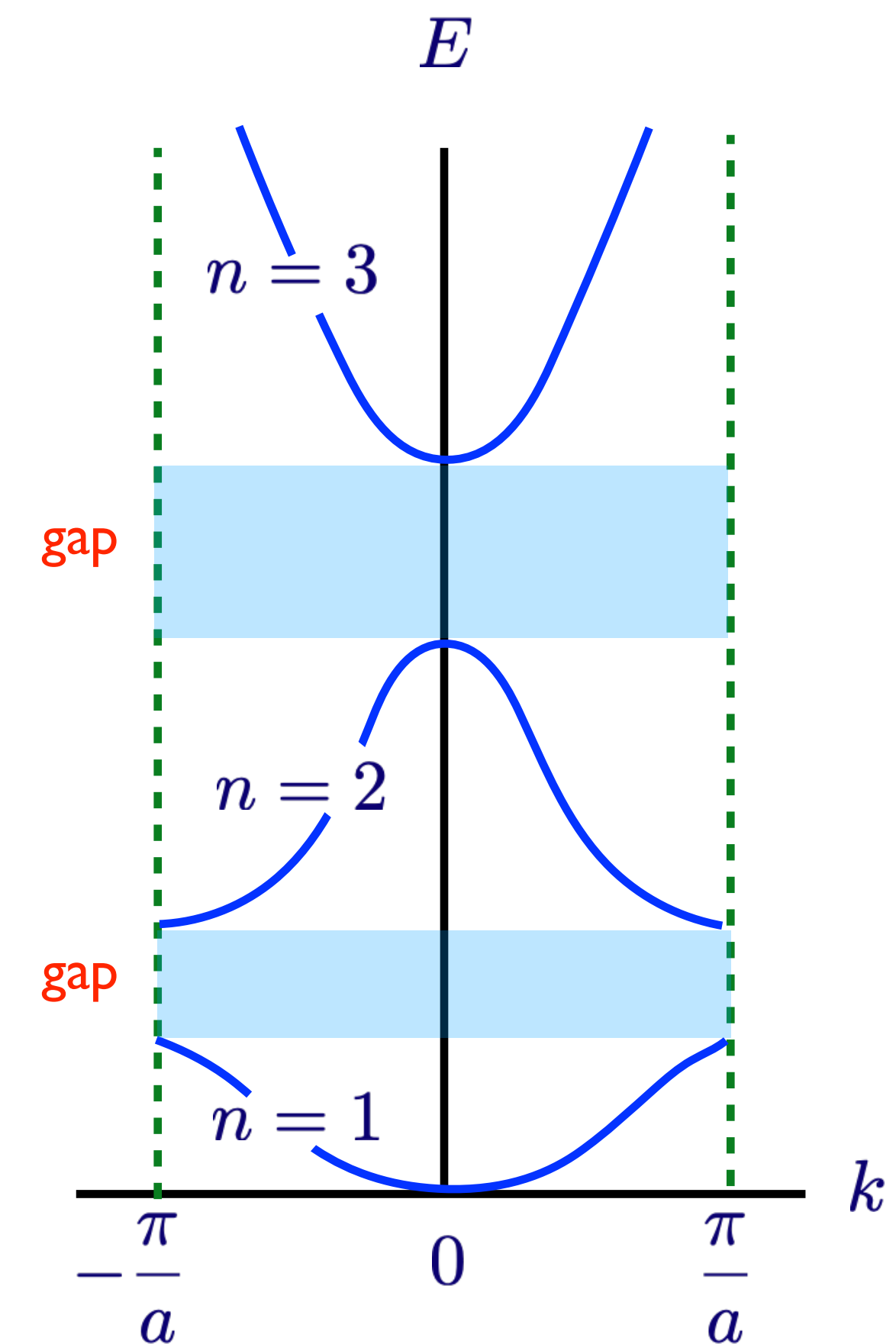
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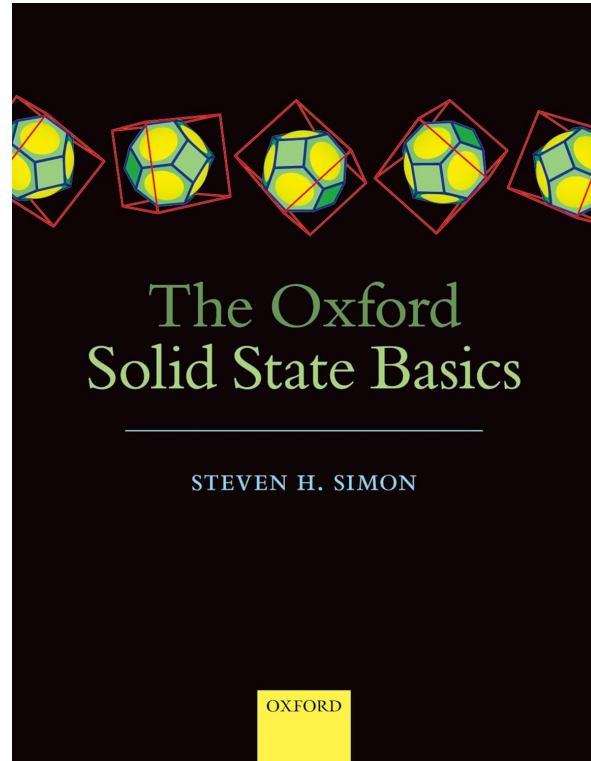
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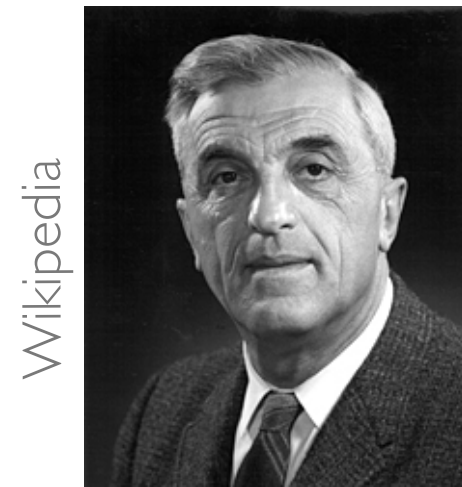
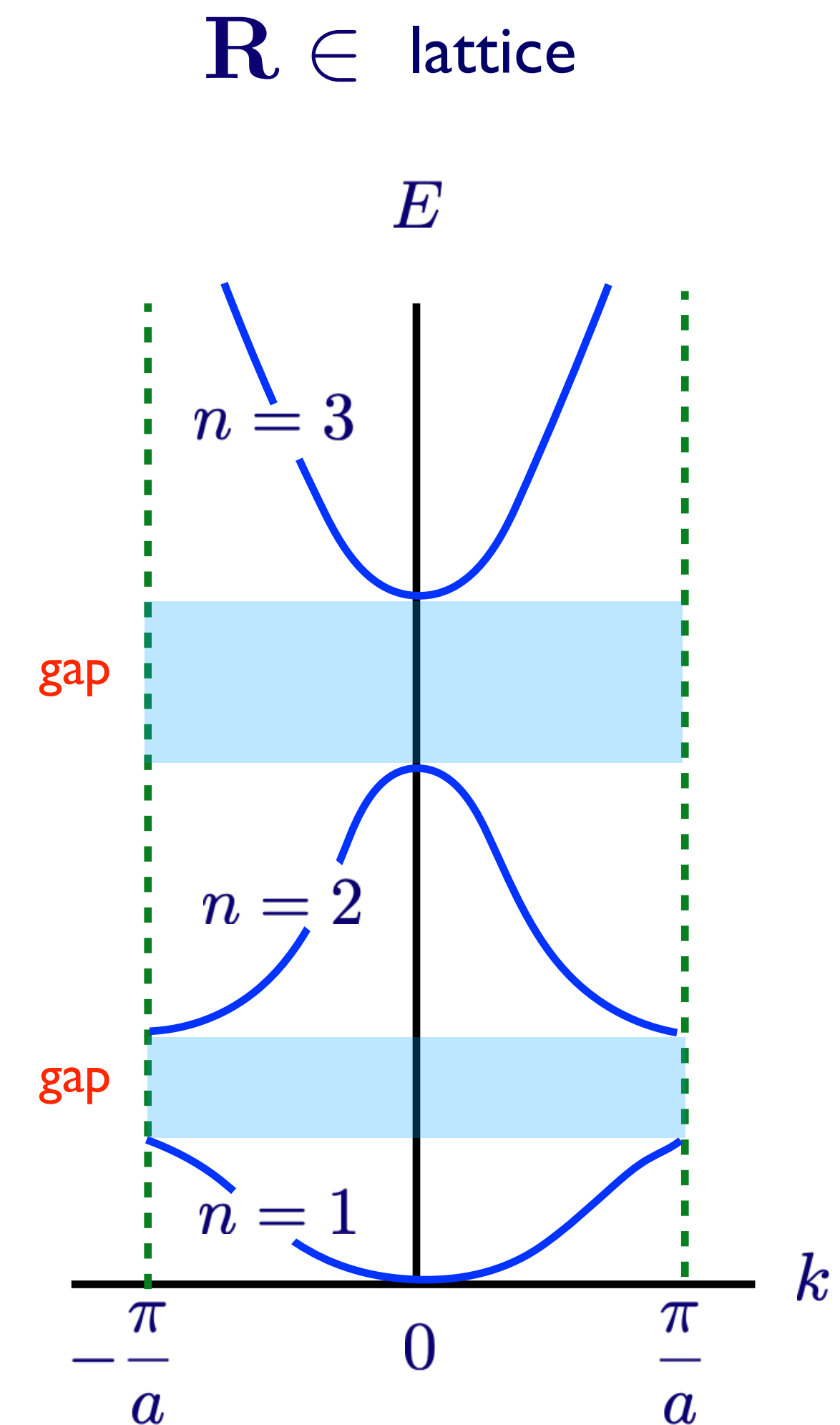
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- energy levels : **bands** w/ discrete label  $n$  + “gaps”
  - 1 band per orbital in the unit cell
- **crystal momentum**  $k$  is periodic
  - e.g. in 1D,  $k \equiv k + 2\pi/a$



# Topology in Bloch Bands

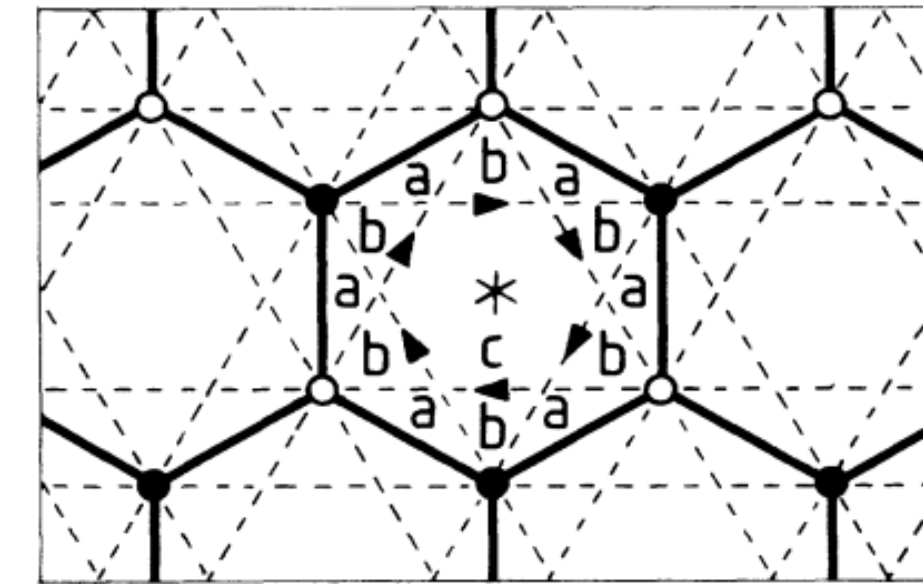
As we learned in Shivaji's talk, Bloch bands can also have topology ("Chern insulators")

**Chern bands** —  $B=0$  lattice versions of Landau levels

topological index: integer "Chern number"  $C$

filled Chern band: quantized Hall response

$$\sigma_{xy} = C \times \frac{e^2}{h}$$



Nobel Foundation

[Haldane PRL '88; Thouless et al PRL '82]

Wolf Foundation



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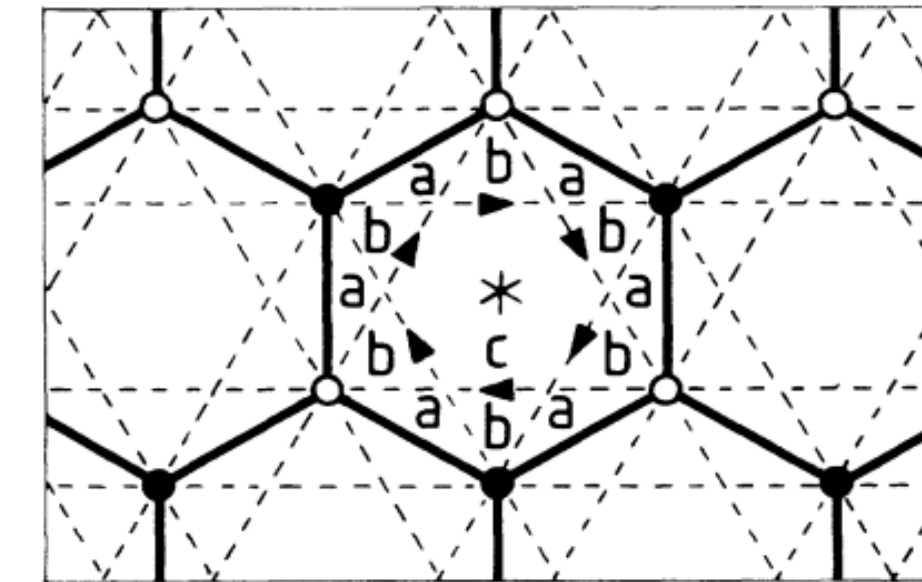
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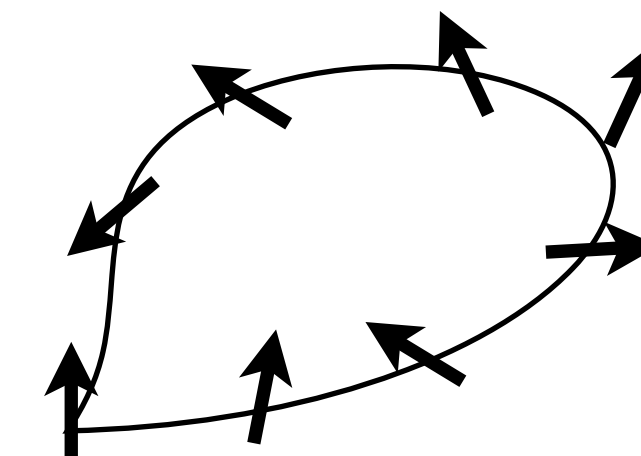
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**Where does the topology come from?**

**Berry's Phase** ~ "winding" of electron wavefunction as it moves

- cf Aharonov-Bohm phase in magnetic field
- often arises in systems w/ strong spin-orbit coupling



Wolf Foundation

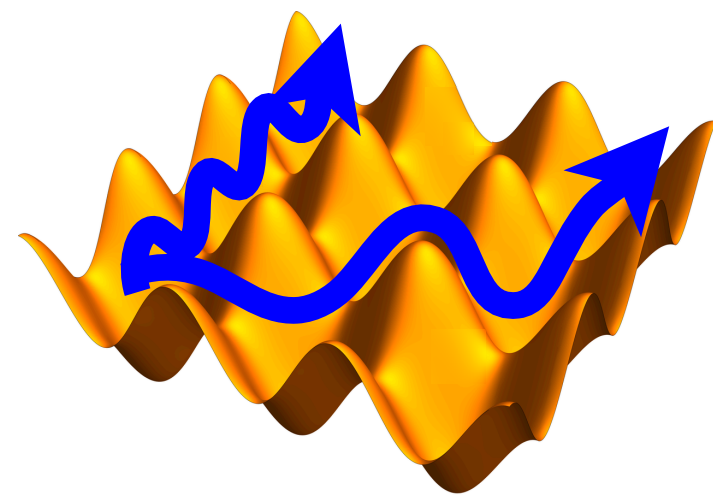
## Ingredient #2: Correlations



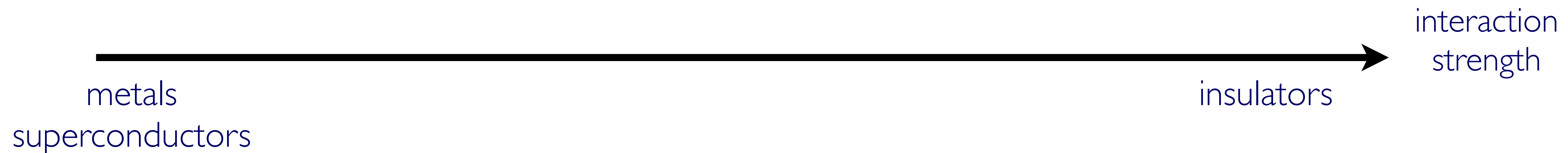
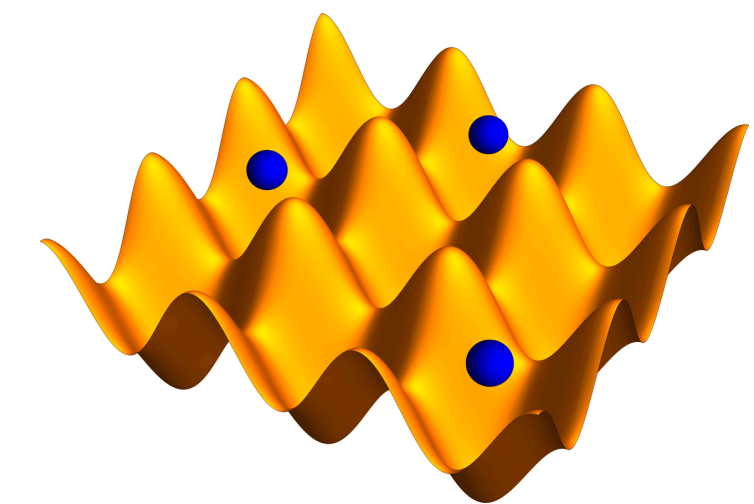
# What do we mean by “correlations”?

competition between kinetic energy & interactions decides the fate of matter

more itinerant  
(wave-like)



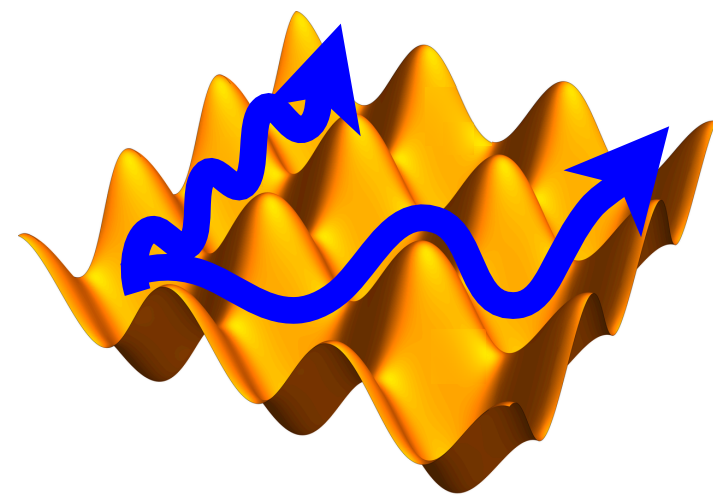
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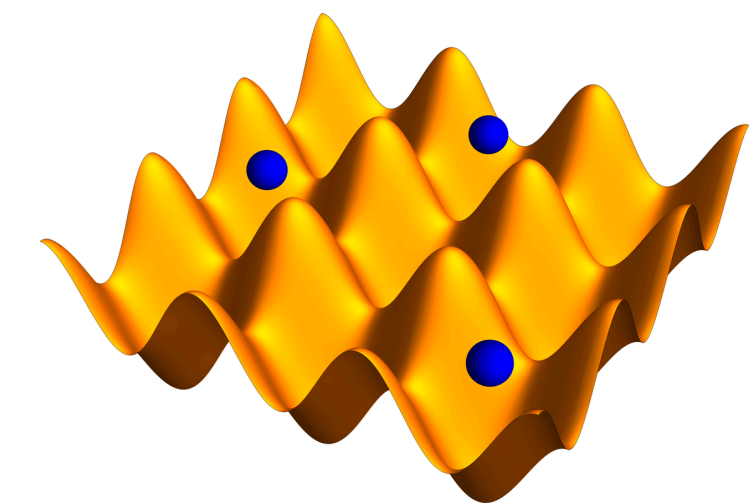
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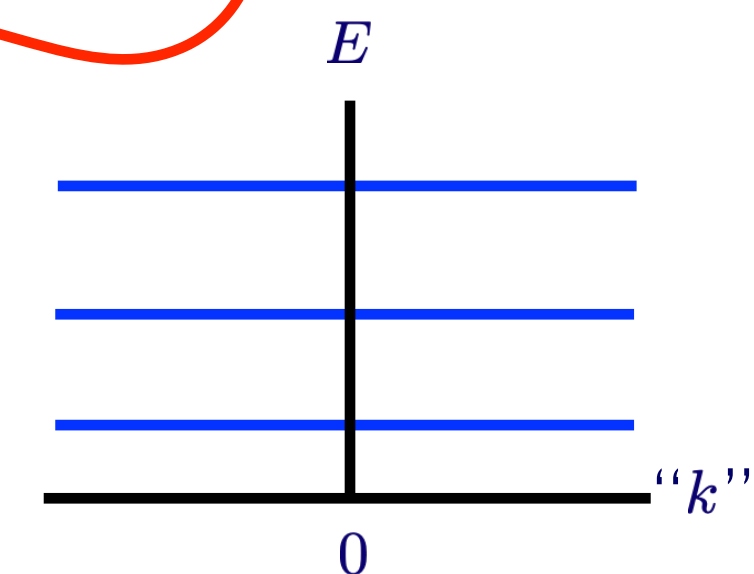


metals  
superconductors

insulators

interaction  
strength

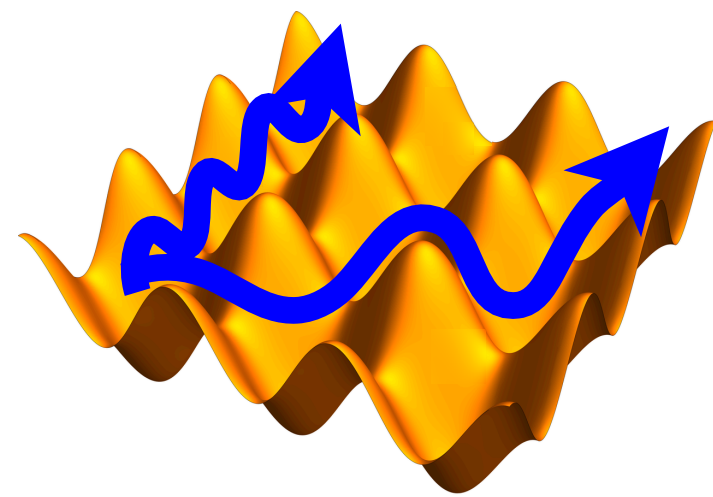
Landau levels: zero kinetic energy  
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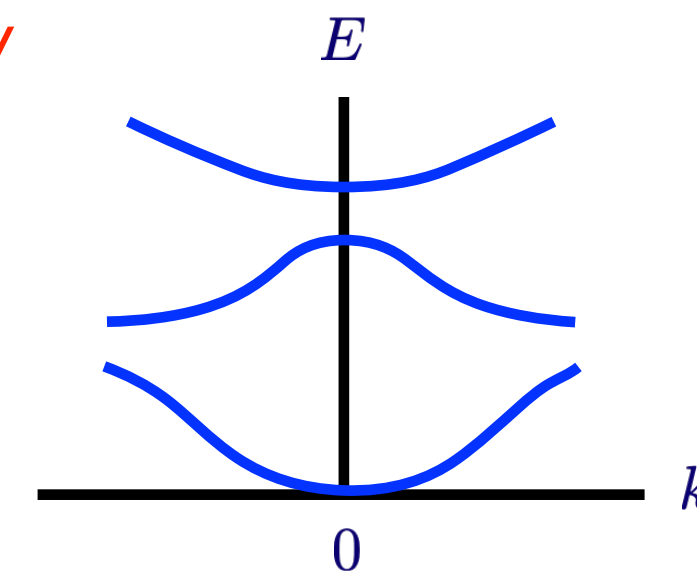
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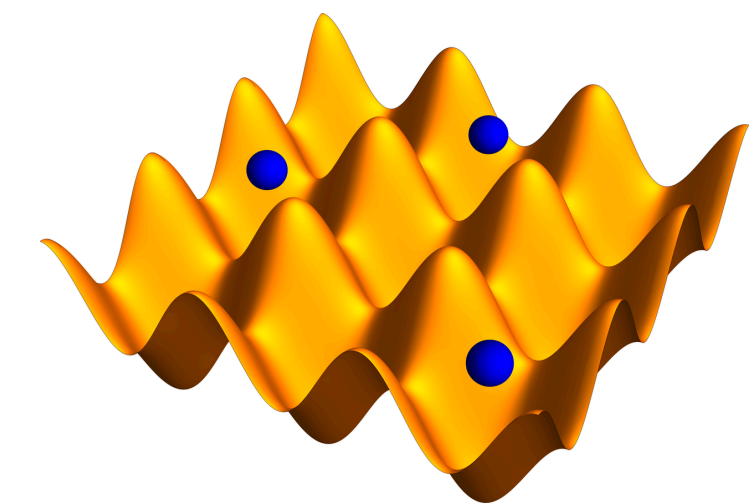
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Bloch bands usually  
have non-zero  
kinetic energy:  
“intermediate  
coupling”



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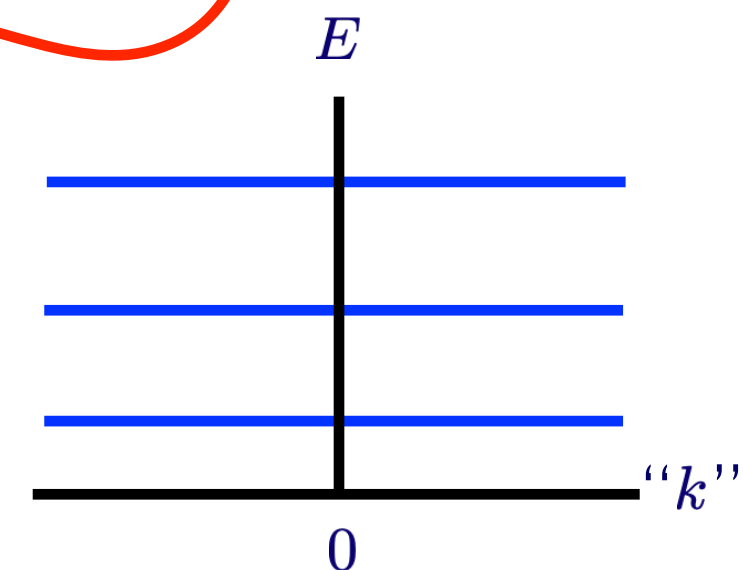


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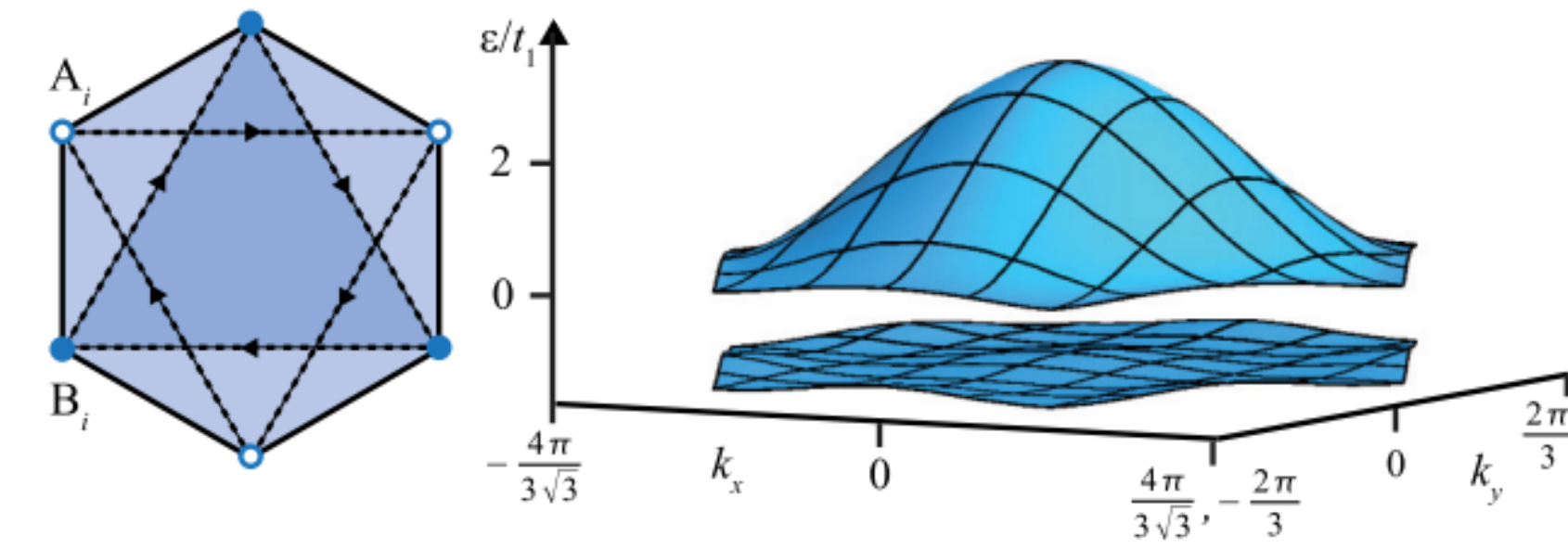
# “Fractional Chern Insulators”

“Fractional Chern insulators”: lattice analog of fractional QHE

[Tang et al PRL '11; Neupert et al PRL '11; Sun et al PRL '11]

“flatten” dispersion of Chern bands to enhance correlations (easy in theory)

Under right conditions, interactions  $\approx$  those in a Landau level



[Qi, PRL '11; SP, Roy, Sondhi PRB '12]

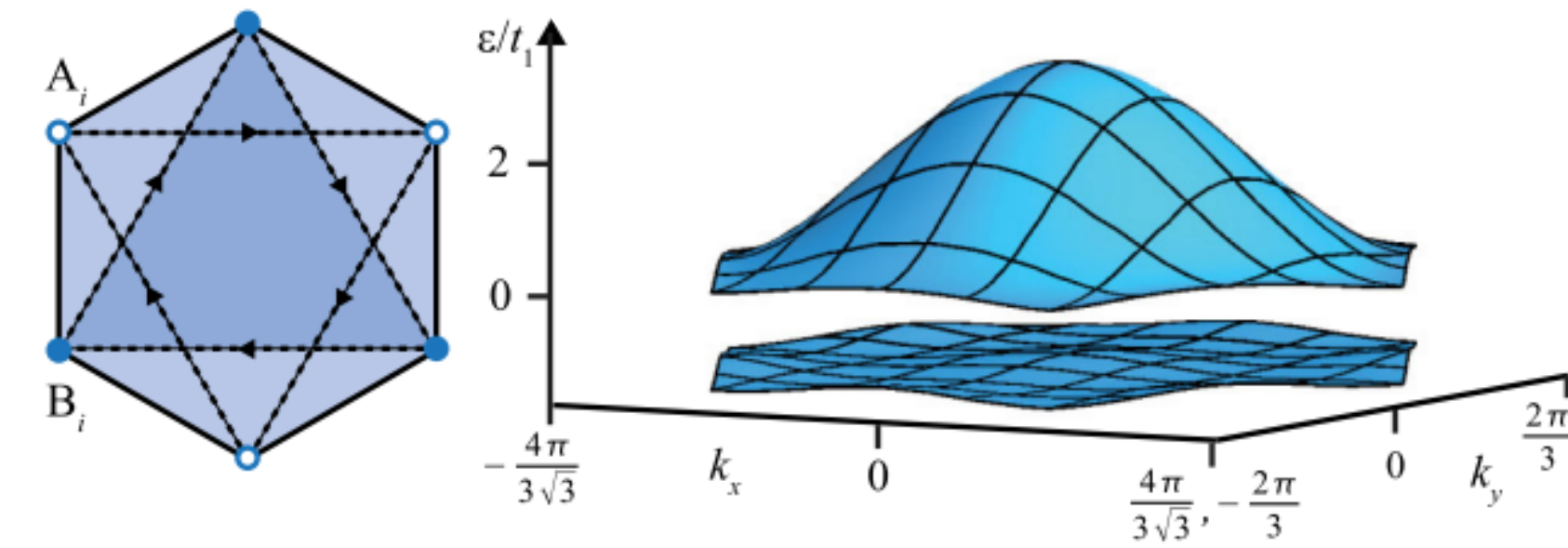


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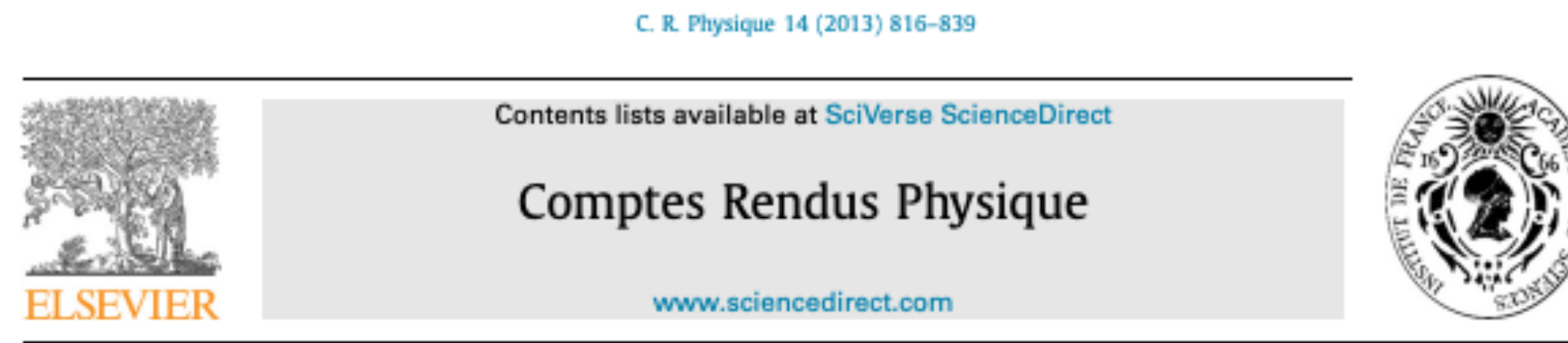
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Lots of subsequent theory... enough for a review article already in 2013



Rahul Roy  
Oxford Postdoc  
2009-11



Topological insulators/Isolants topologiques

Fractional quantum Hall physics in topological flat bands

*Physique de l'effet Hall quantique fractionnaire dans des bandes plates topologiques*

Siddharth A. Parameswaran<sup>a,\*</sup>, Rahul Roy<sup>b</sup>, Shivaji L. Sondhi<sup>c</sup>

... but “flattening” bands is not easy in experiments!



Ingredient #3: Tunability

# What do we need to tune?

---

Ideally... **lots** of things!

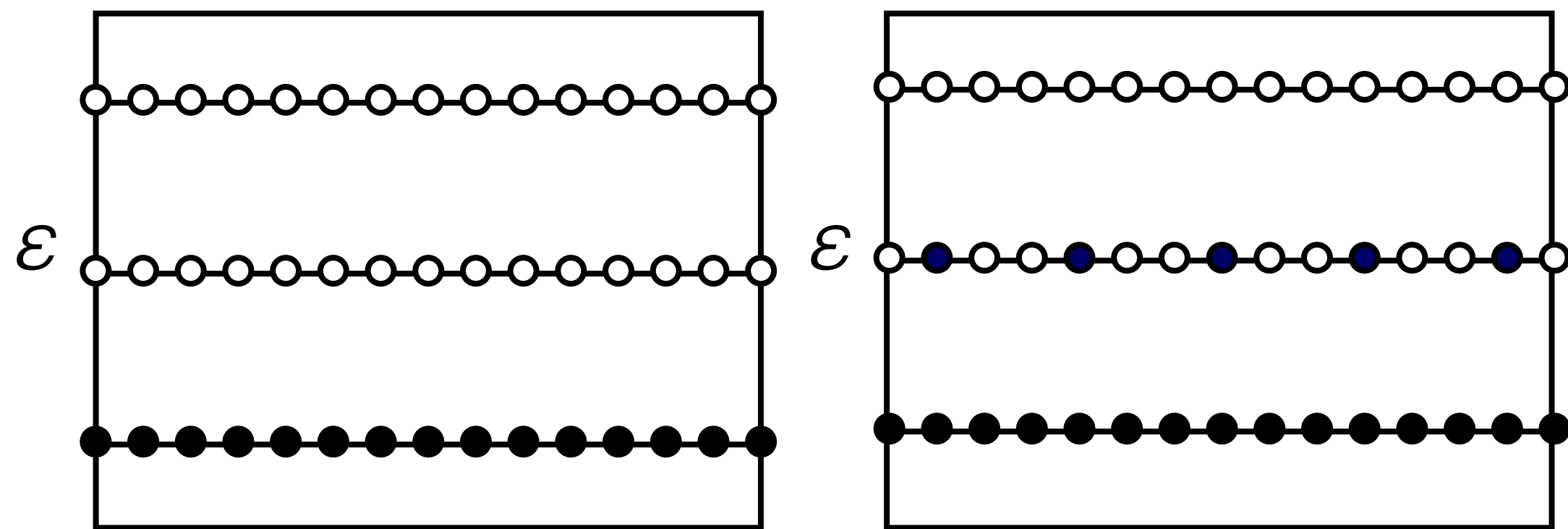
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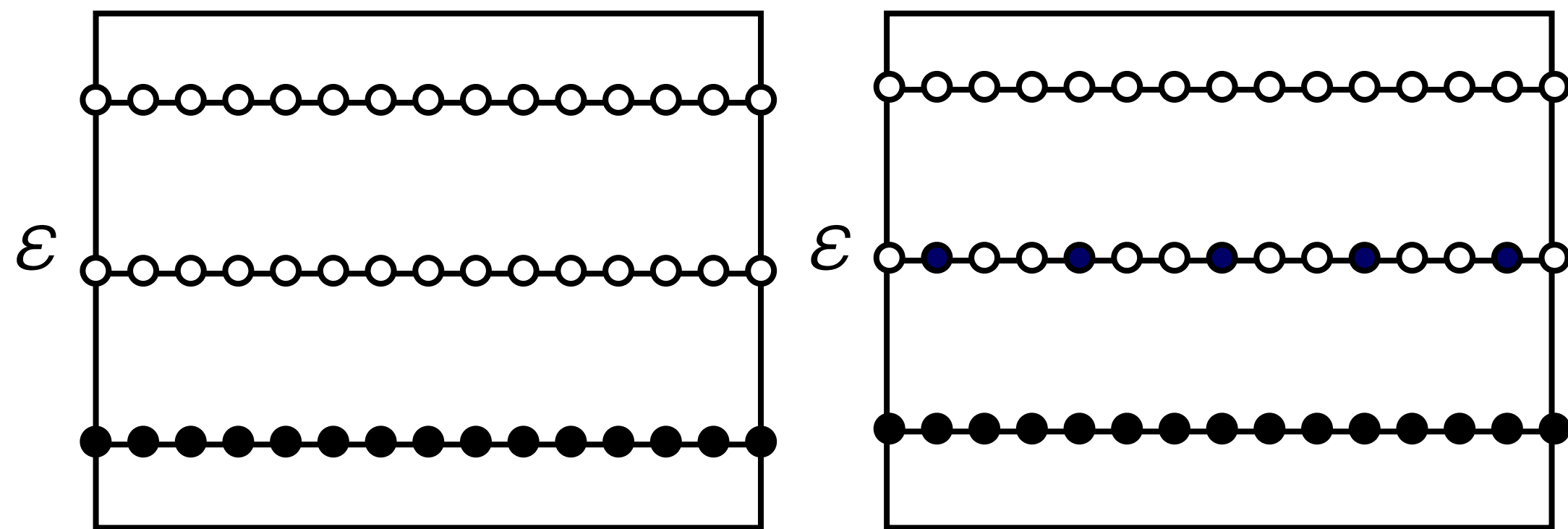
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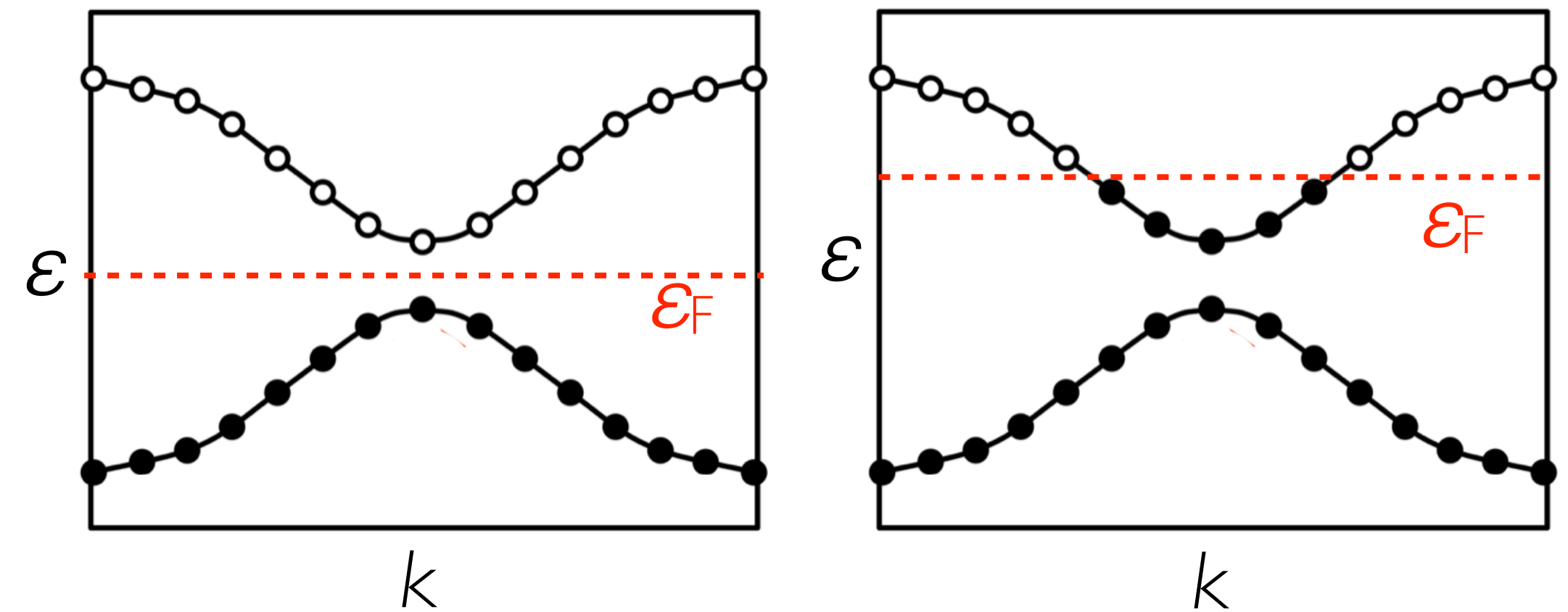
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## Bloch Bands



band insulator

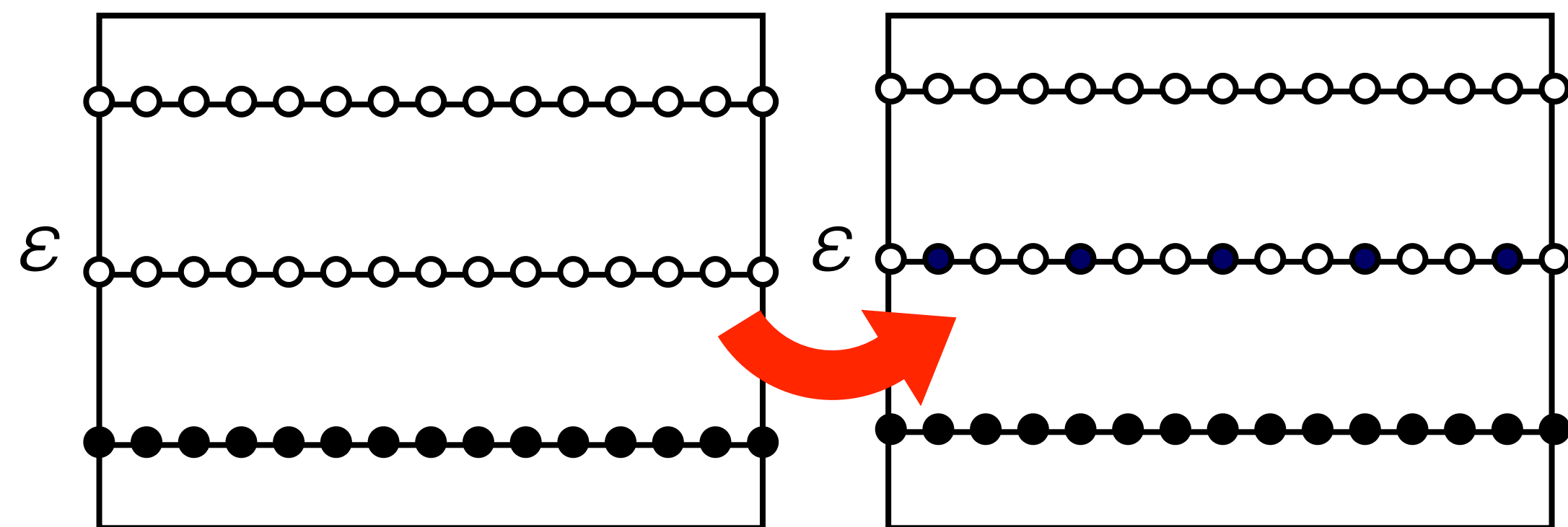
metal  
"Mott" insulator w/  
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Chern/fractional Chern insulator if  $C \neq 0$

# What do we need to tune?

By tuning density, “integer” states  $\rightarrow$  “fractional” states  
(no correlations needed)  $\rightarrow$  (correlations essential)

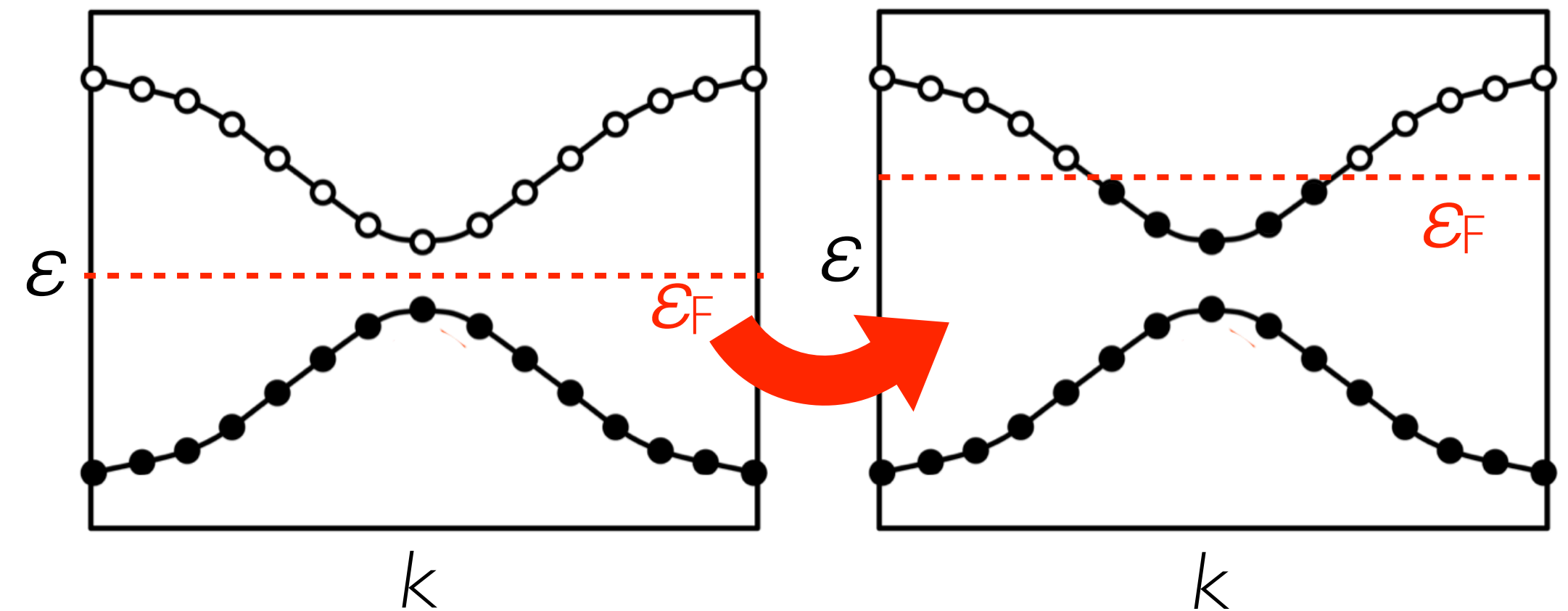
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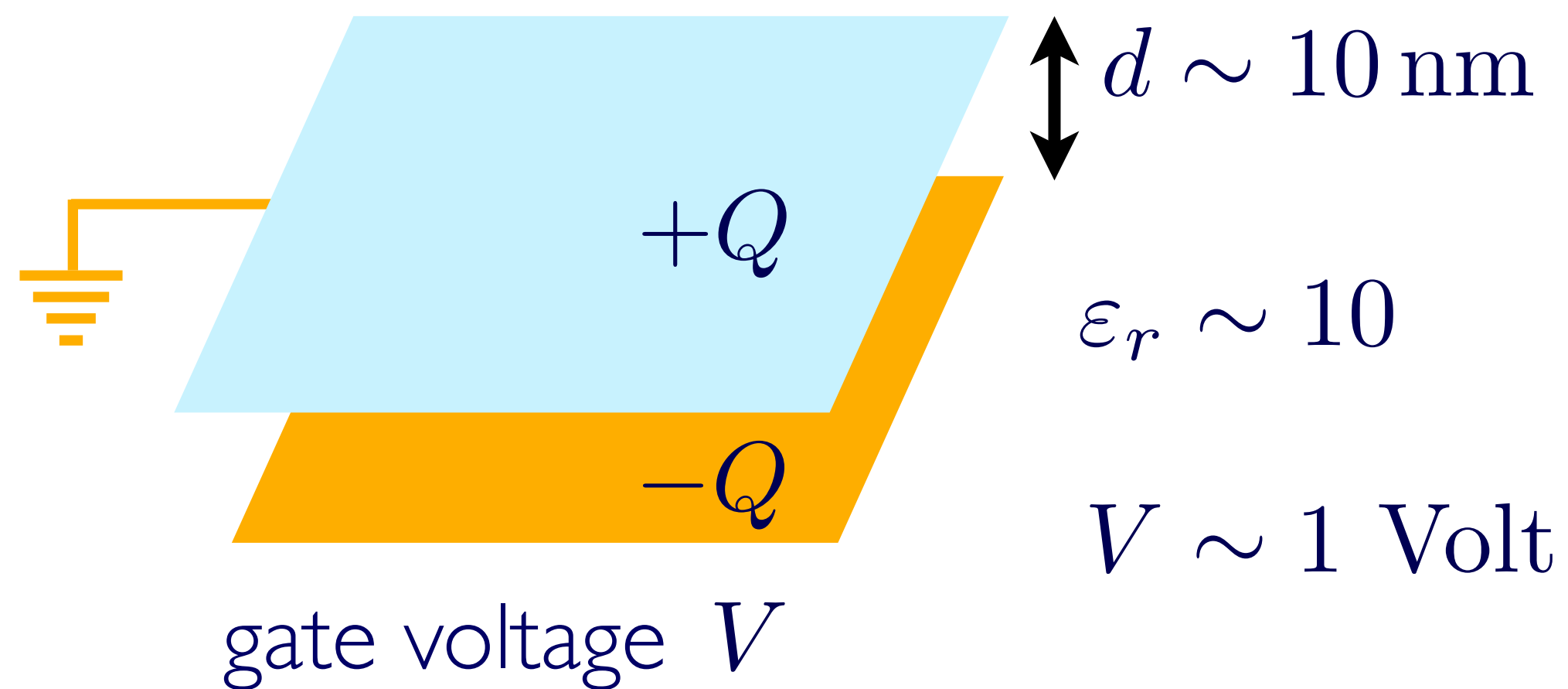
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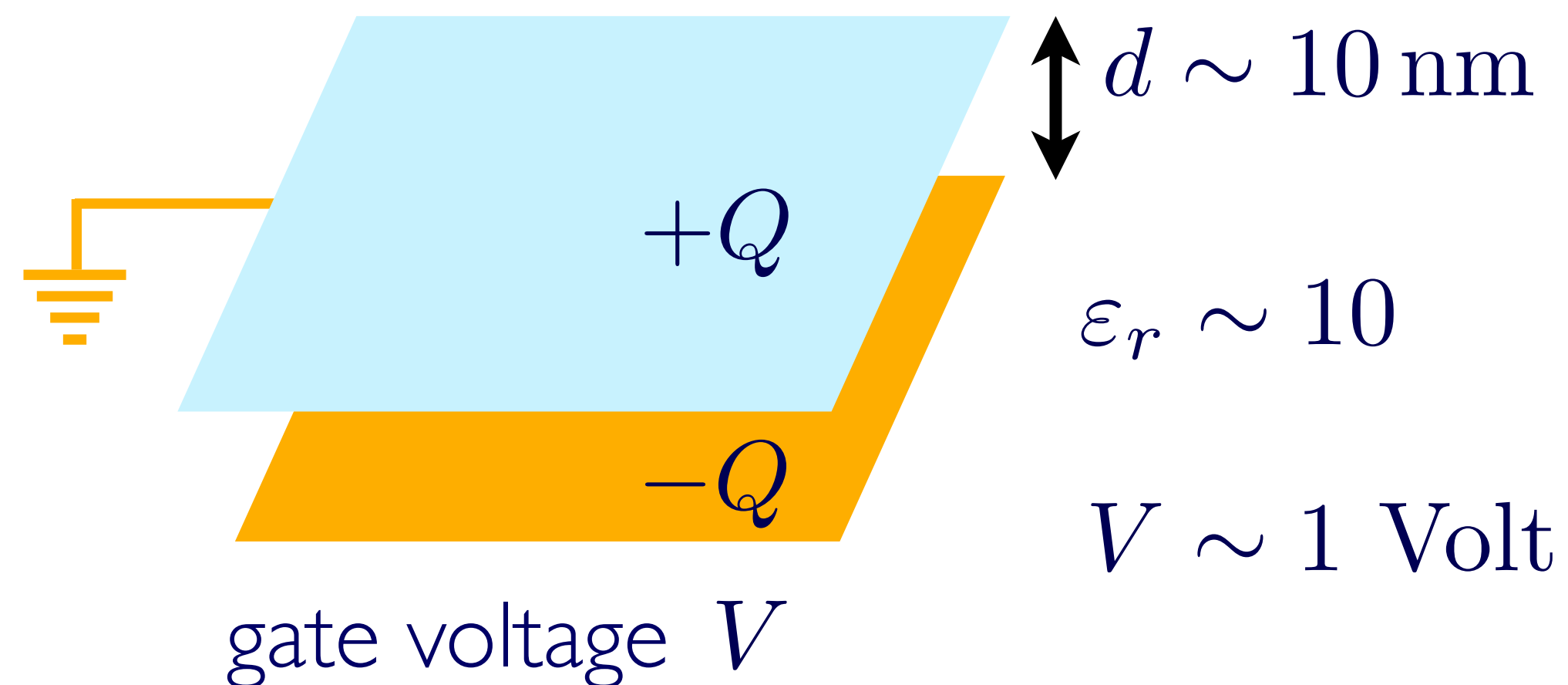
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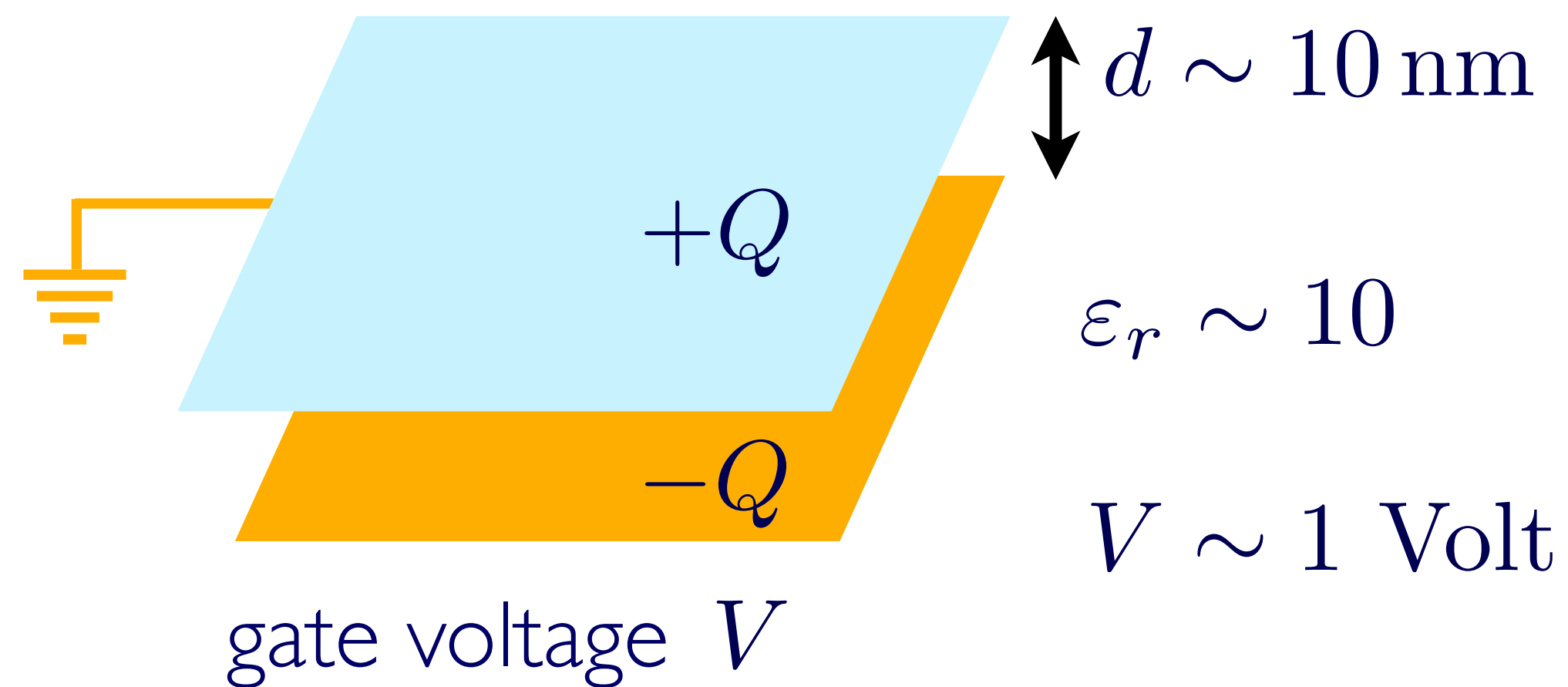
Charge density:

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How does this compare to the length scales we have at hand?

# Length scales in Landau Levels vs. Materials

---

Landau levels have a single scale: the magnetic length

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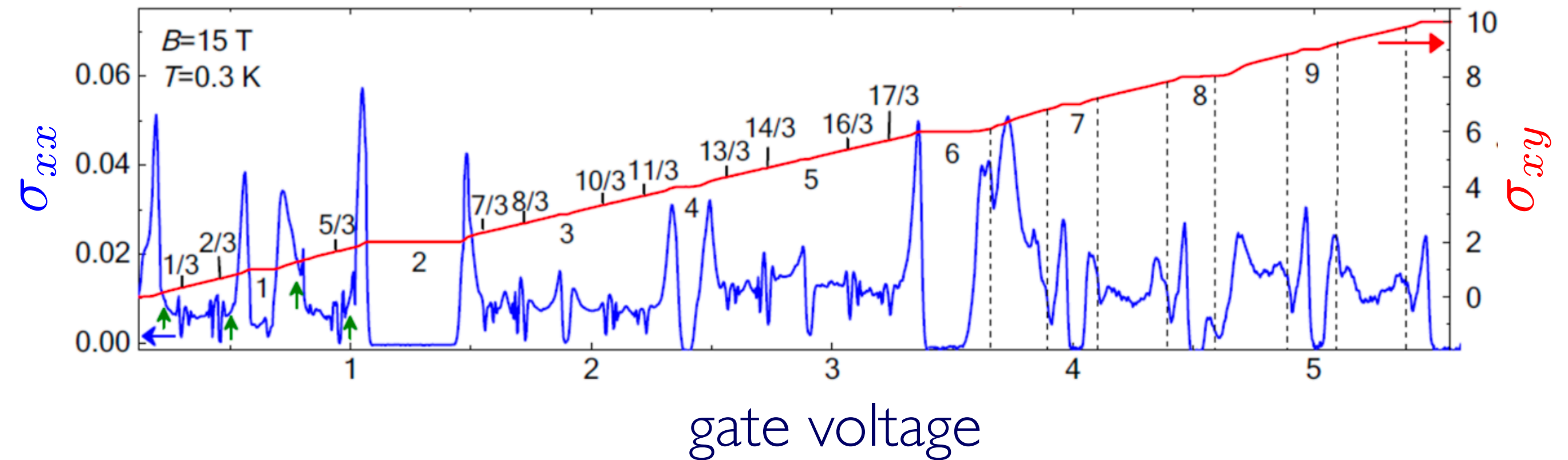
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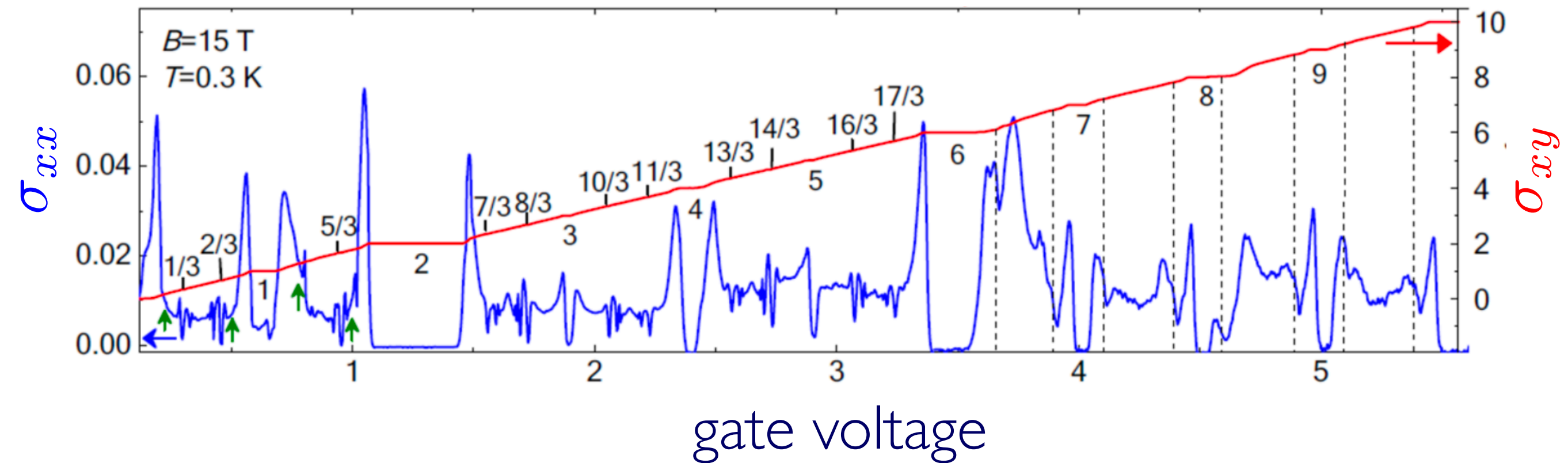


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In materials: typical unit cell scale  $a \sim 0.3 \text{ nm}$ , so

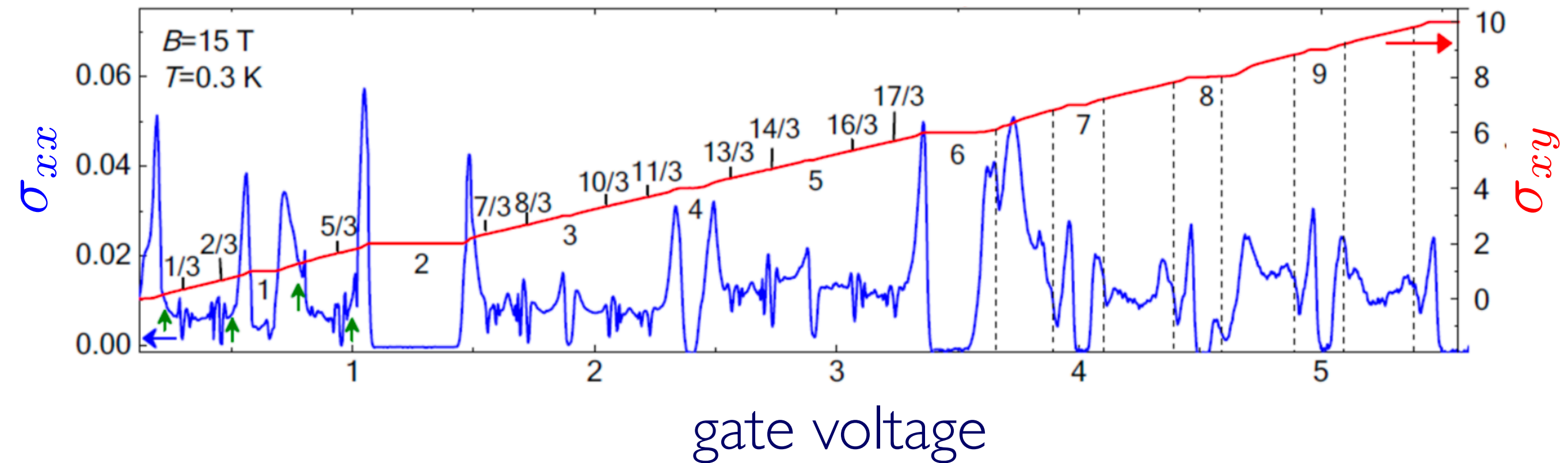
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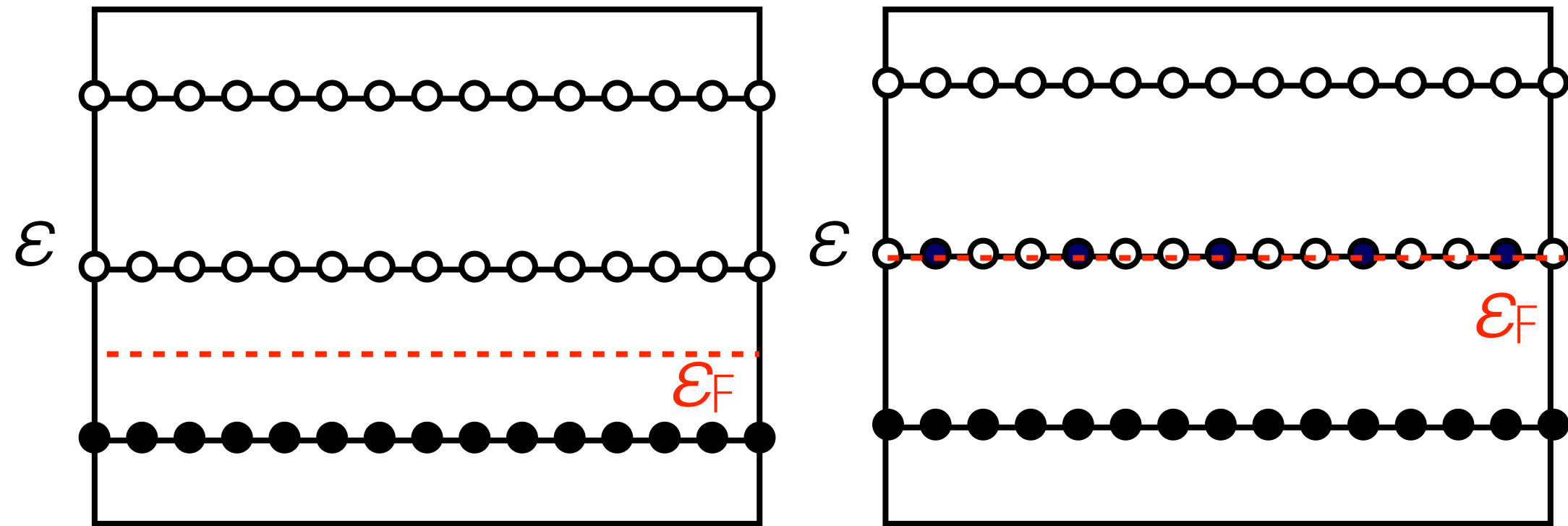
In materials: typical unit cell scale  $a \sim 0.3 \text{ nm}$ , so  $n \sim \frac{1 \text{ electron}}{(10 \text{ nm})^2} \sim \frac{10^{-3} \text{ electron}}{(\text{unit cell})}$

So even **if** we realise a Chern band in a regular crystal, very difficult to access sensible fractional fillings!

# State of Play: Landau Levels vs. Chern Bands

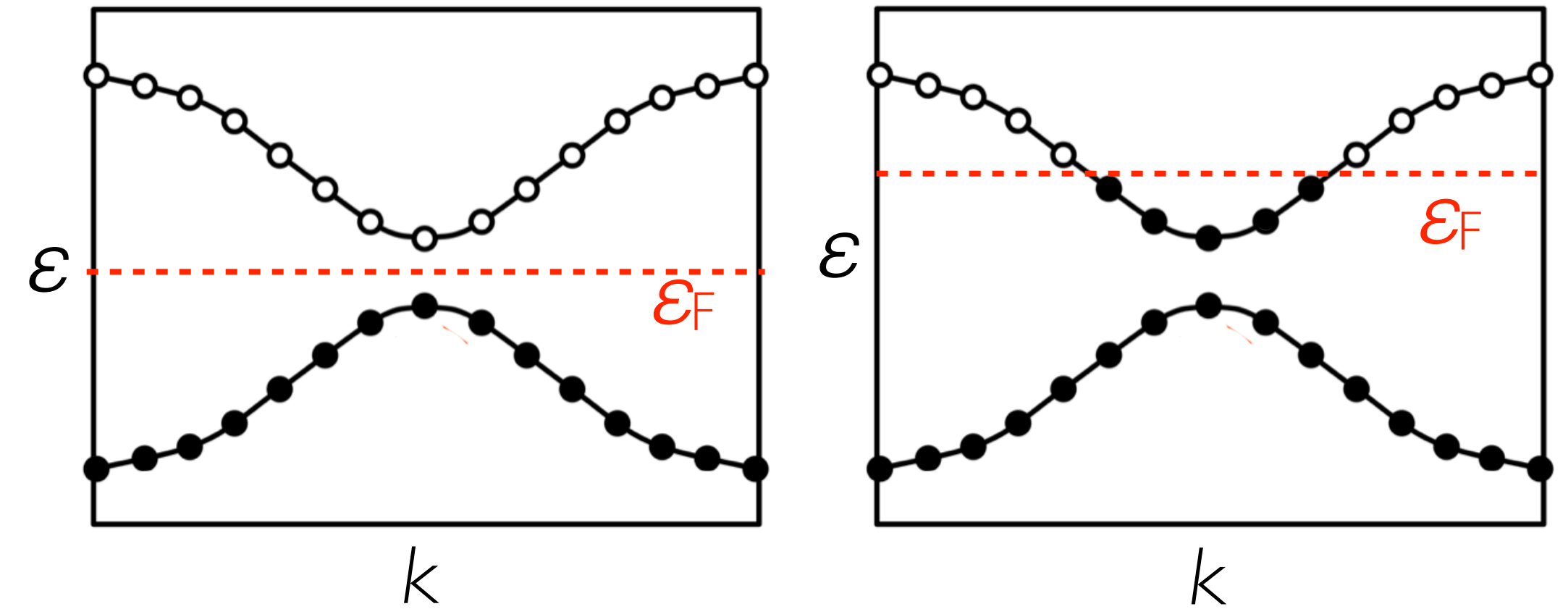
**Landau Levels**

$$\nu = \frac{\text{number of electrons}}{\text{number of flux quanta}}$$



**Chern Bands**

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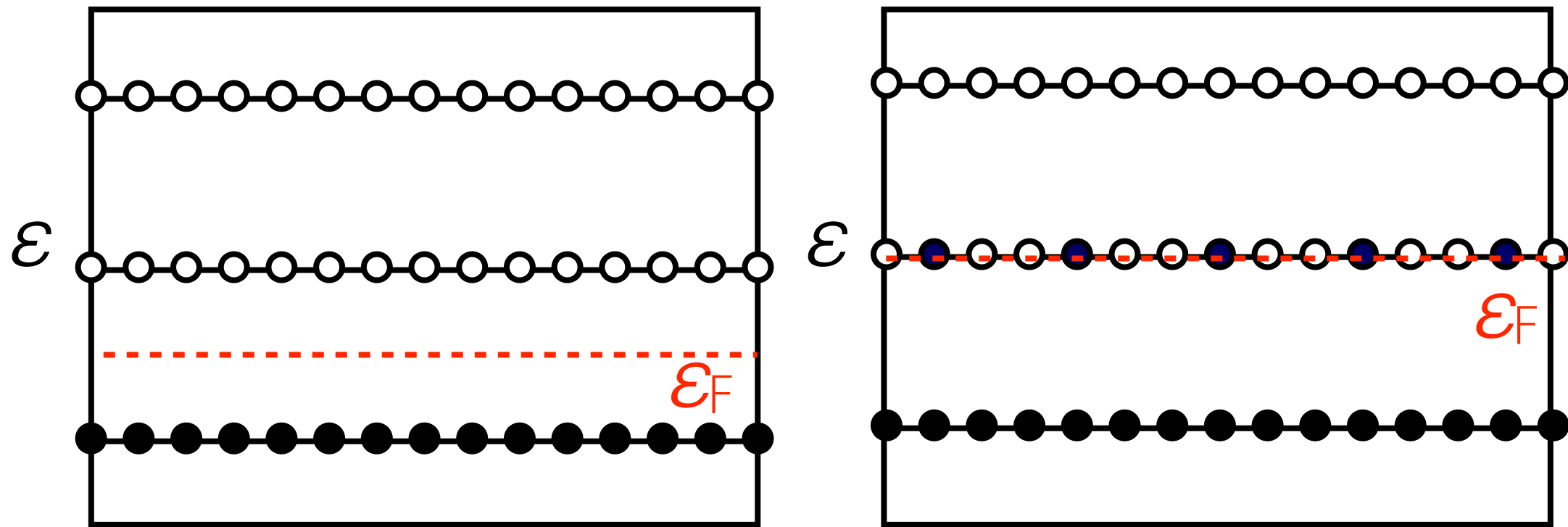




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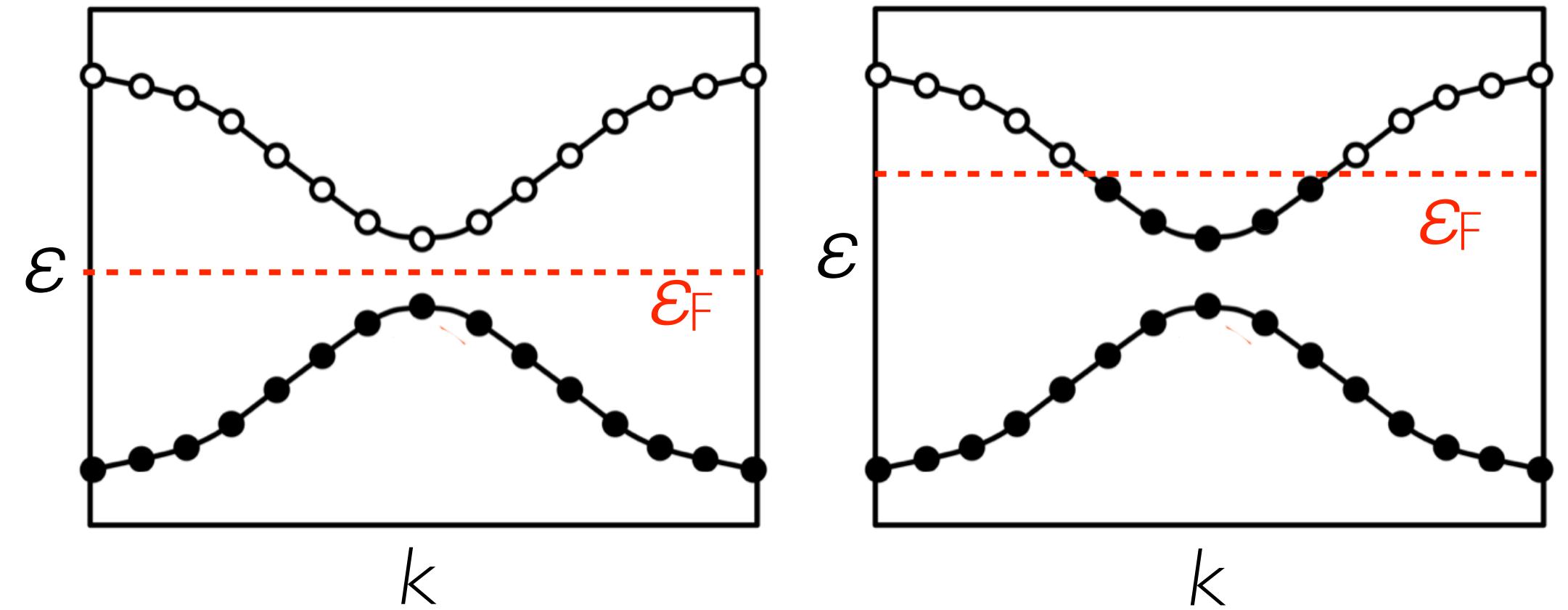
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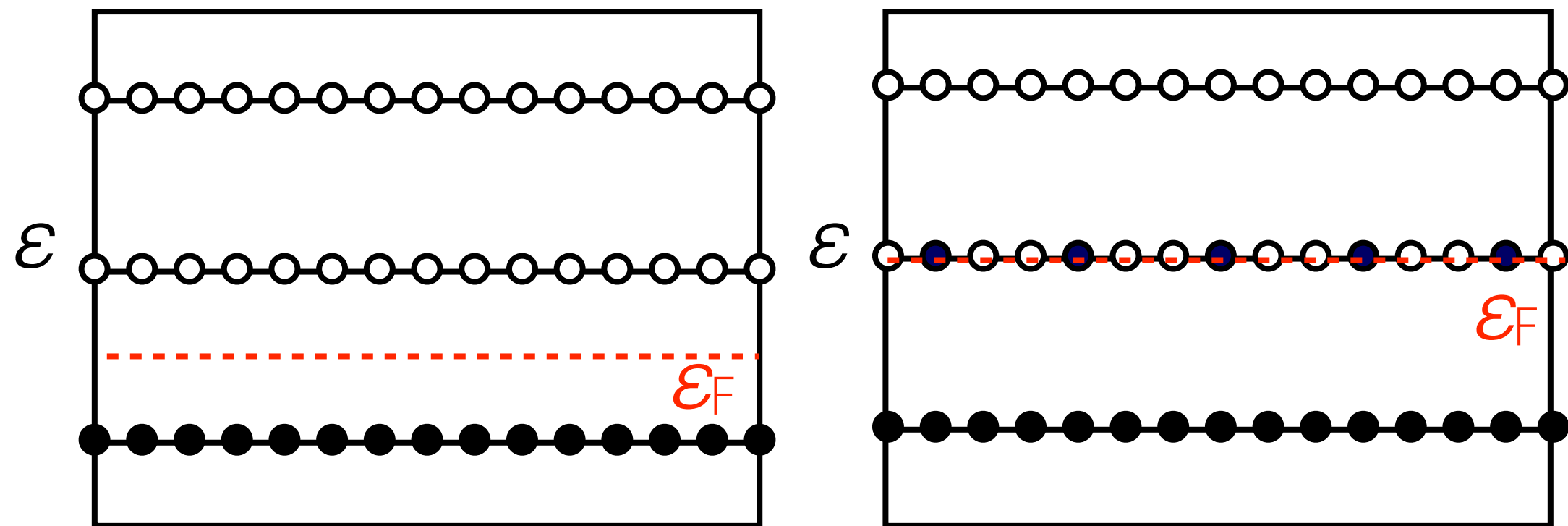


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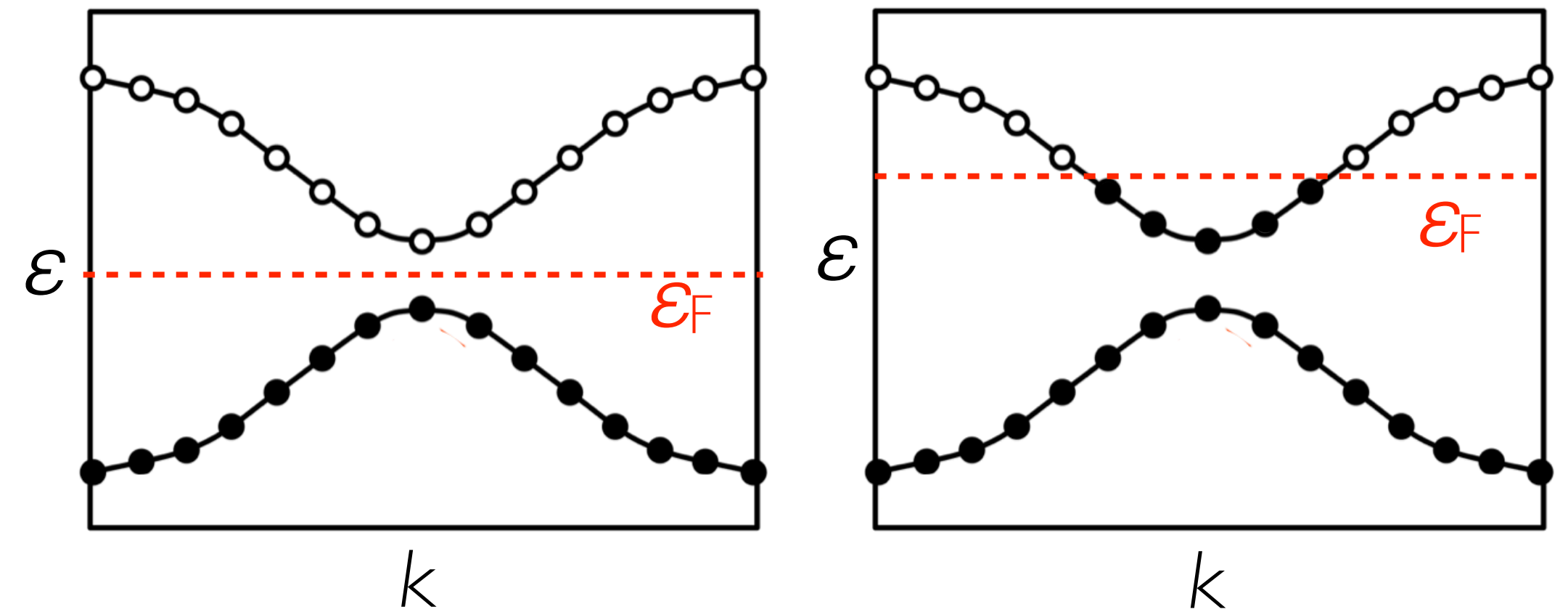
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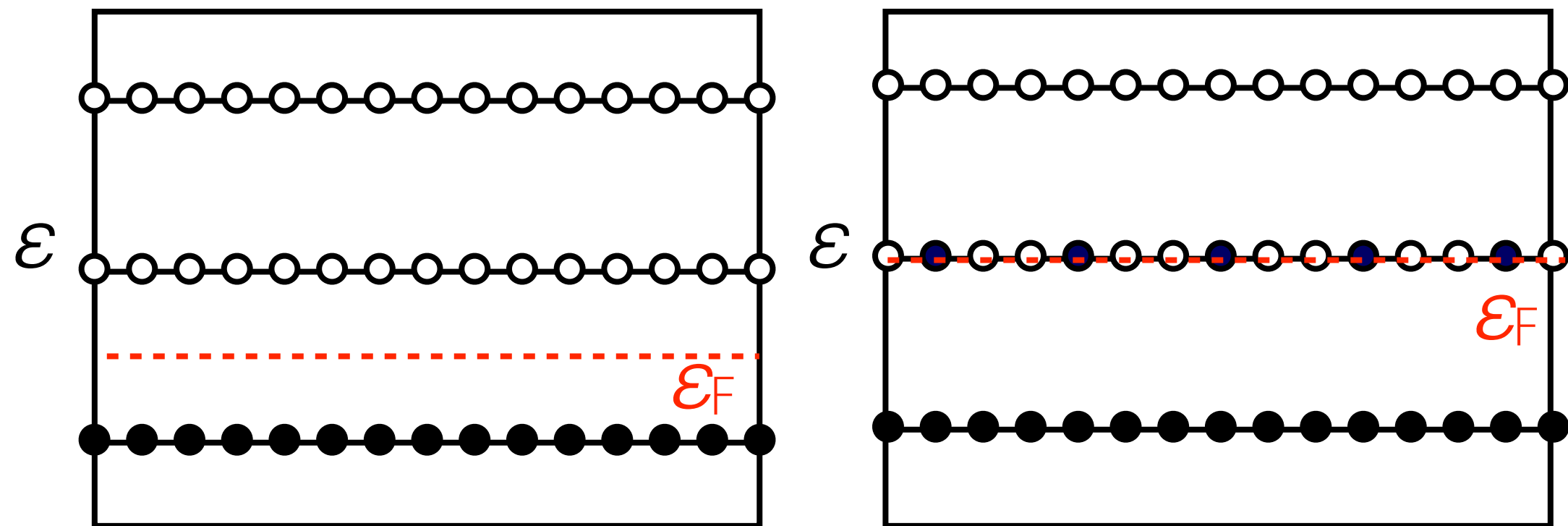


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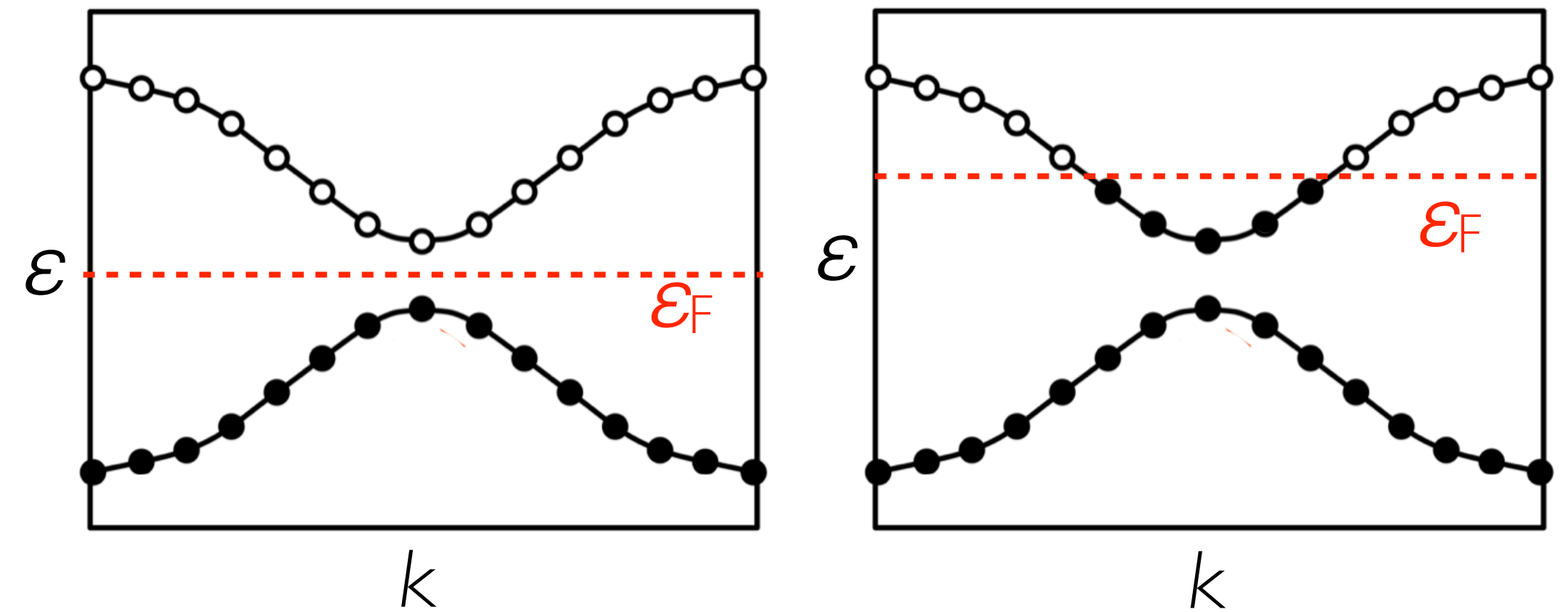
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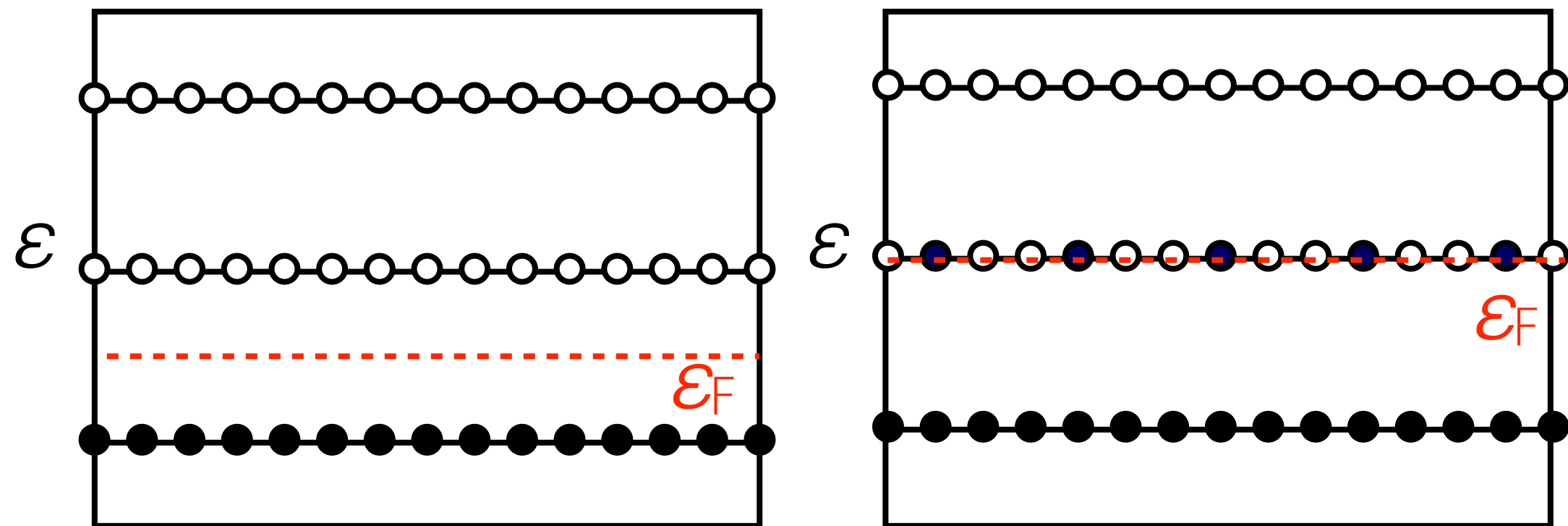


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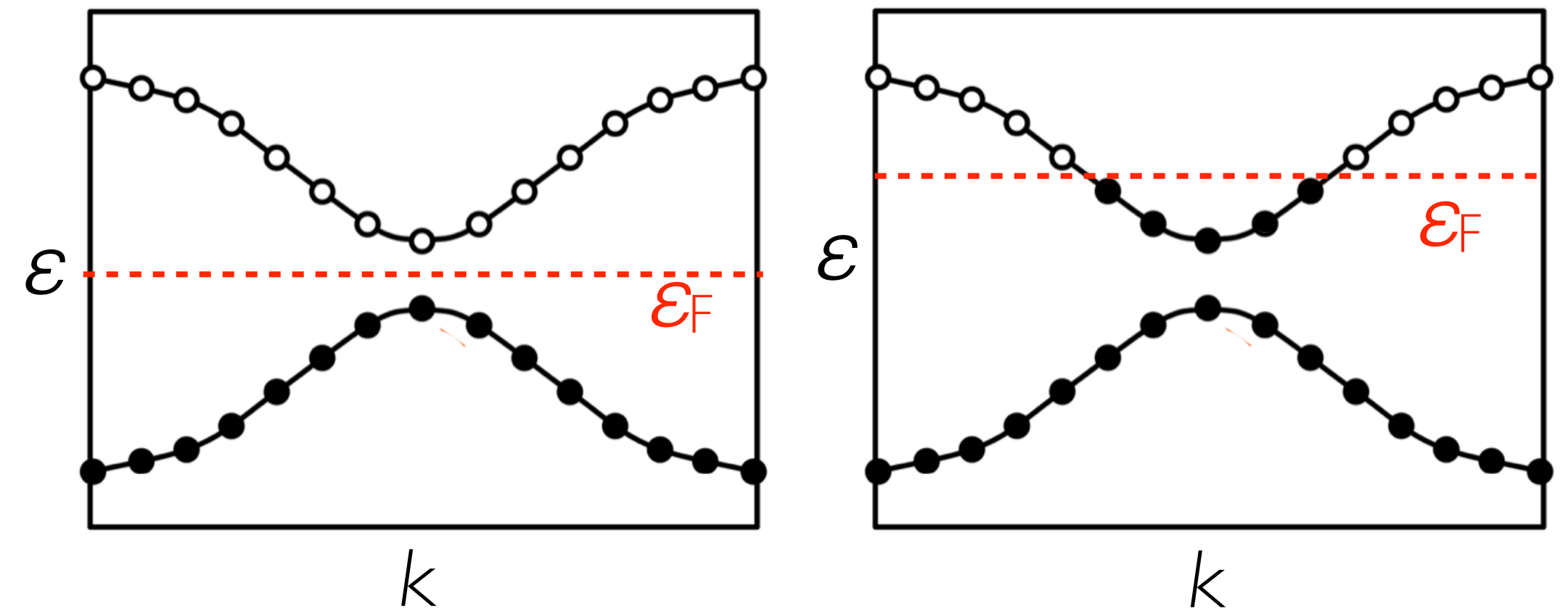
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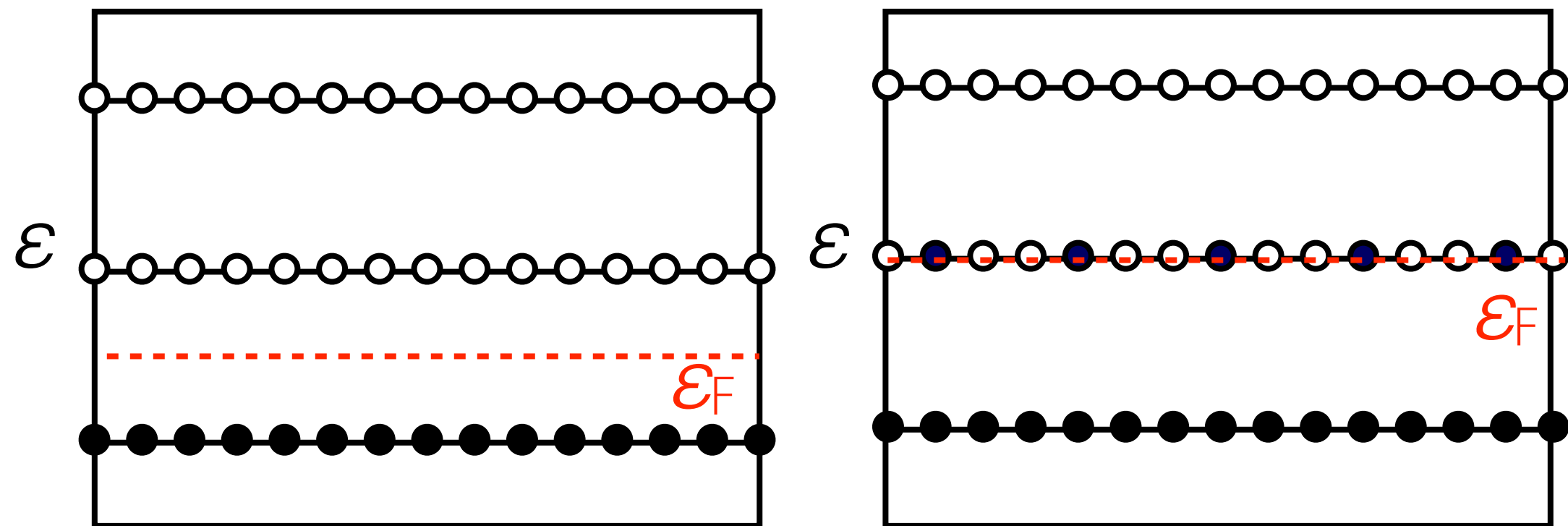


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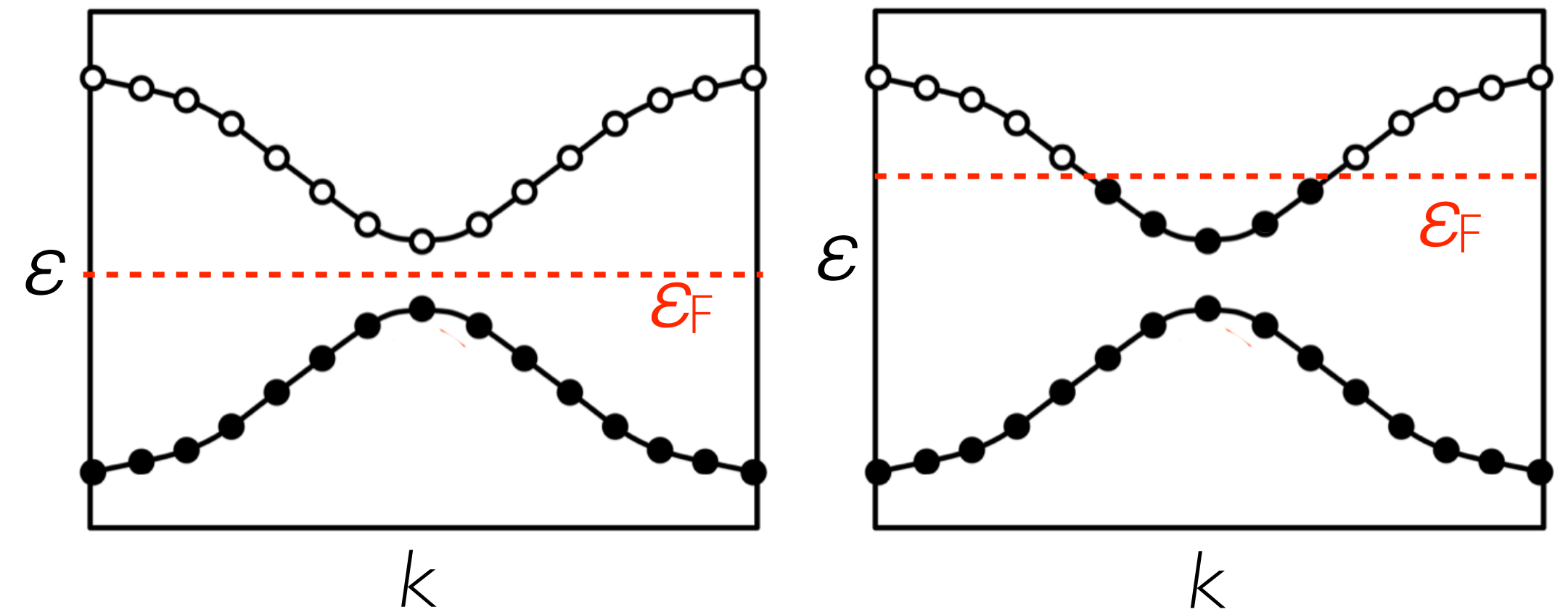
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- Filled LL  $\Rightarrow$  Integer QH insulator
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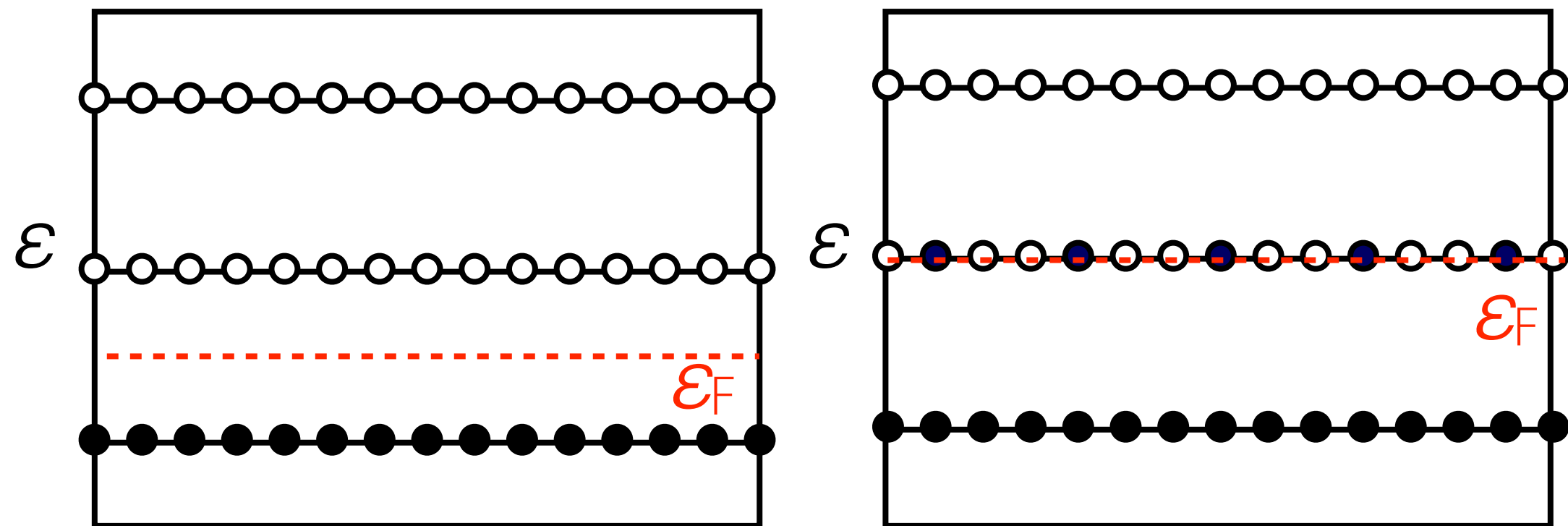
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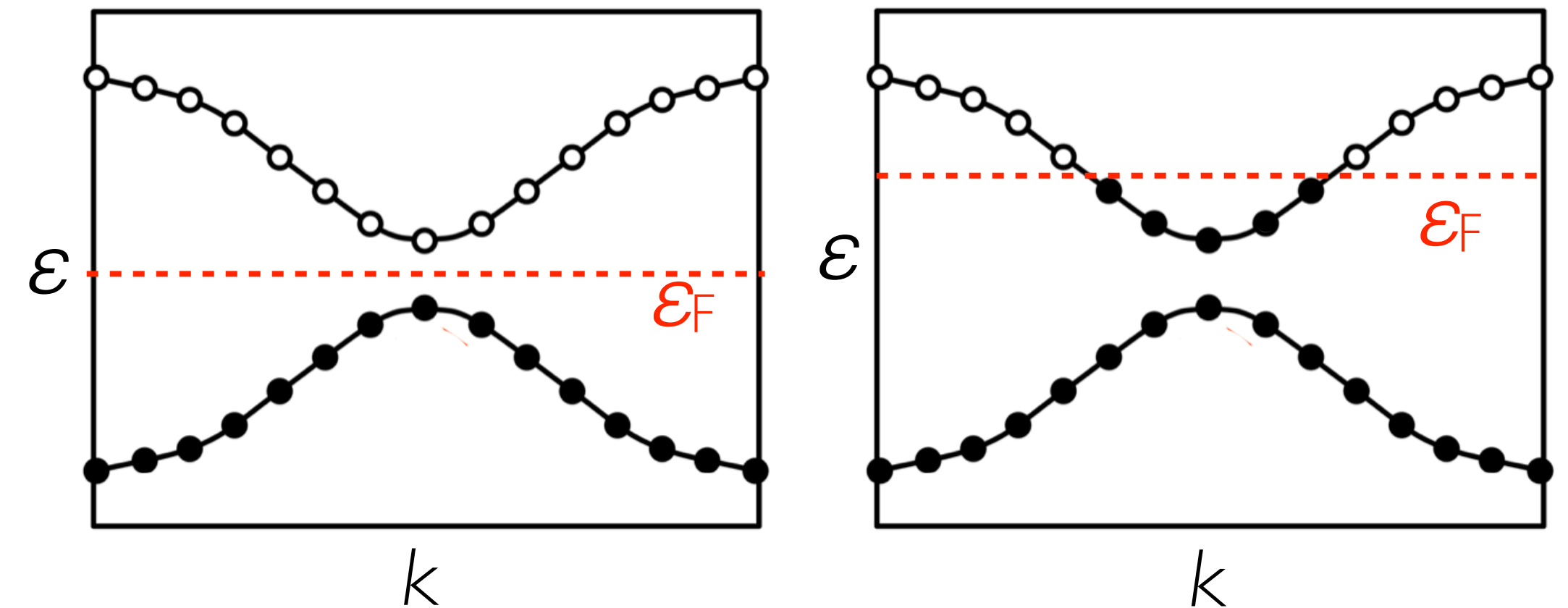
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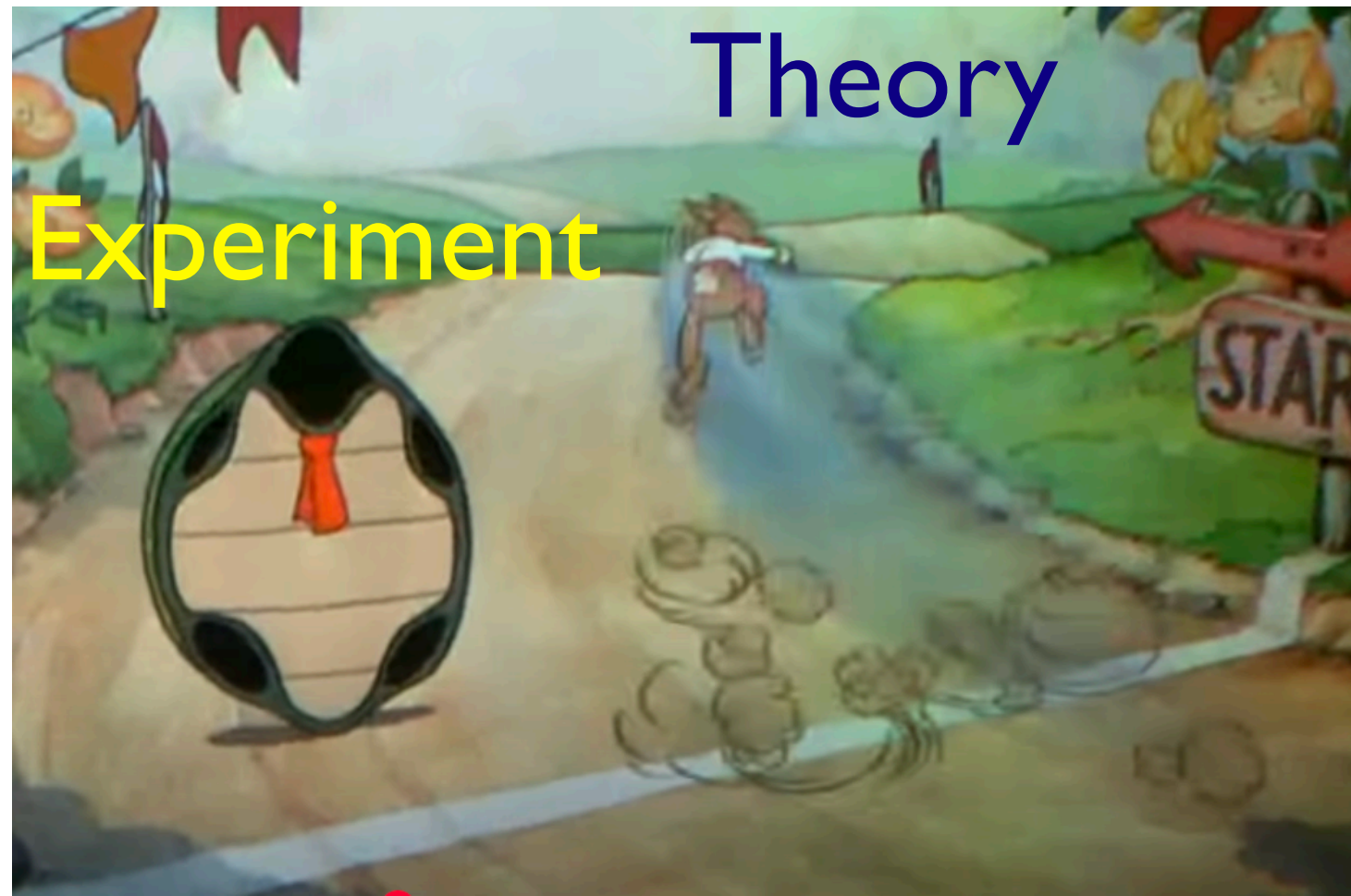
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So, the challenge is clear: need crystalline systems with

- **topology:** energy bands with Chern numbers
- **correlations:** interactions enhanced relative to kinetic energy
- **tunability:** ability to easily change filling by  $\pm O(1)$  electron per unit cell

# What happened next... the Hollywood version

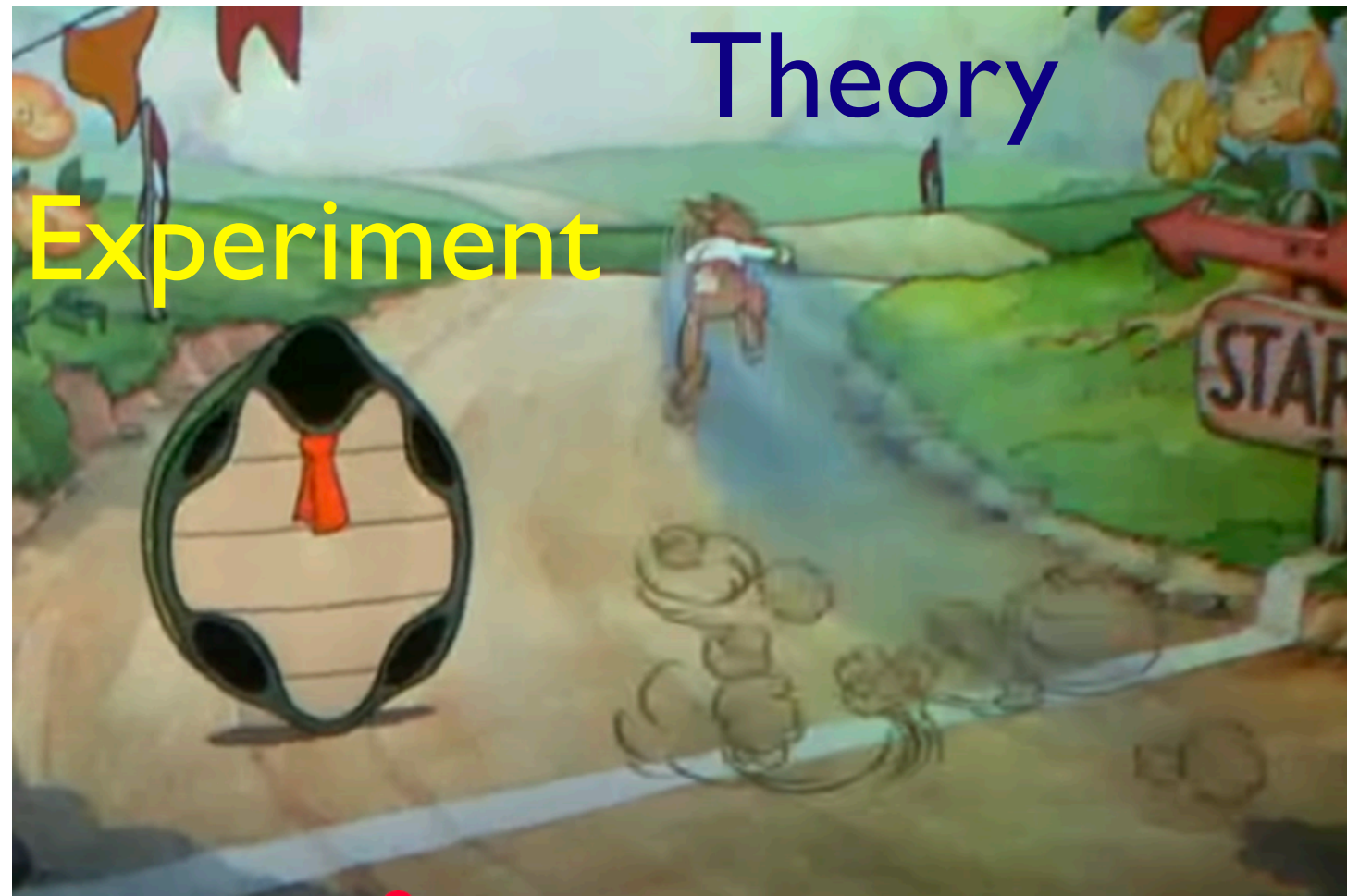
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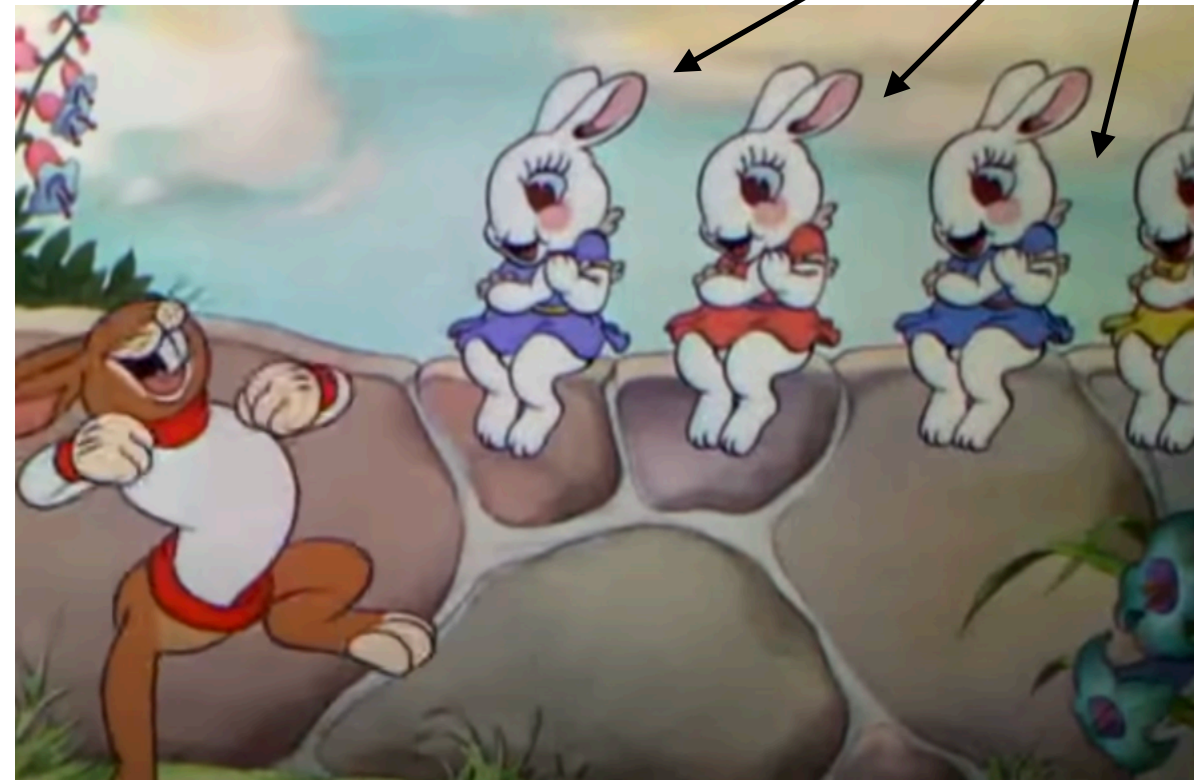
c. 2013



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c. 2013

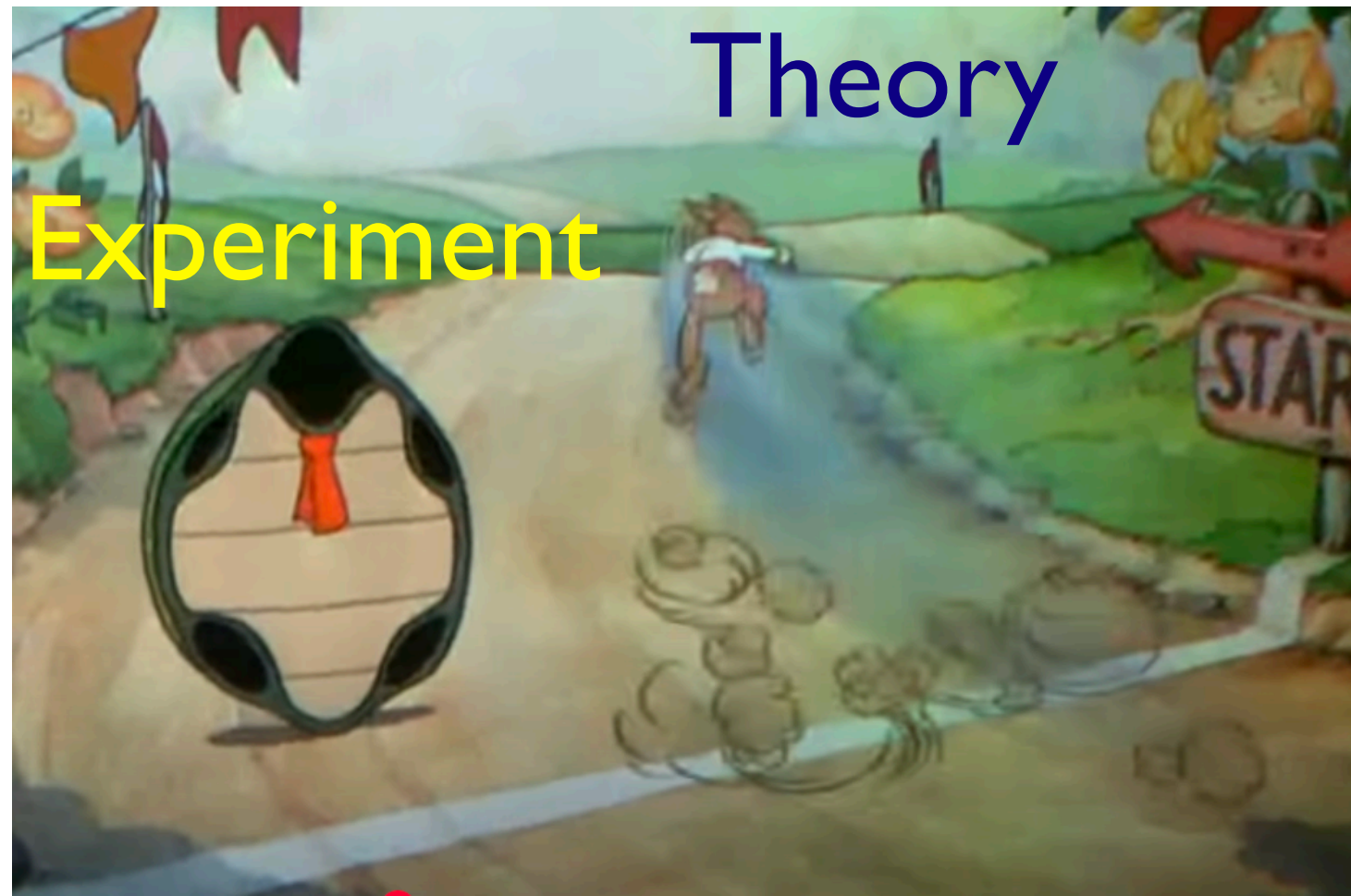


Lots of very esoteric questions

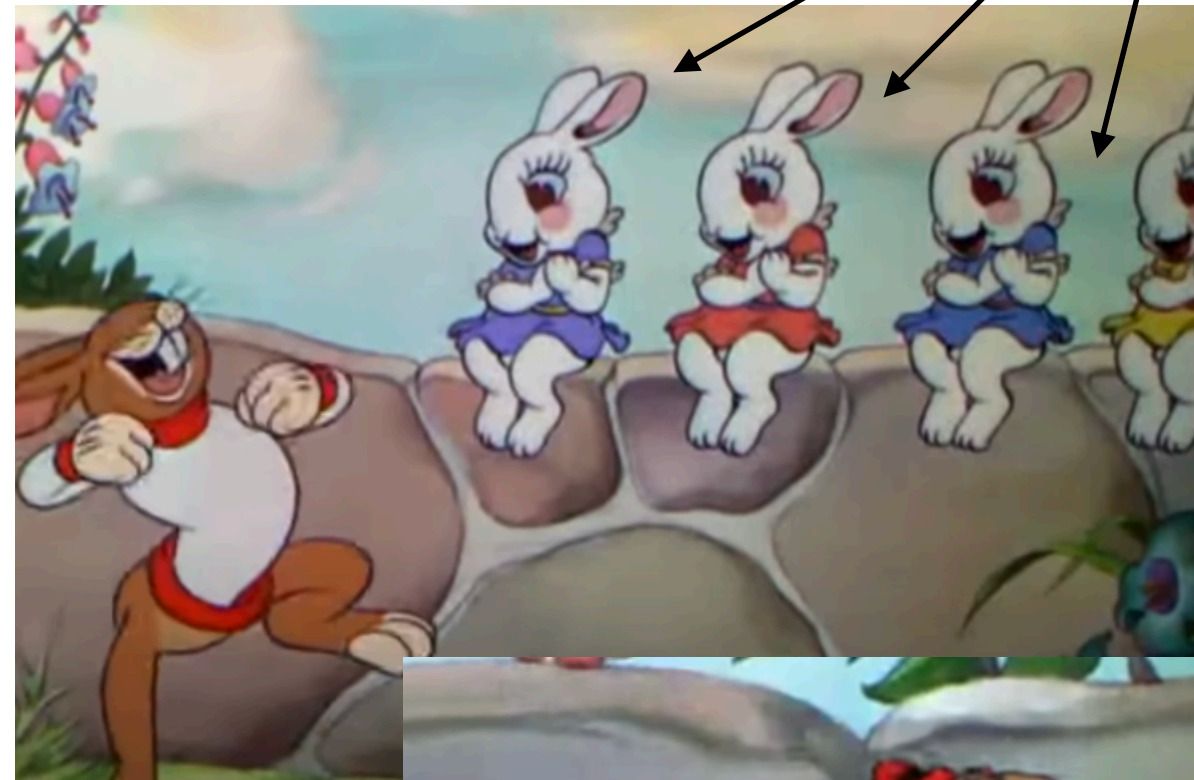
2013-2018



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c. 2013



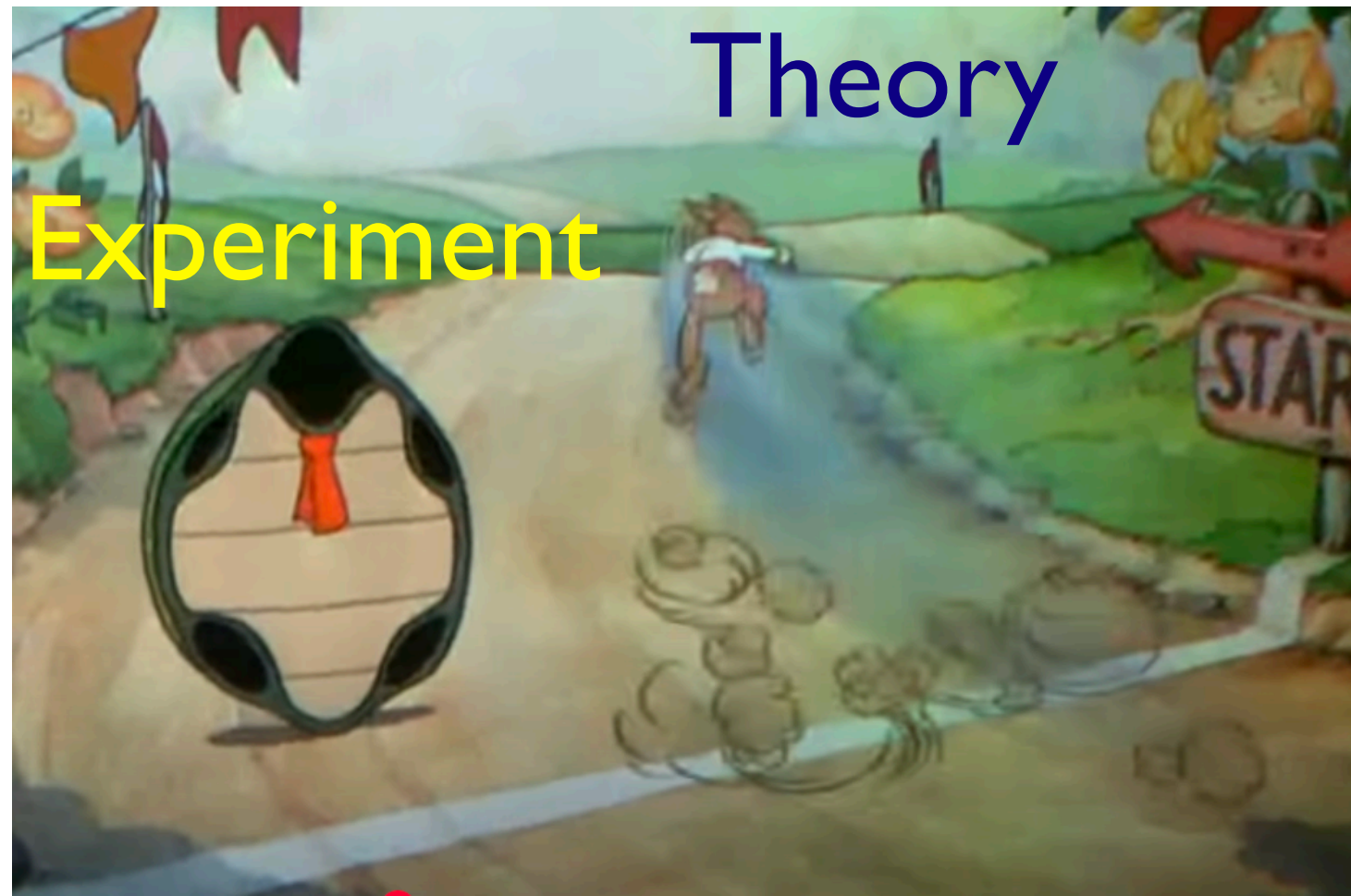
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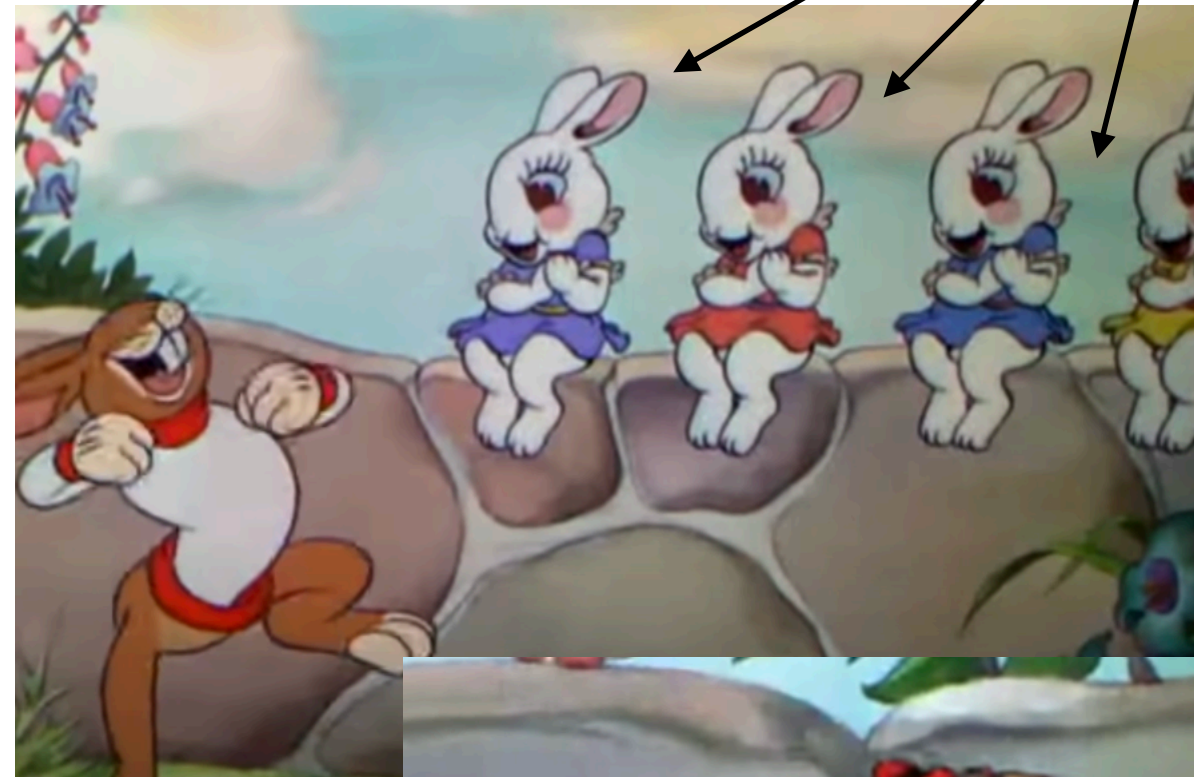
2013-2018



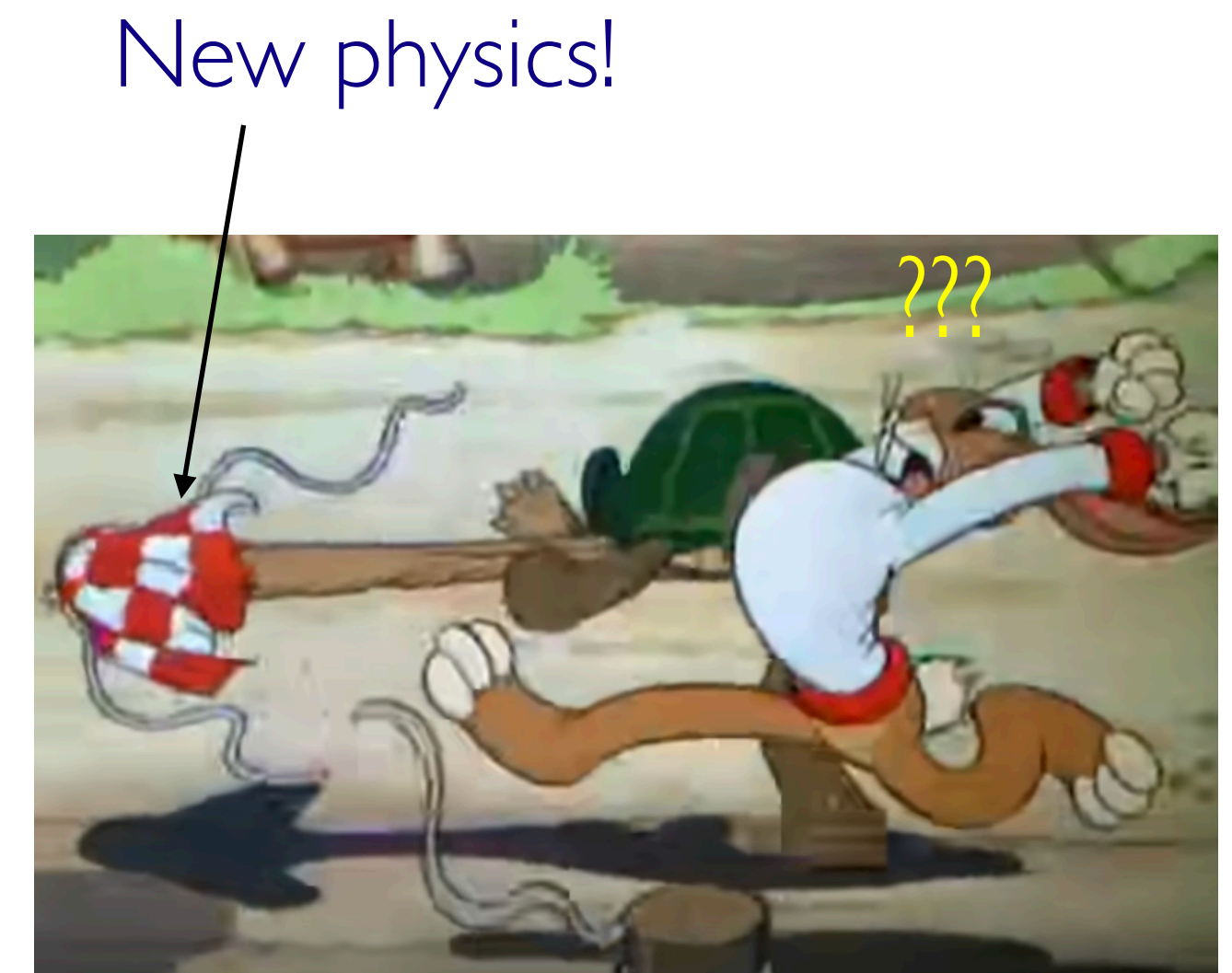
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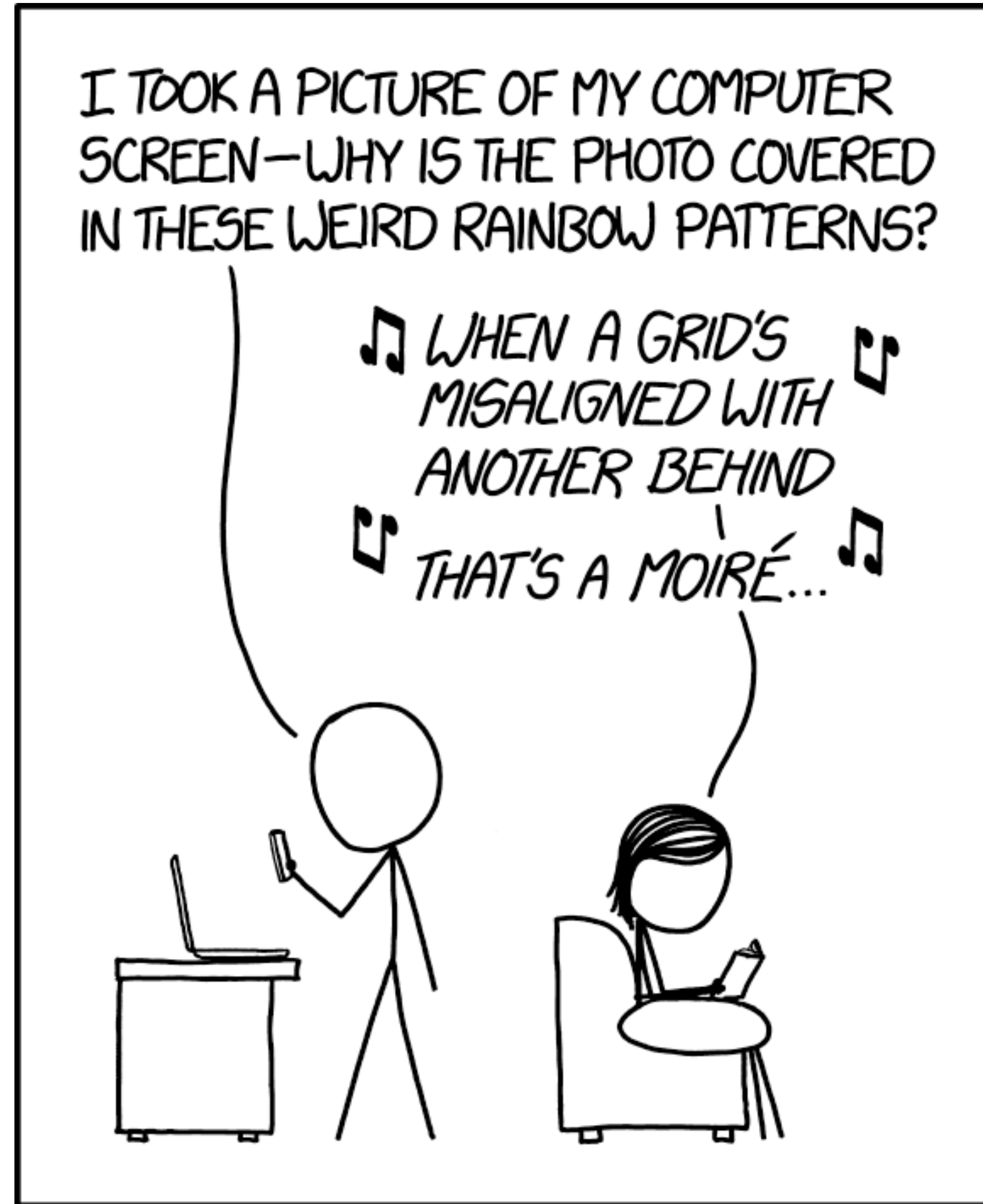
2013-2018



c. 2018



# New Physics: the “Moiré Effect”



xkcd

(with apologies to Dean Martin)



# New Physics: the “Moiré Effect”

**moiré** — from textile industry

~ moirer (French) ~ mohair (English) ~ mukhayyar (Arabic = “chosen”)



A. ZWICKY'S BLOG

“beating” of periodic structures w/ slightly offset period or orientation



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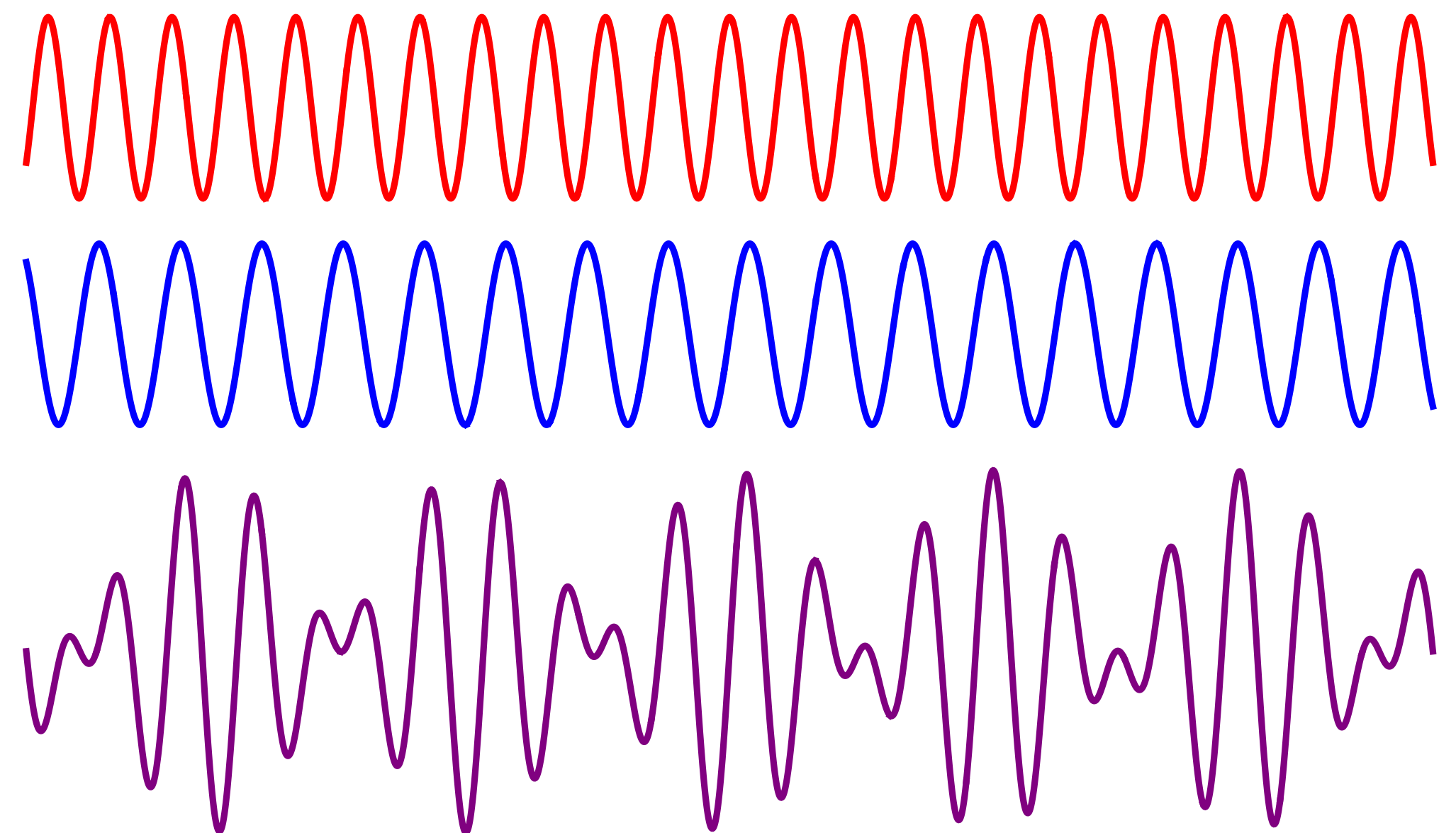


“beating” of periodic structures w/ slightly offset period or orientation

**1D example:**

$$V_{\pm}(x) = \sin[(k \pm \delta)x]$$

$$V_{+}(x) + V_{-}(x) = 2 \cos(\delta x) \sin(kx)$$



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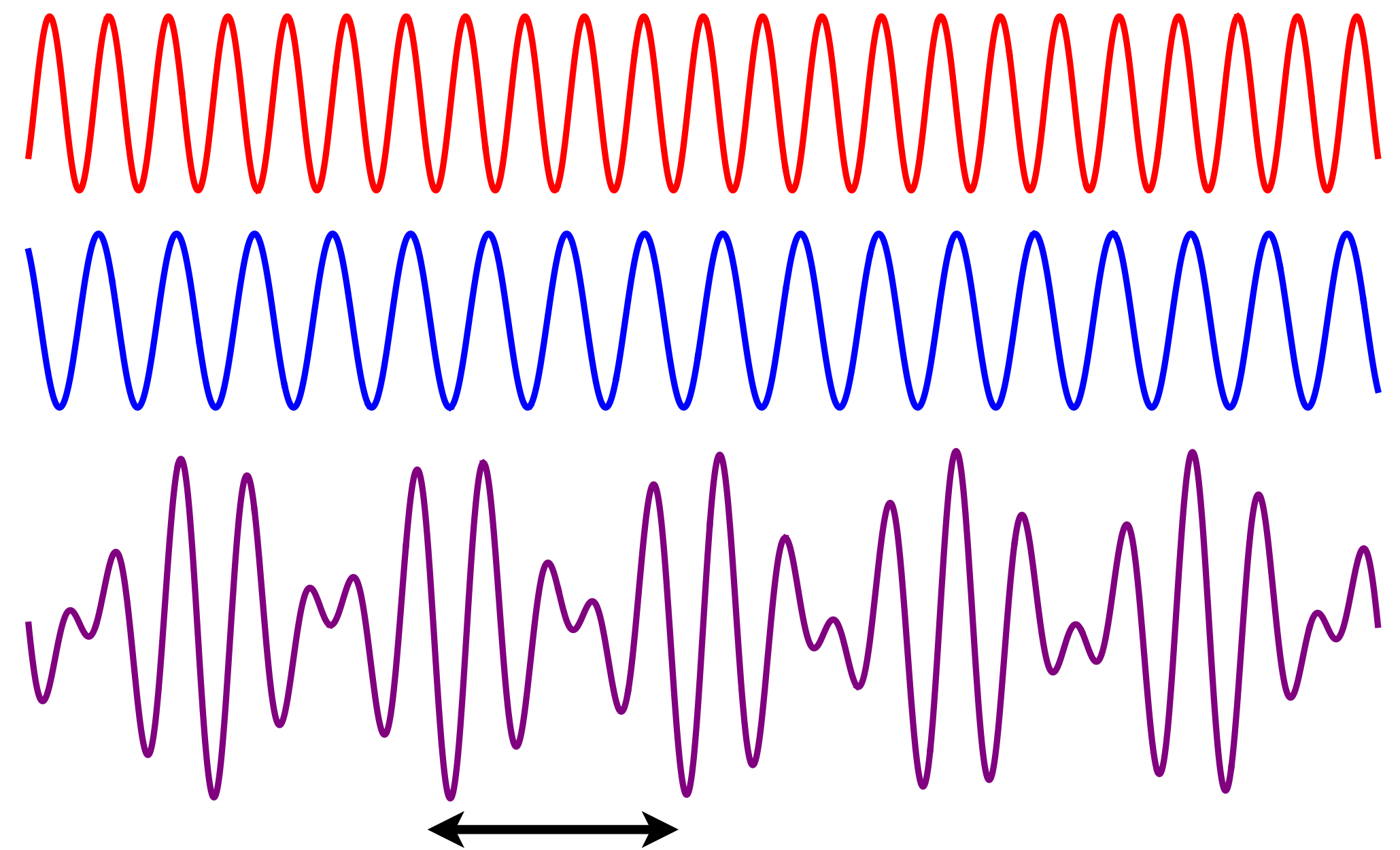


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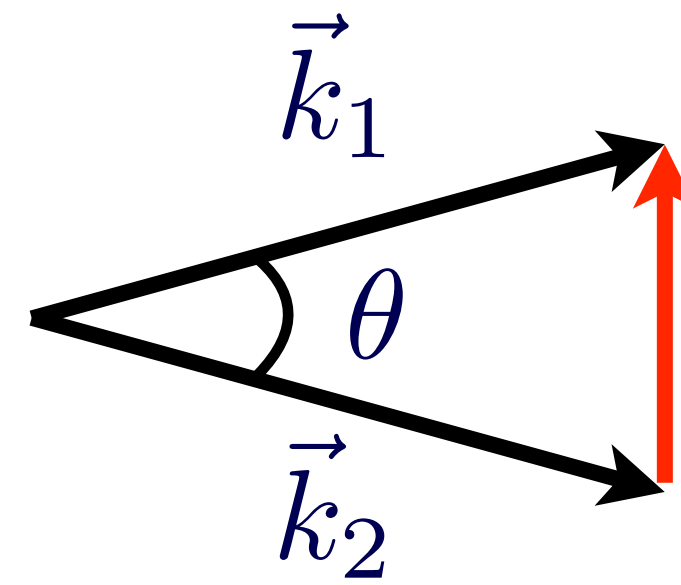
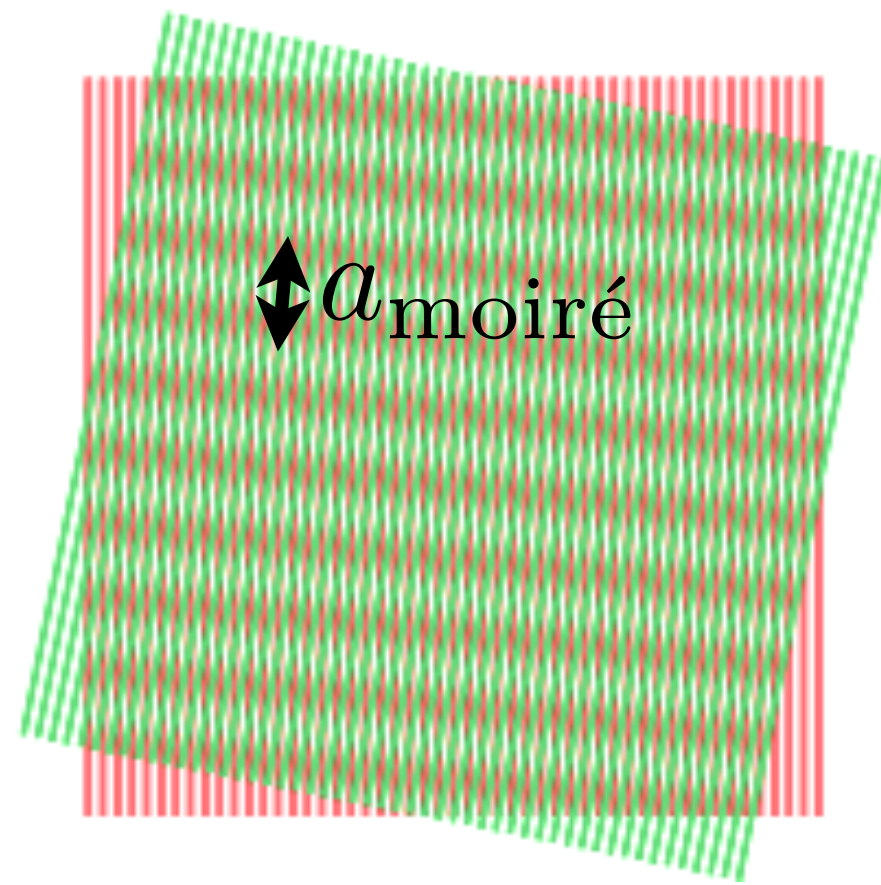


“superlattice” w/ approximate period  $a_{\text{moiré}} = \frac{2\pi}{\delta} \gg \frac{2\pi}{k}$



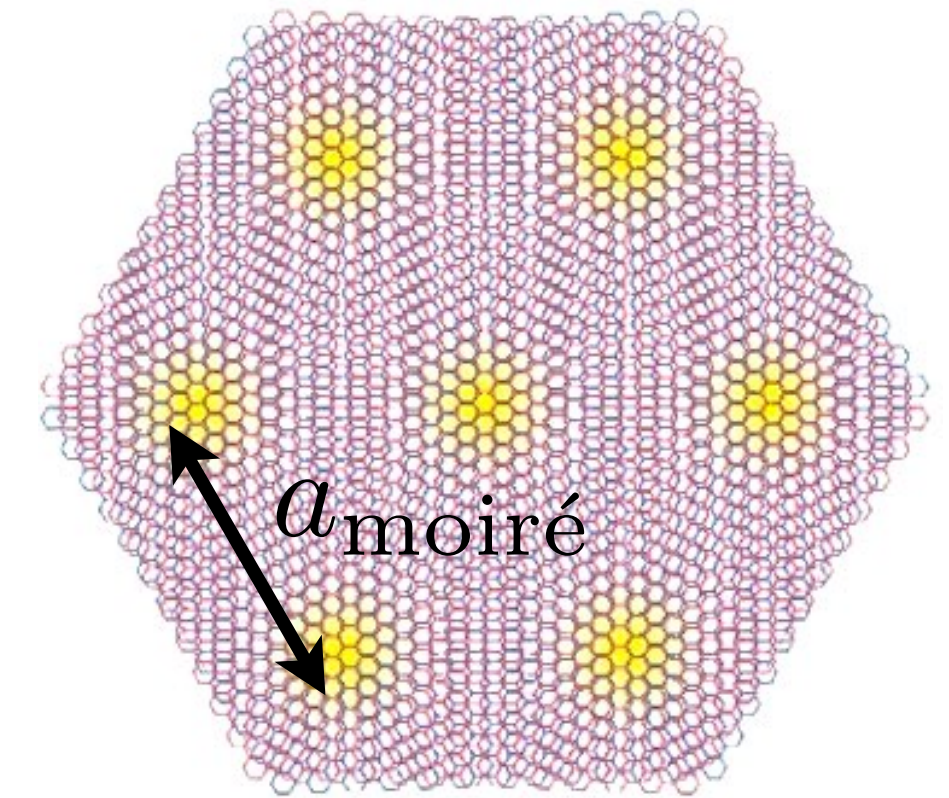
# Moiré Materials

2D materials (e.g. graphene) held together by van der Waals forces: **moiré from twisting**



$$V_i(x) \sim \cos(\vec{k}_i \cdot \vec{x})$$

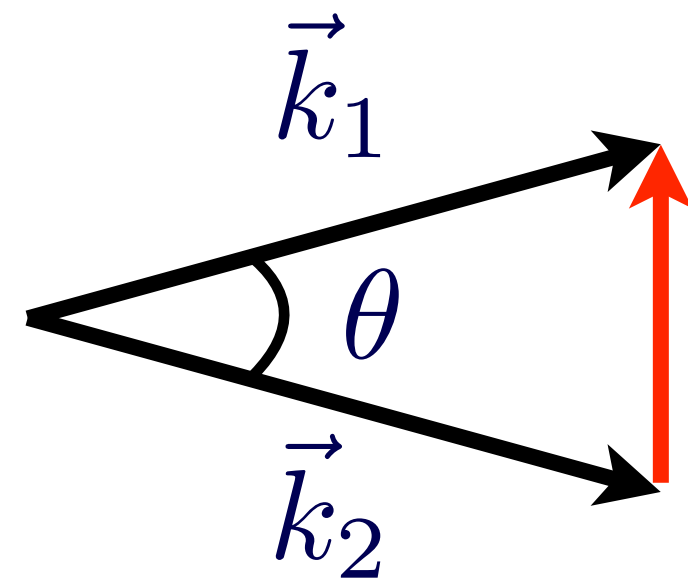
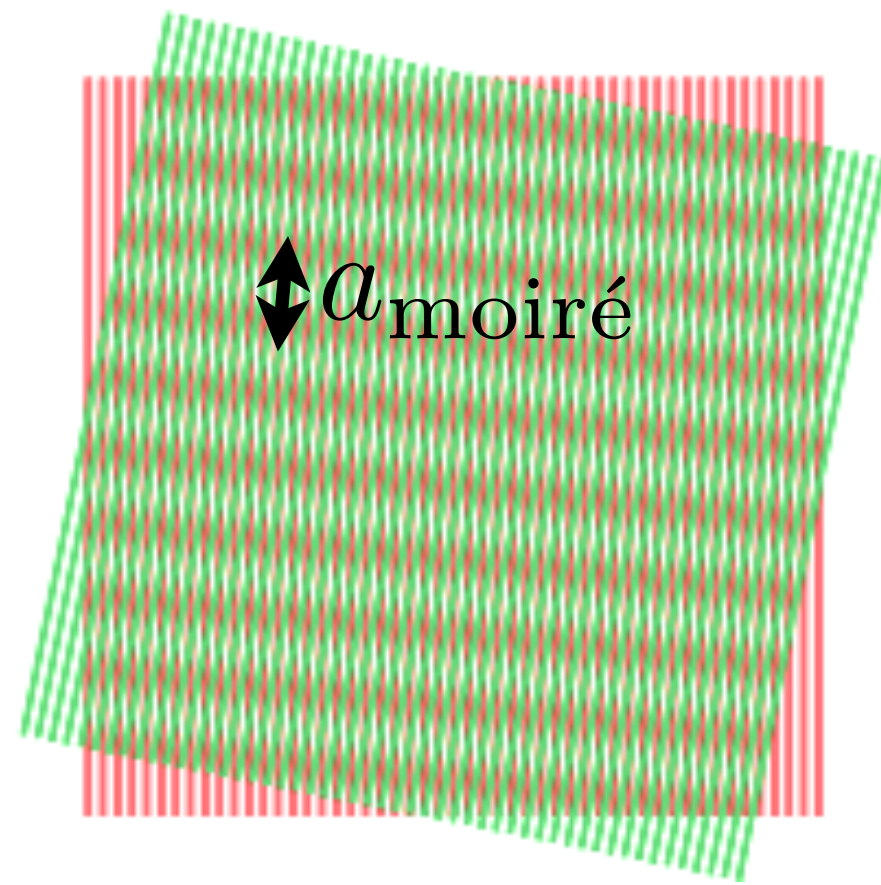
$$\delta = |\vec{k}_1 - \vec{k}_2| \sim 2|\vec{k}_i| \sin \frac{\theta}{2} \approx |\vec{k}_i| \theta$$





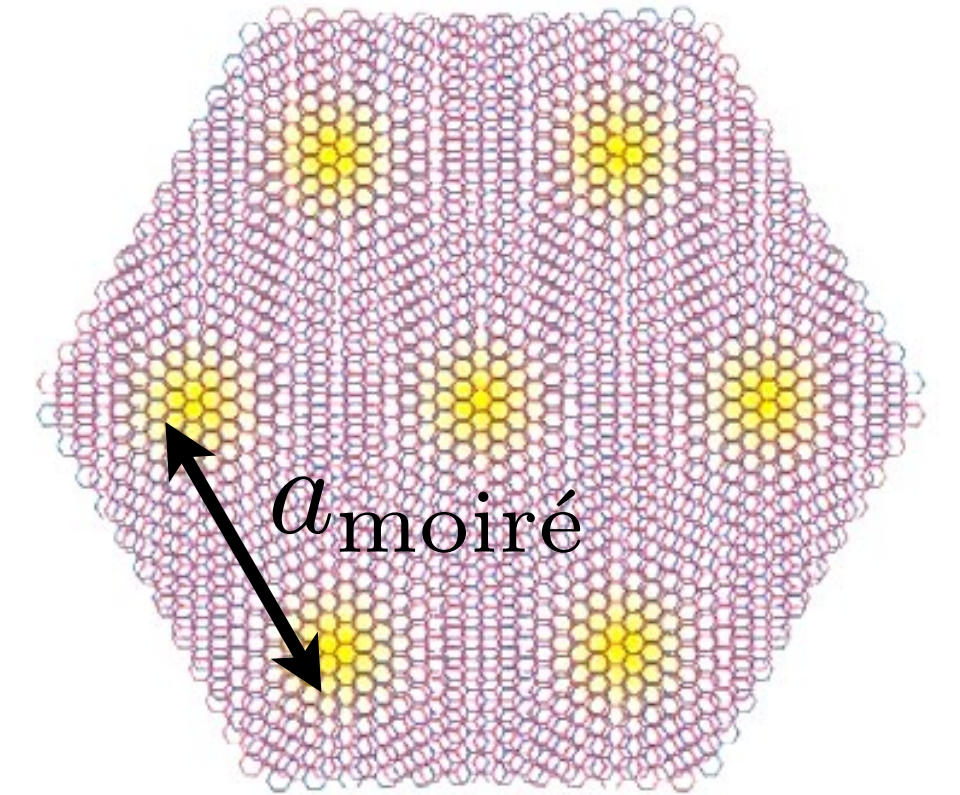
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$$a_{\text{lattice}} \sim 0.3 \text{ nm}$$

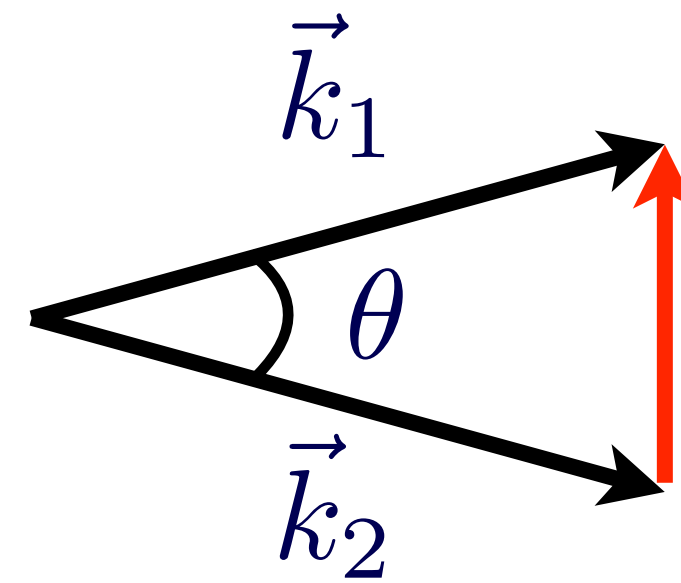
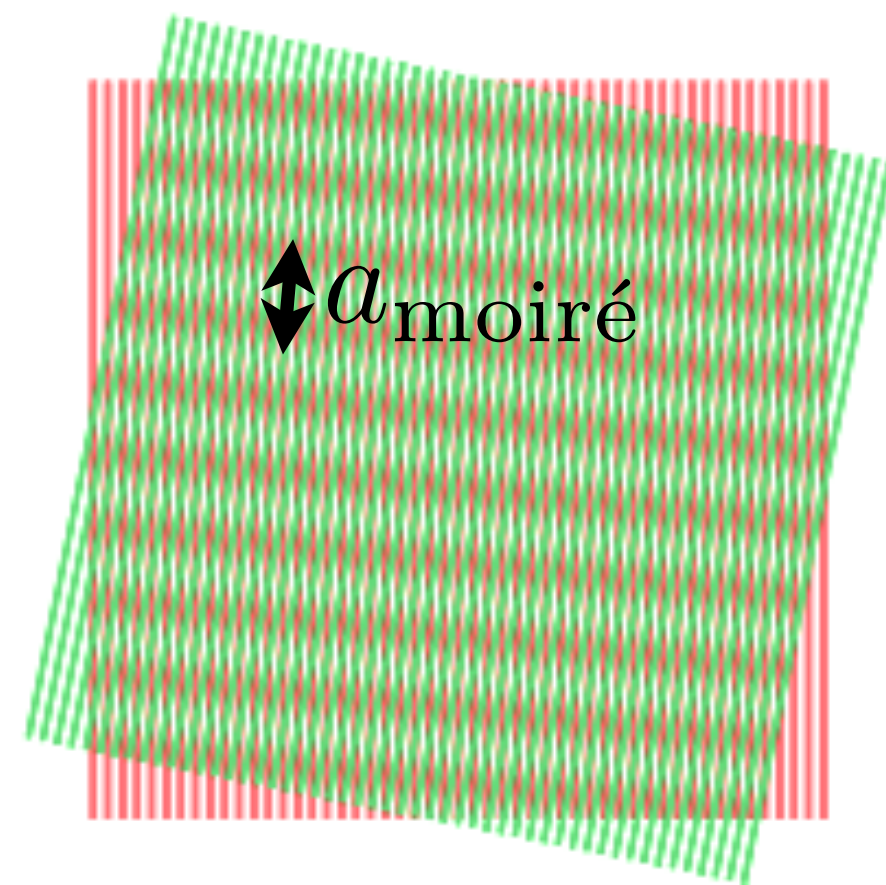
$$\theta \sim 1.5^\circ$$

$$a_{\text{moiré}} = \frac{2\pi}{\delta} \sim \frac{a_{\text{lattice}}}{\theta} \sim 10 \text{ nm}$$



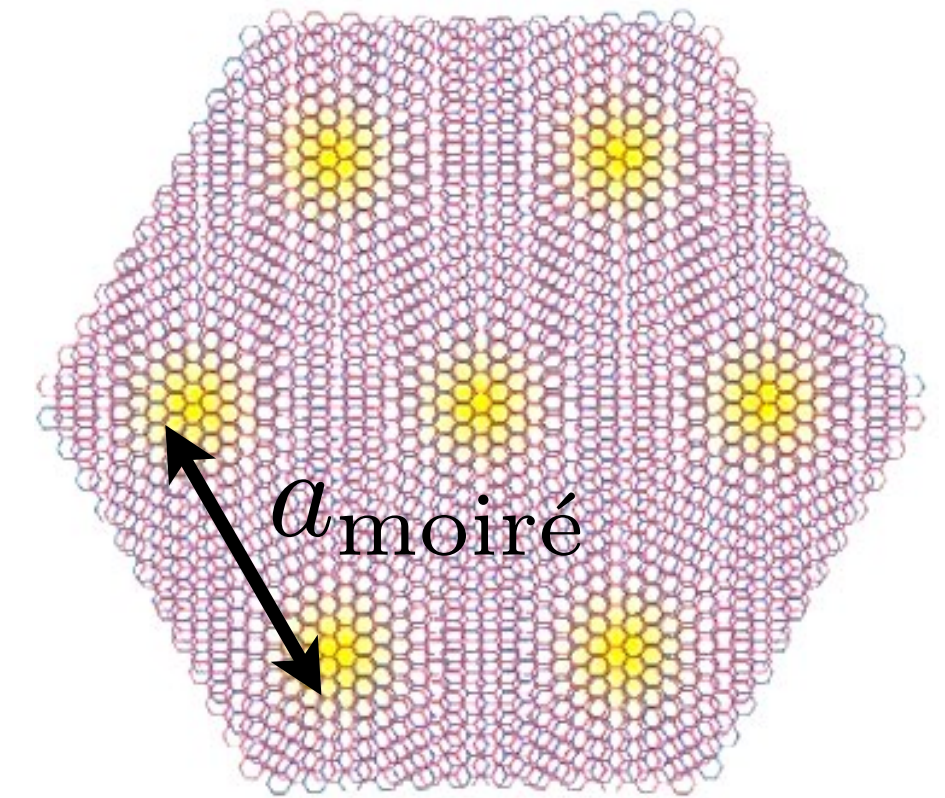
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Just as magnetic field modifies the kinetic energy of free electrons, moiré modifies  $\epsilon(k)$

$\Rightarrow$  “flat” bands w/ small kinetic energy  $\Rightarrow$  strong correlations

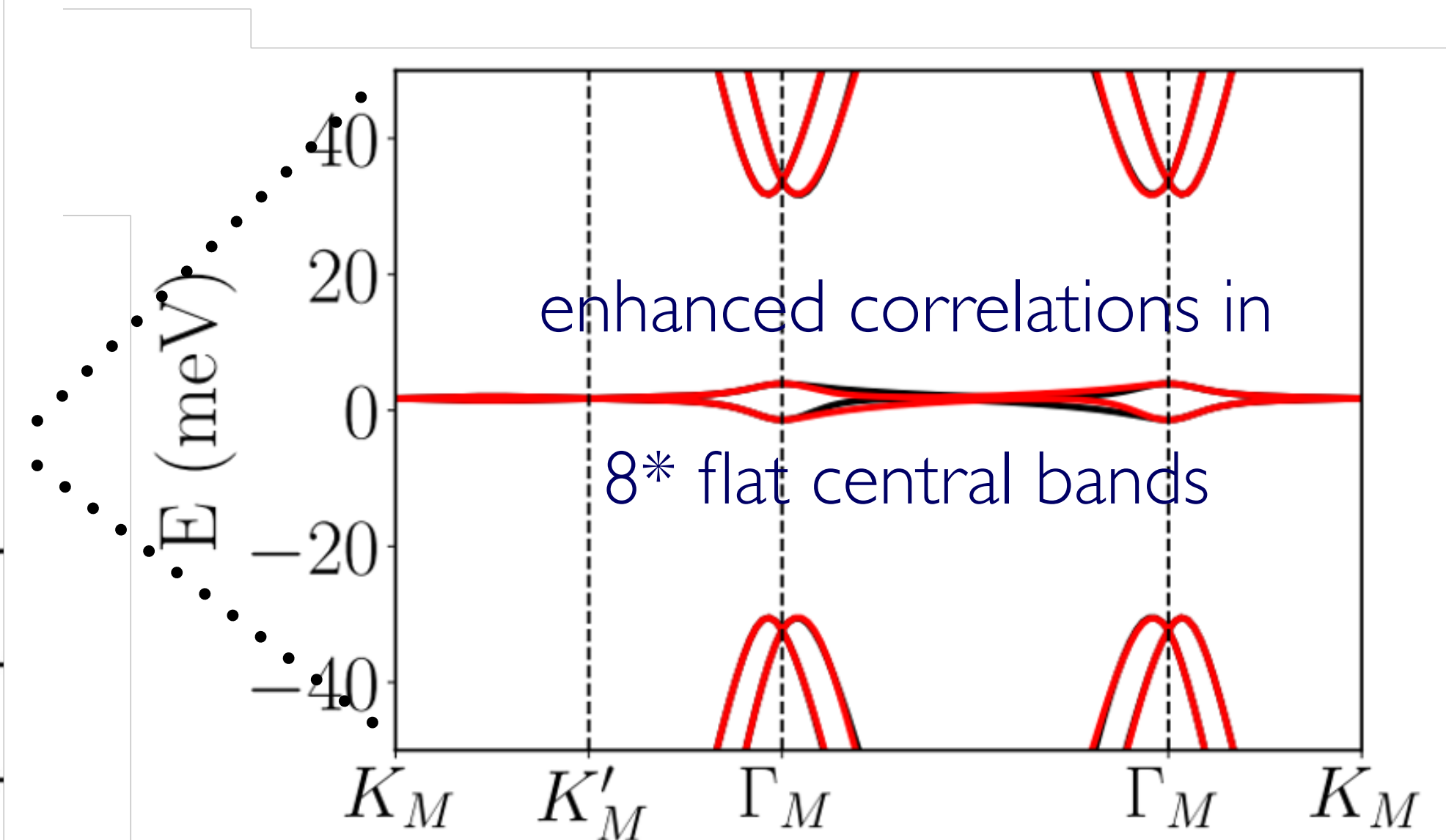
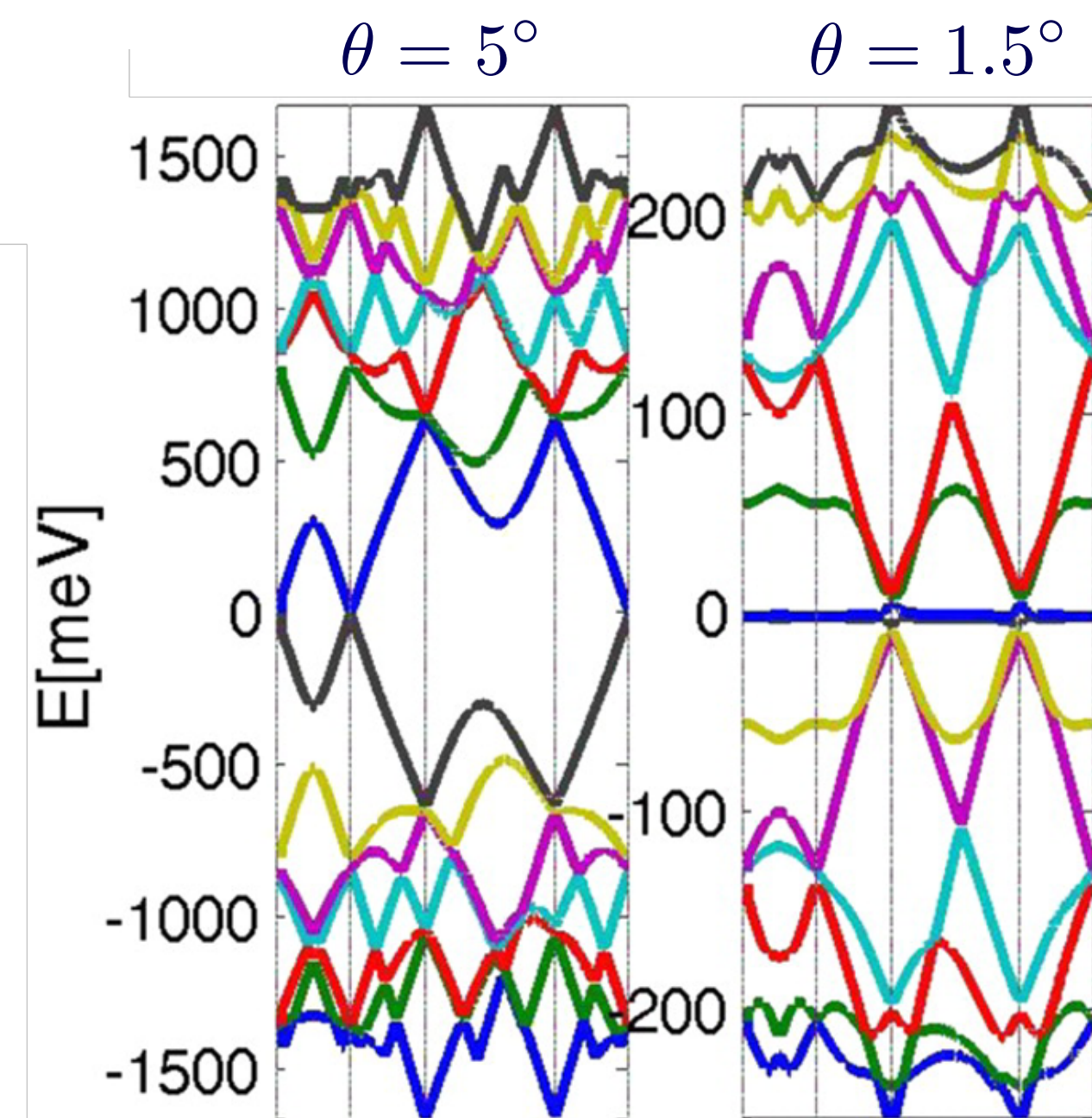
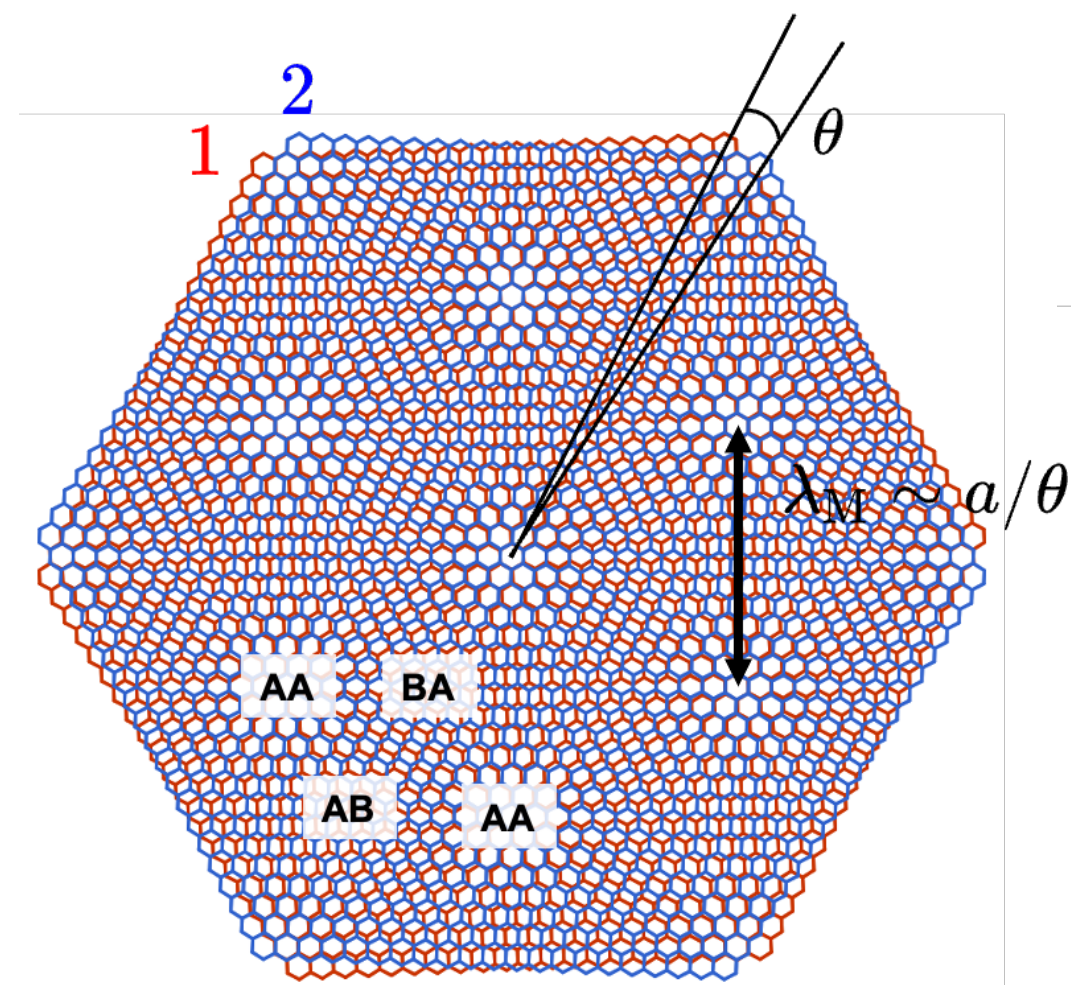
**Many possible combinations & parameters — routes to new physics!**



# “Hydrogen Atom” of Moiré Materials: Twisted Bilayer Graphene (TBG)

Linear “Dirac” dispersion gives special structure to twisted moiré multilayers of graphene

moiré-reconstructed TBG bands **almost perfectly flat** near “magic” twist angle  $\theta \sim 1.05^\circ$



\*8 electron “flavors” - 2 spin  $\times$  2 “valley”  $\times$  2 “sublattice”

[Bistritzer & Macdonald, PNAS'11]



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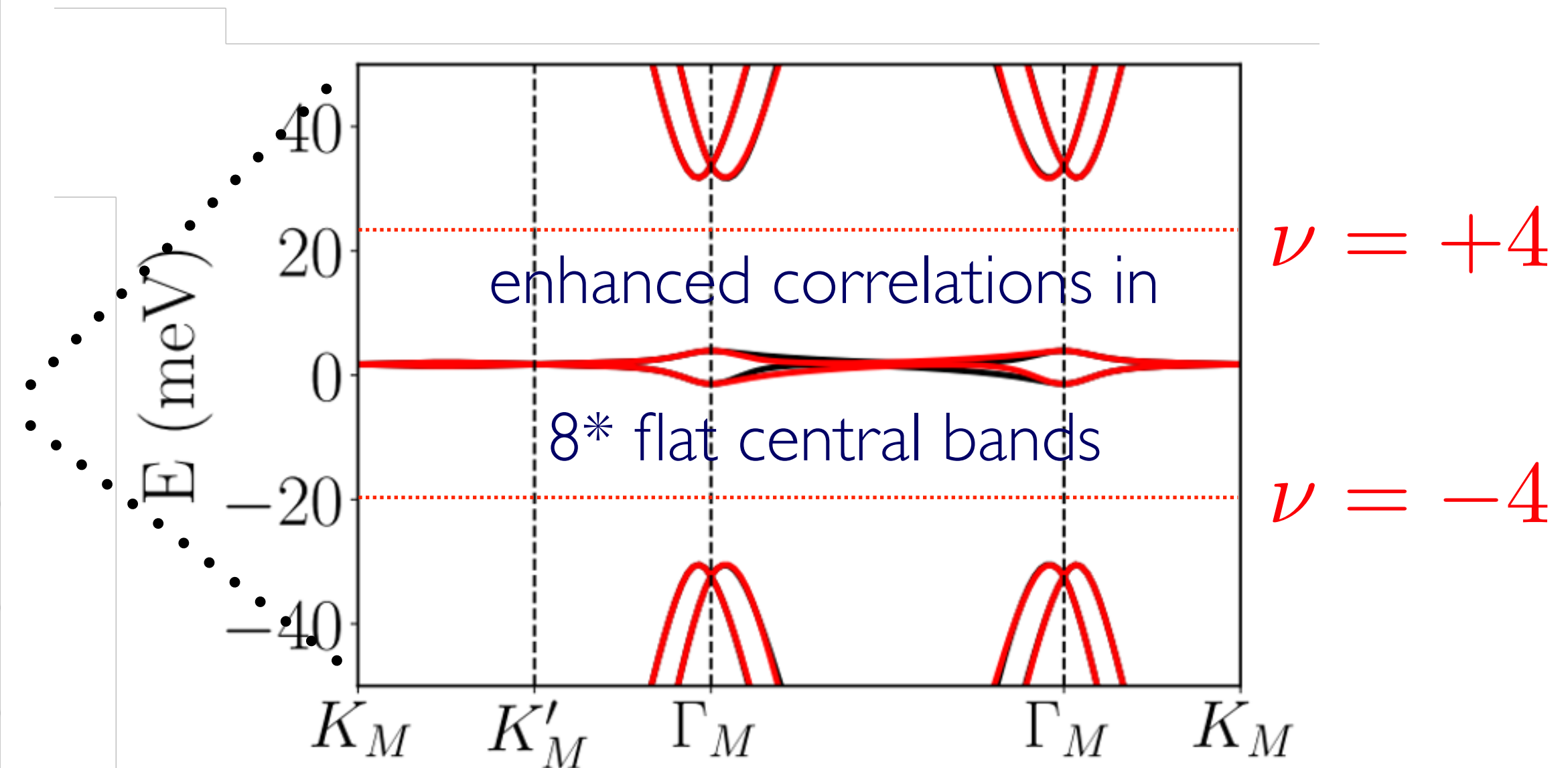
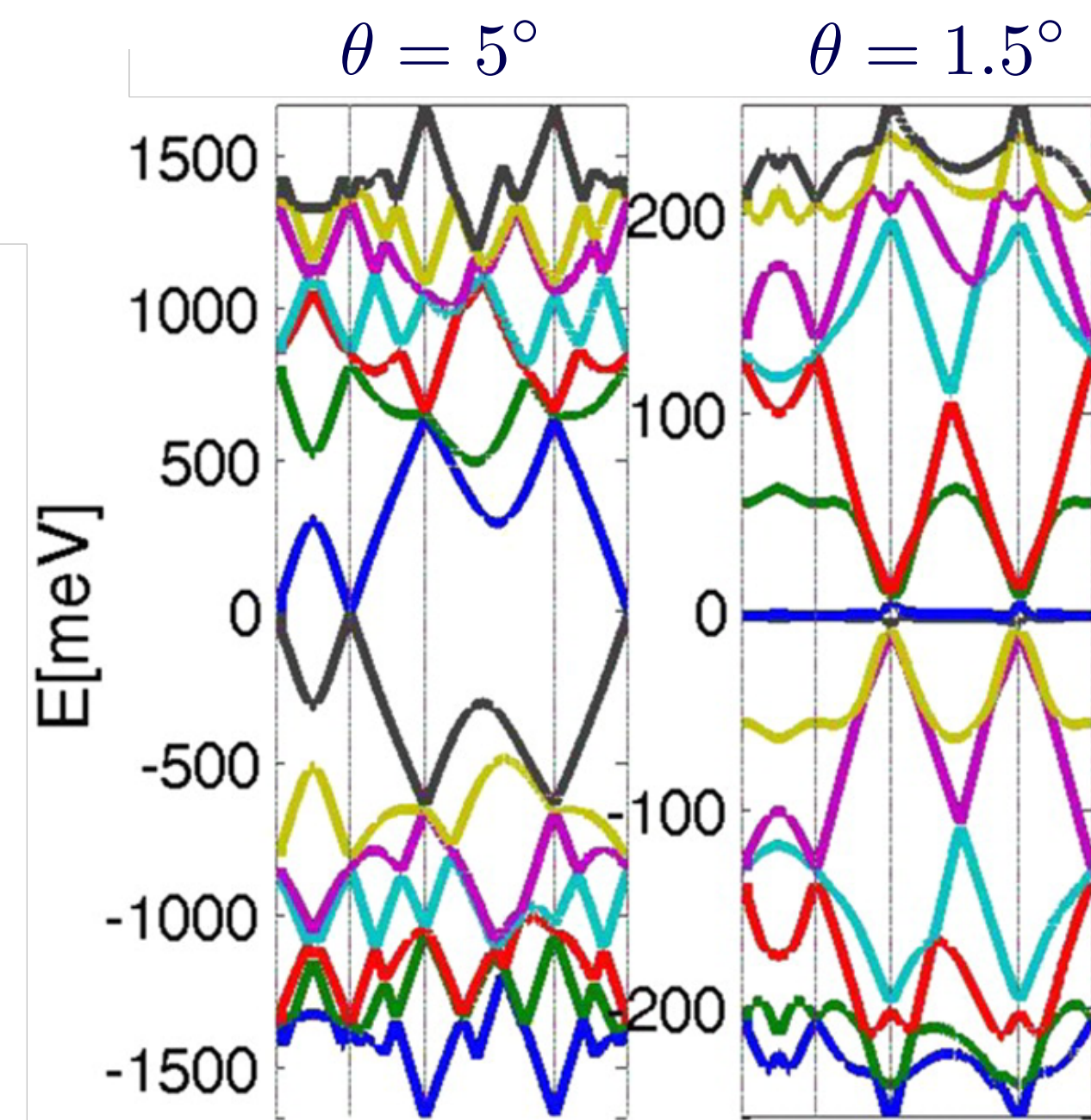
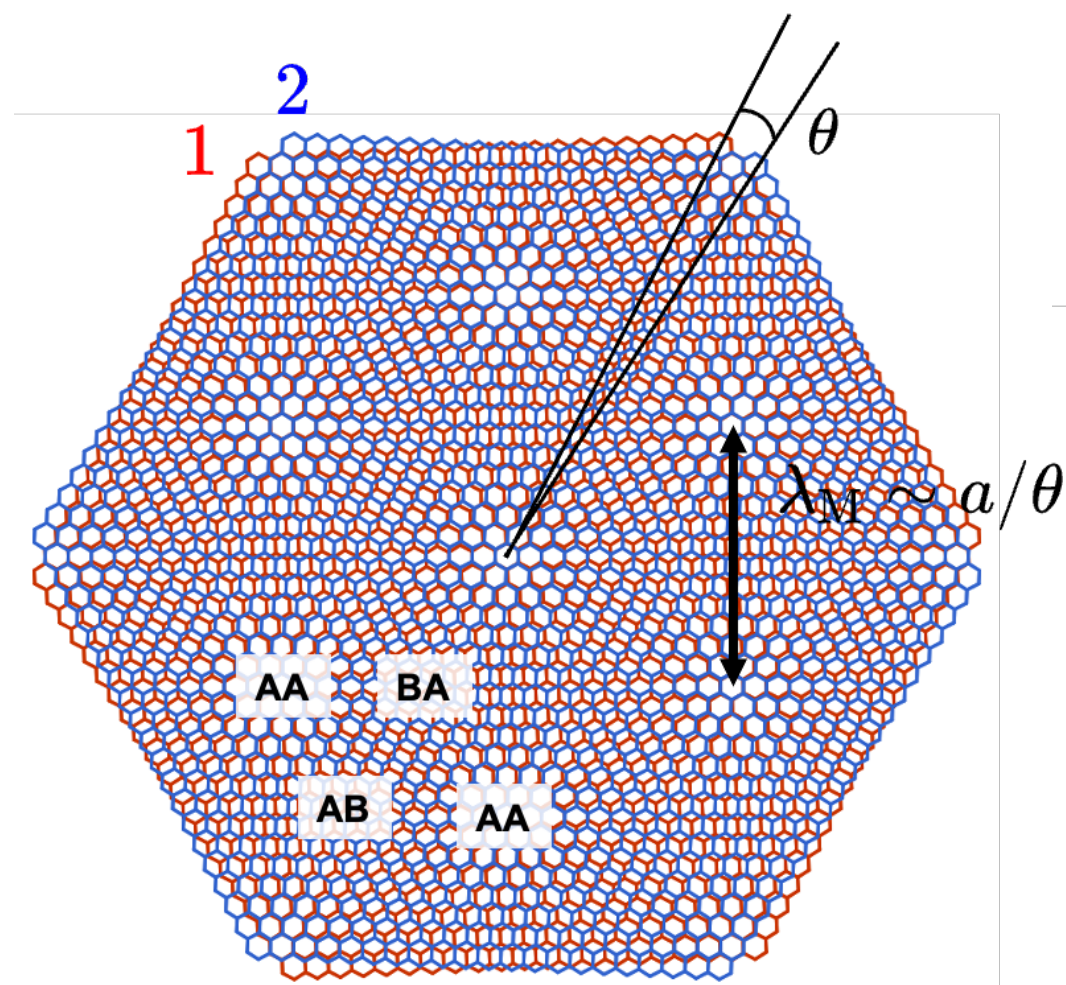
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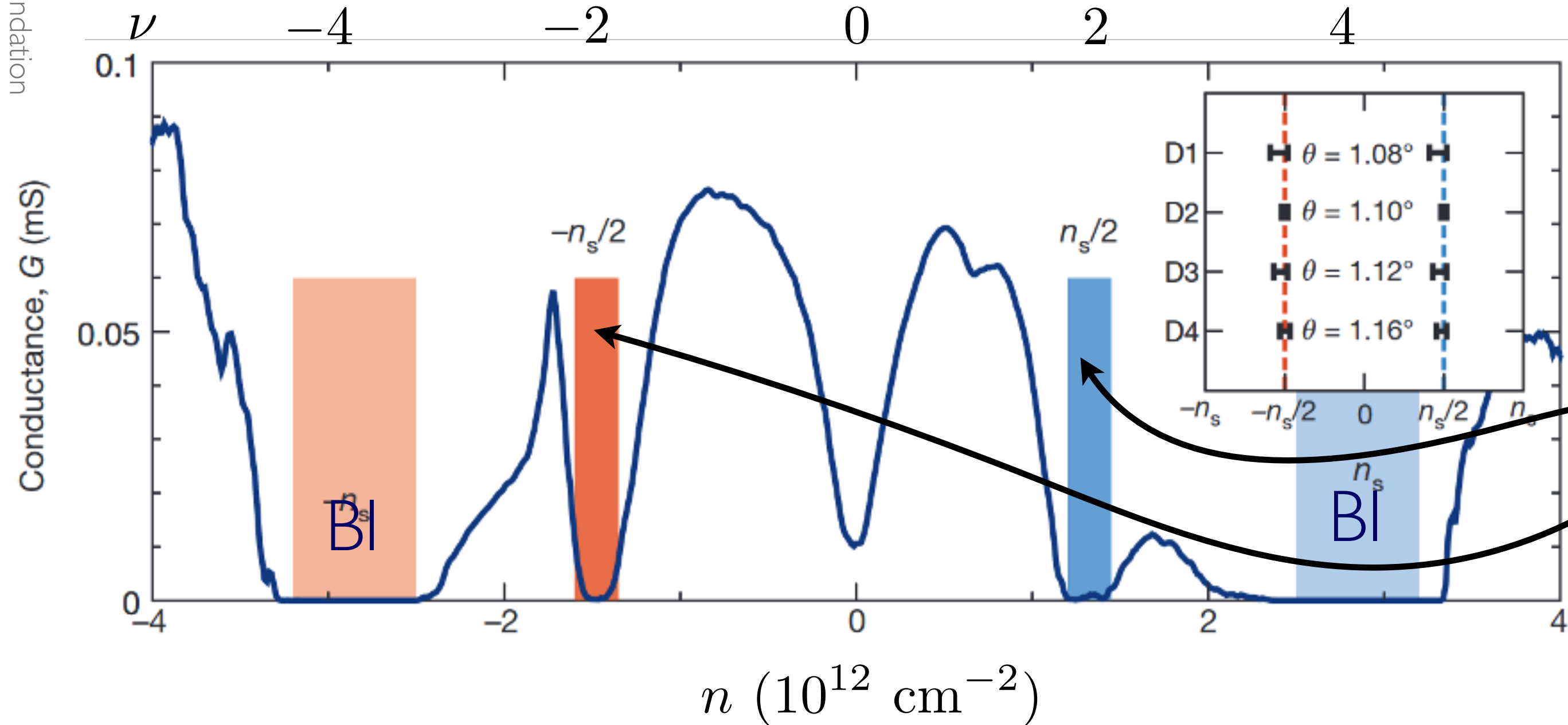
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Pablo Jarillo-Hererro (MIT): experiments on magic-angle graphene bilayers

[Cao *et al* Nature '18a,b]



“correlated insulators”  
(band theory predicts metal)

Many proposed explanations:  
**correct one:** SP, SH Simon + Oxford  
students/postdocs (2021)  
[experimental confirmation in 2023!]



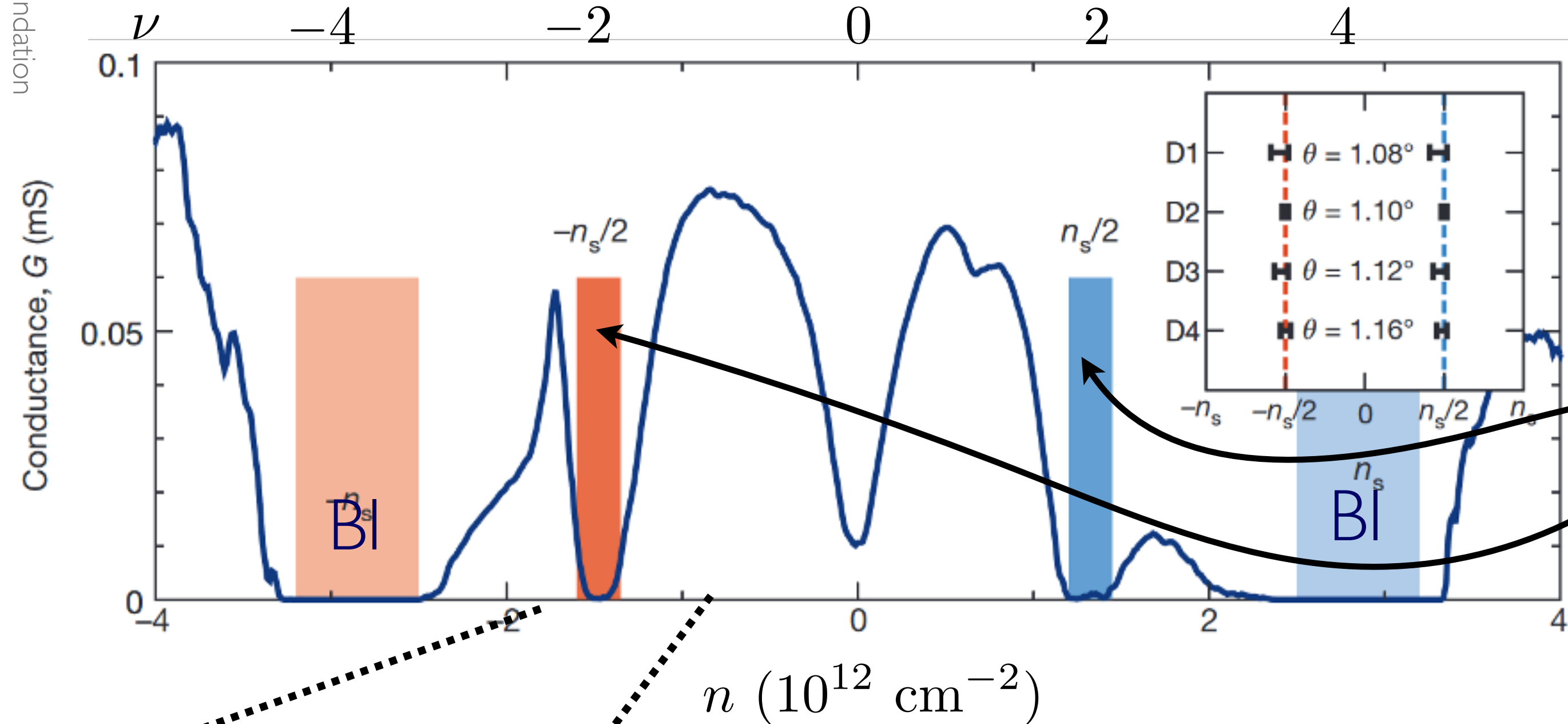
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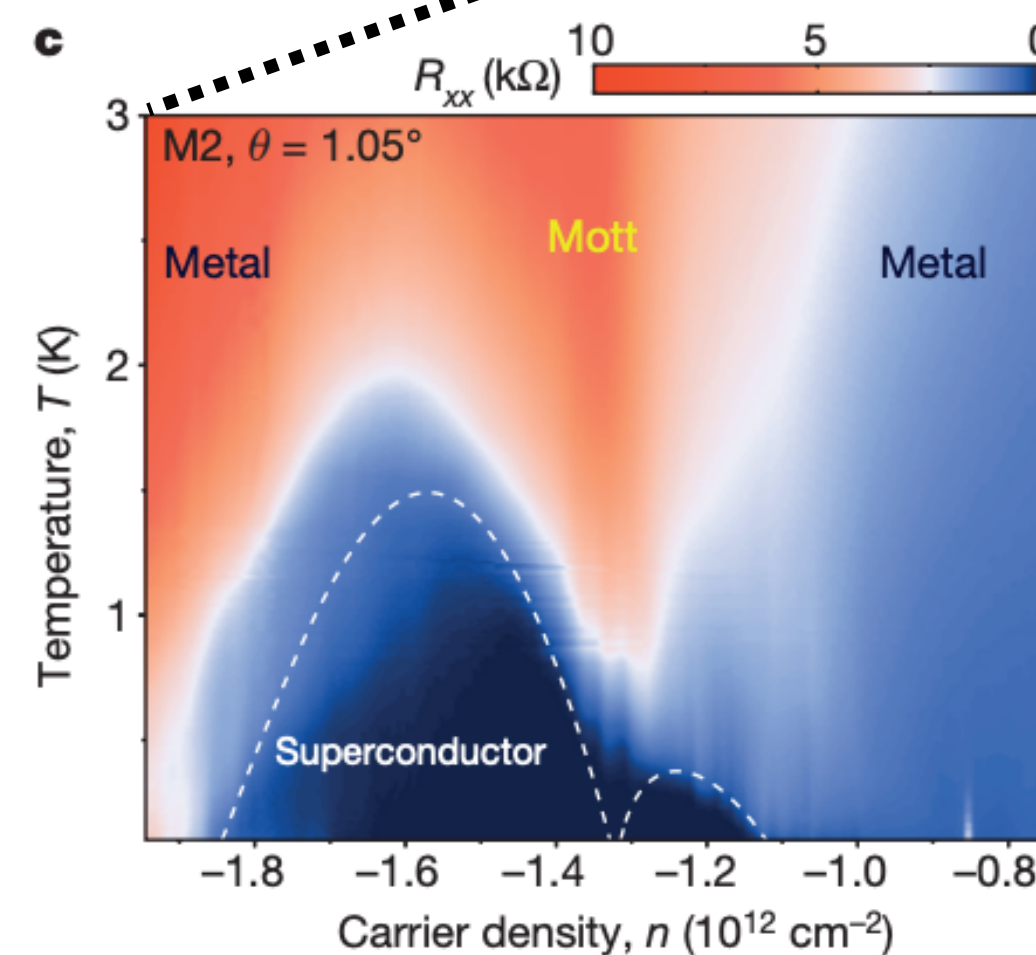
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gate-tunable  
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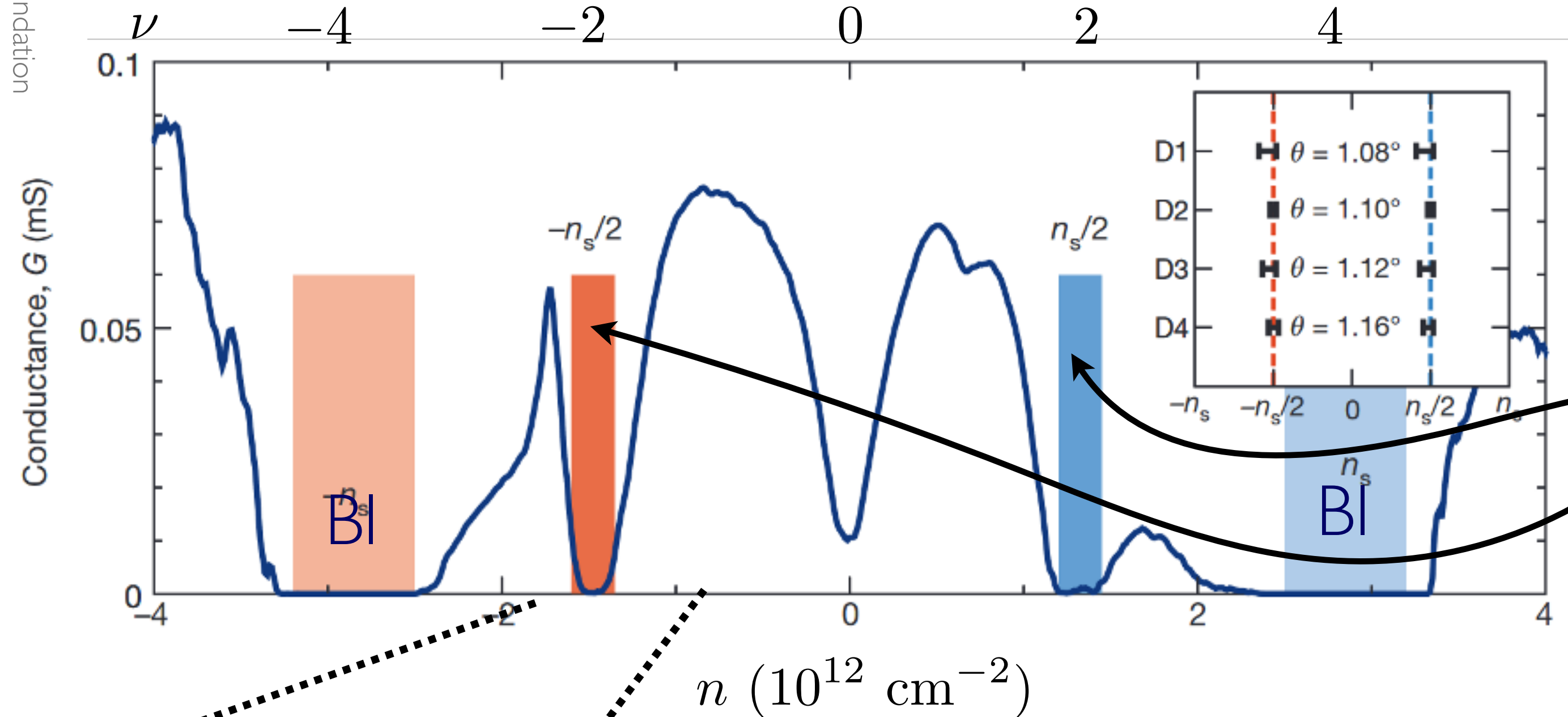


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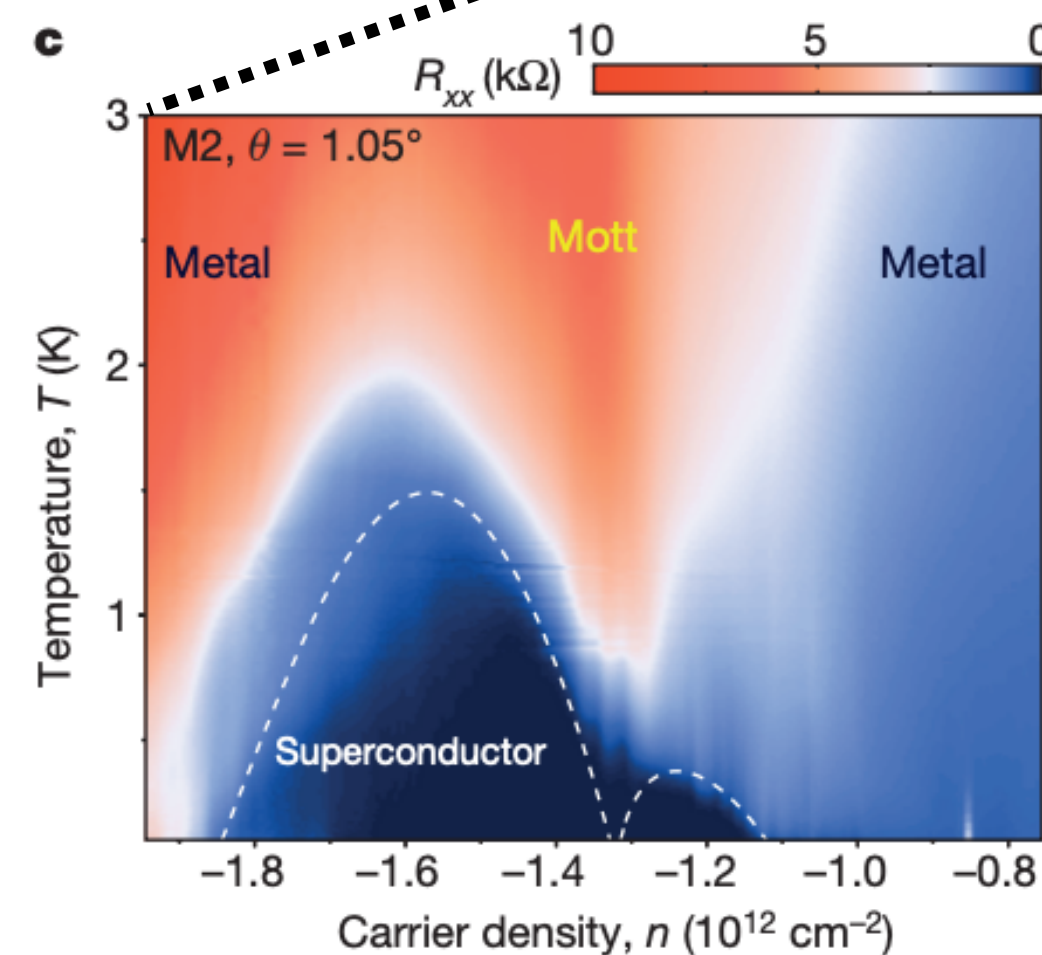
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gate-tunable  
superconductivity

**Wide range of other phenomena:**  
including some hints of topology...  
but difficult to get topological states reliably



Wolf Foundation

So we found a nice system with correlations and tunability...

but only tantalizing hints of topology

Can we do better?

# Other Moiré Materials

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There are lots of 2D materials!



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There are lots of 2D materials!

Like graphene, can often be prepared by “exfoliation”  
a.k.a. “the scotchtape method”



[lostinscience.wordpress.com/](http://lostinscience.wordpress.com/)



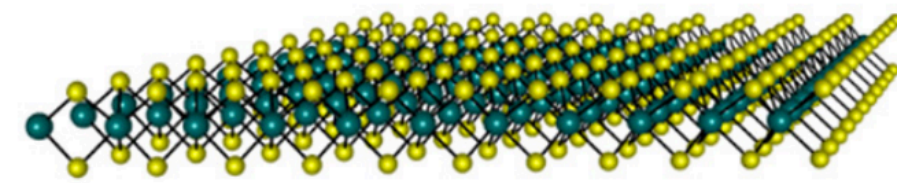
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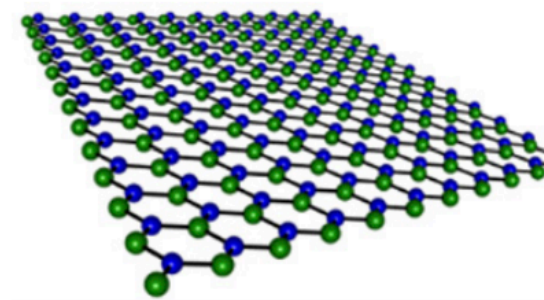
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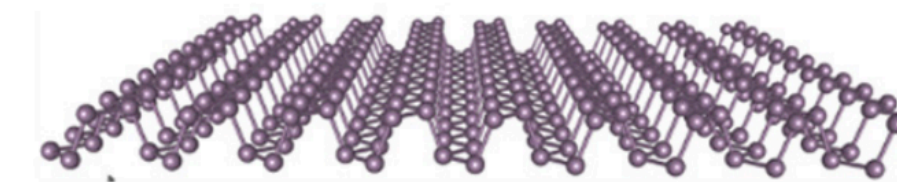
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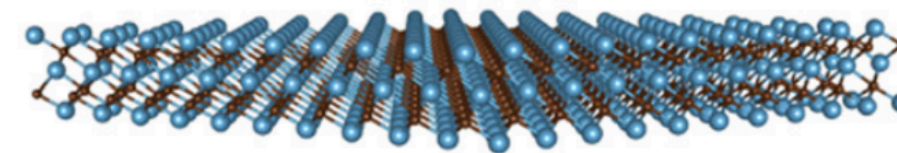
Transition Metal Dichalcogenides, TMDs  
( $\text{MoS}_2$ ,  $\text{WS}_2$ ,  $\text{MoTe}_2$ ,  $\text{HfS}_2$ ...)



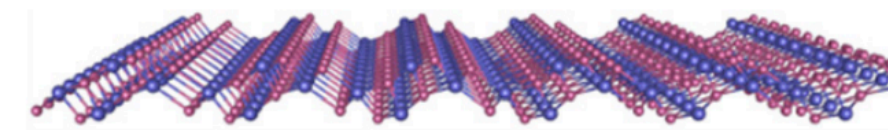
hBN



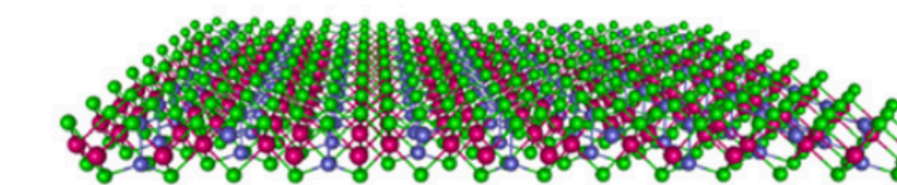
Black Phosphorous



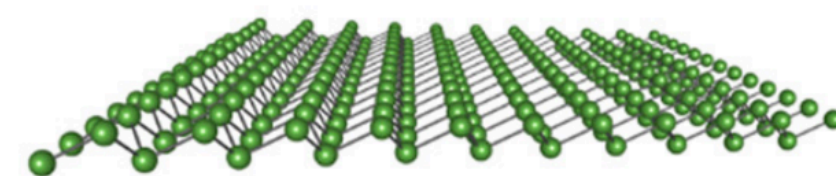
MXene



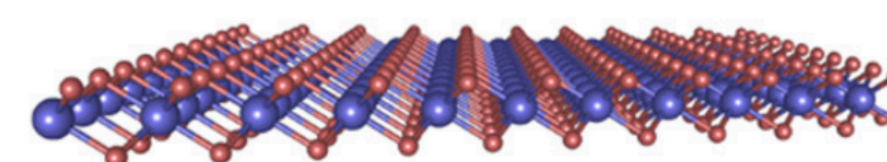
Post-Transition Metal Chalcogenides, PTMCs  
( $\text{In}_2\text{Se}_3$ ,  $\text{Sb}_2\text{S}_3$ ,  $\text{Sb}_2\text{Te}_3$ ,  $\text{Bi}_2\text{Te}_3$ ,  $\text{Bi}_2\text{Se}_3$ ...)



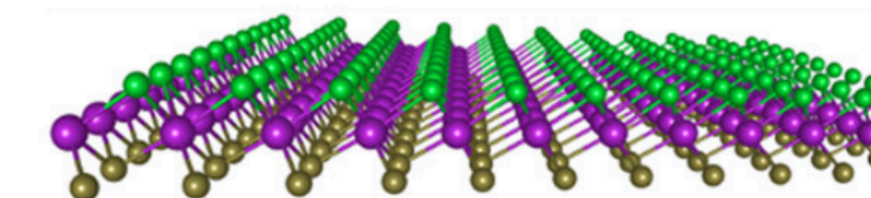
Metal Phosphorous Trichalcogenides, MPTs  
( $\text{NiPS}_3$ ,  $\text{FePS}_3$ ...)



2D Monoelemental materials  
(As, Te, Bi, Ge, Sb...)



2D  $\text{MnO}_2$



Bismuth tellurohalides,  $\text{BiTeX}$   
( $\text{BiTeI}$ ...)

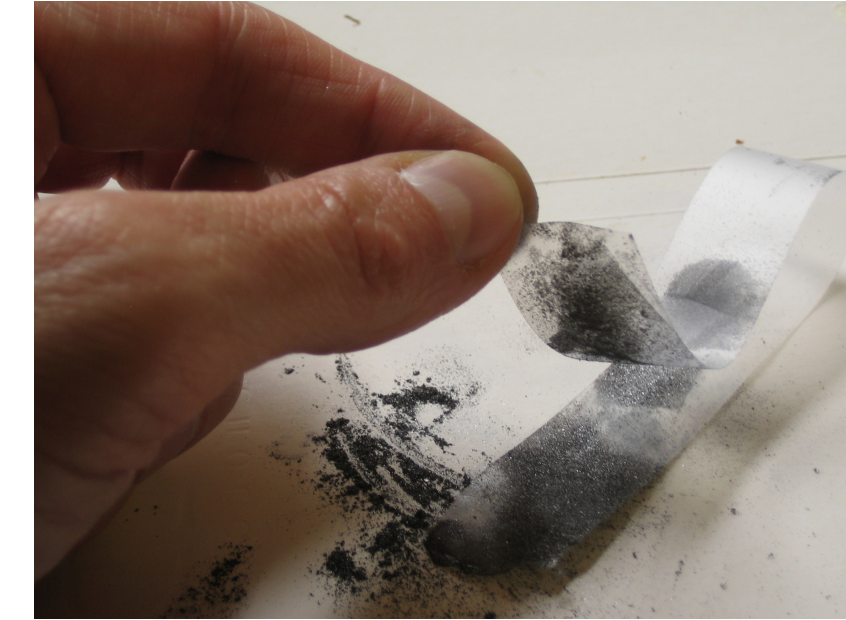
[Zhao *et al* Chem. Soc. Rev. '24]



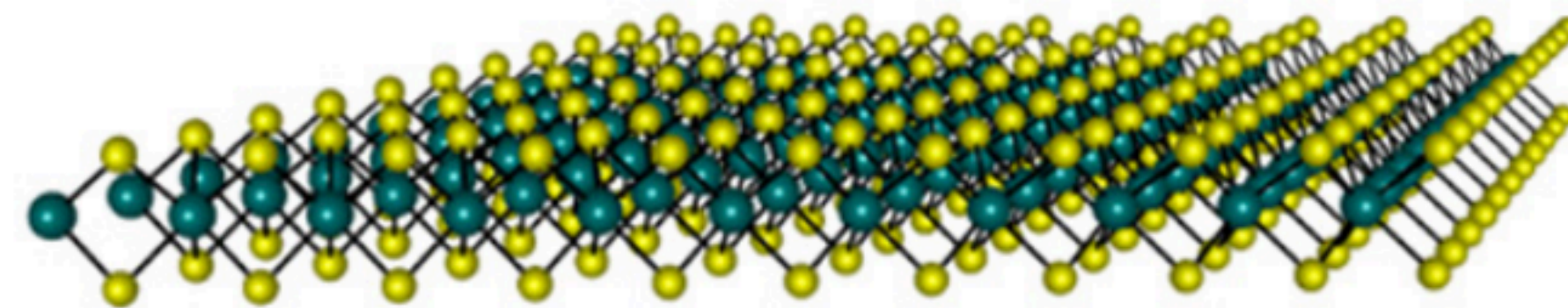
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There are lots of 2D materials!

Like graphene, can often be prepared by “exfoliation”  
a.k.a. “the scotchtape method”



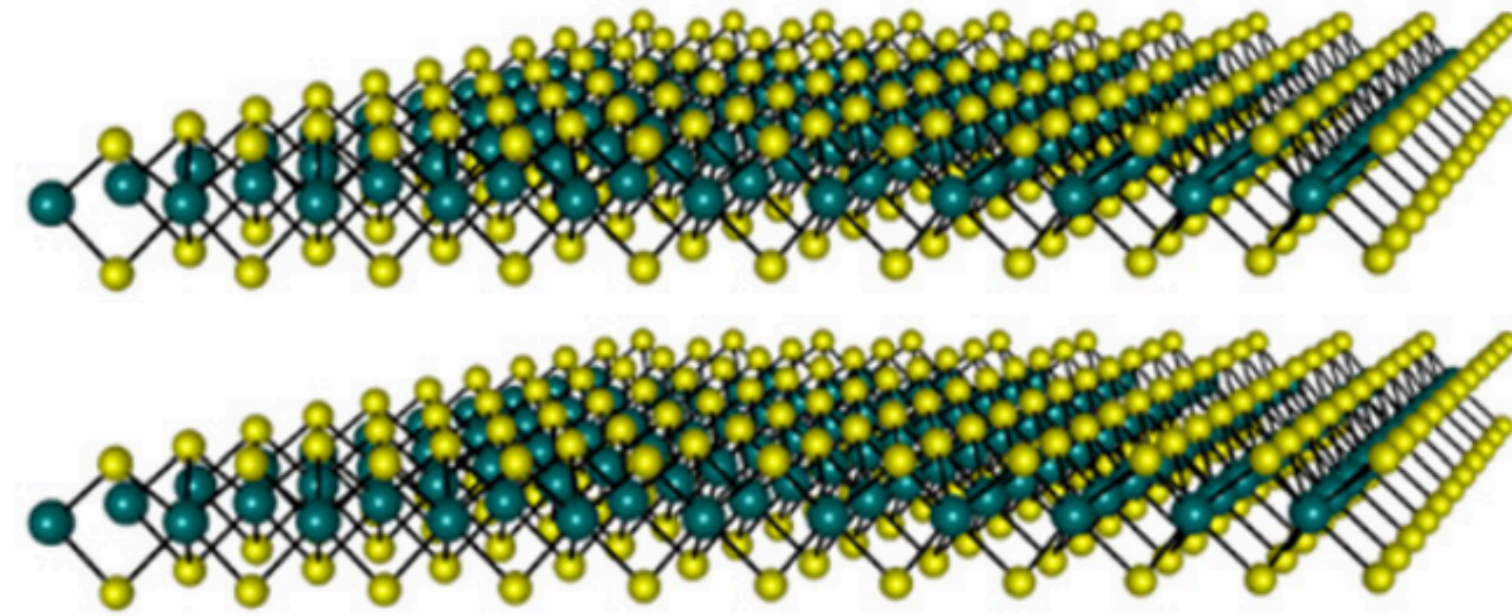
[lostinscience.wordpress.com/](http://lostinscience.wordpress.com/)



Transition Metal Dichalcogenides, TMDs  
( $\text{MoS}_2$ ,  $\text{WS}_2$ ,  $\text{MoTe}_2$ ,  $\text{HfS}_2$ ...)

Focus on one family in particular:  
“twisted TMDs”

# Topology in Twisted TMD Bilayers



= Transition Metal (Mo, W, Hf,...)



= Chalcogen (S, Se, Te,...)

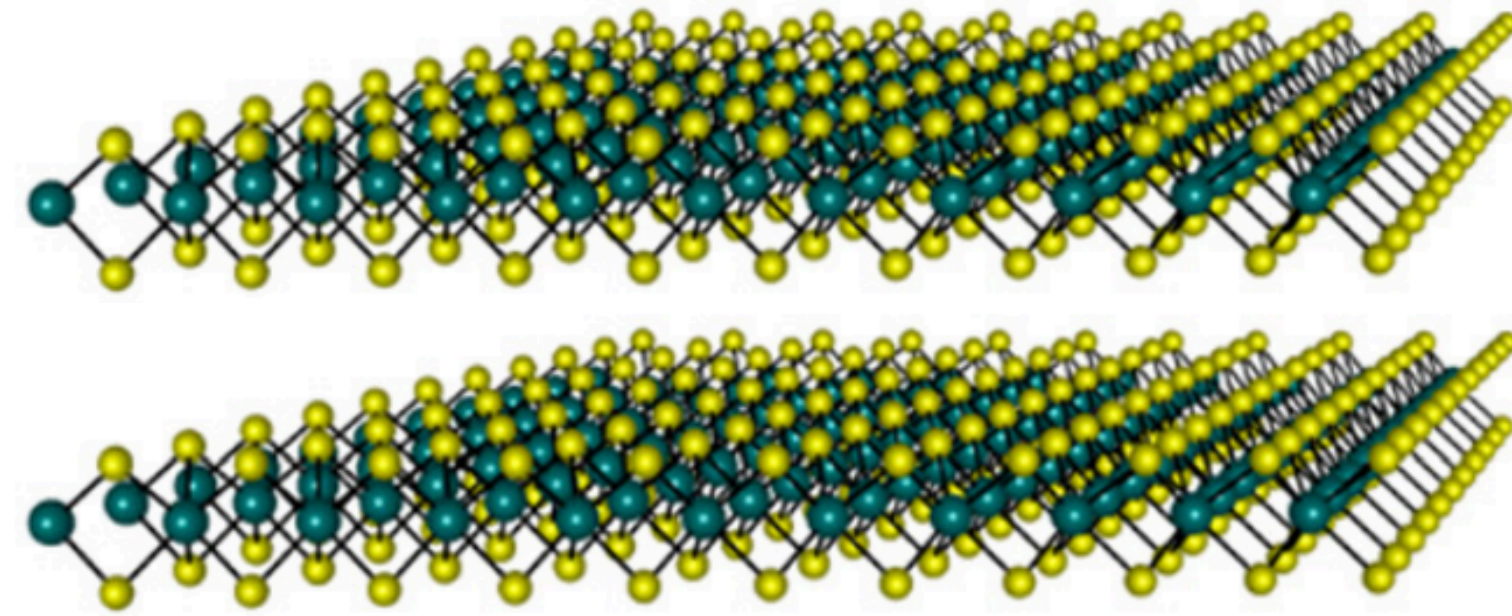
Parabolic dispersion per layer + complex interlayer tunneling amplitude/layer potential  $\Delta(\mathbf{r})$

$$H = \frac{\hbar^2 \mathbf{k}^2}{2m^*} + \Delta(\mathbf{r}) \cdot \boldsymbol{\sigma} \quad \text{where } \boldsymbol{\sigma} = \text{layer "pseudospin"}$$

[Wu et al '19; Pan et al '20; Devakul et al '21; Morales-Duran et al '24]



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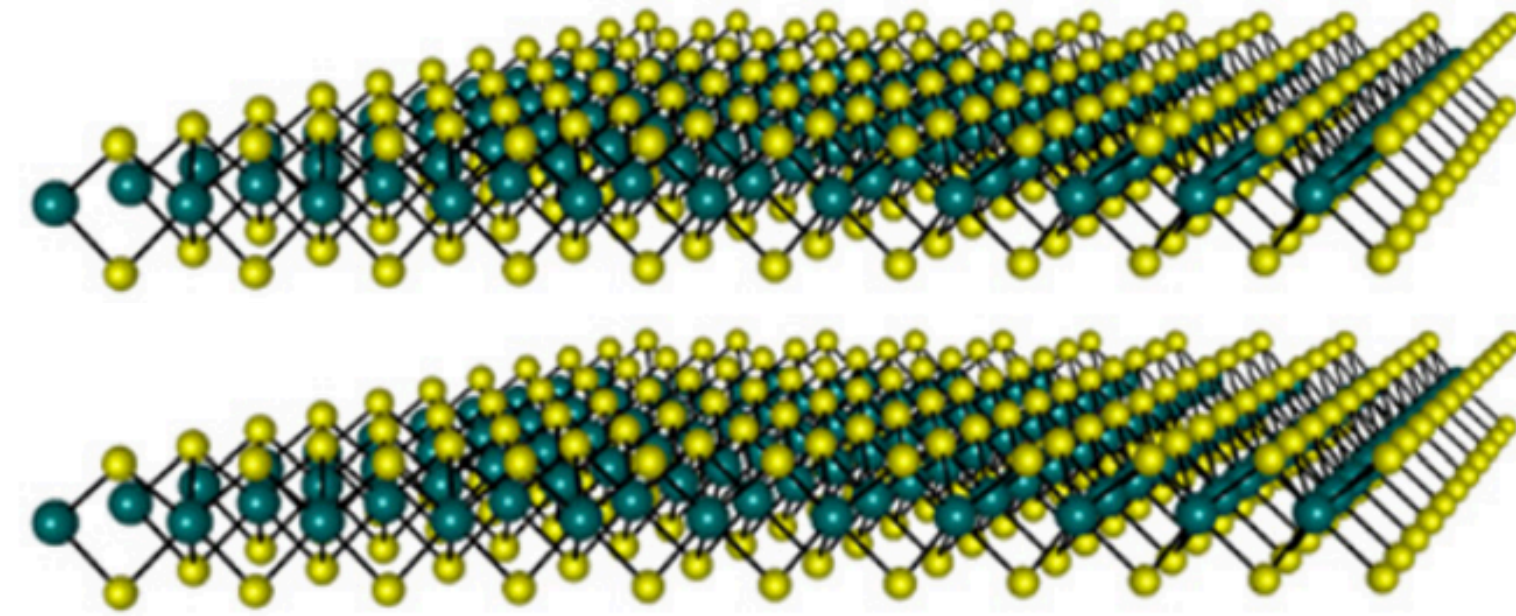
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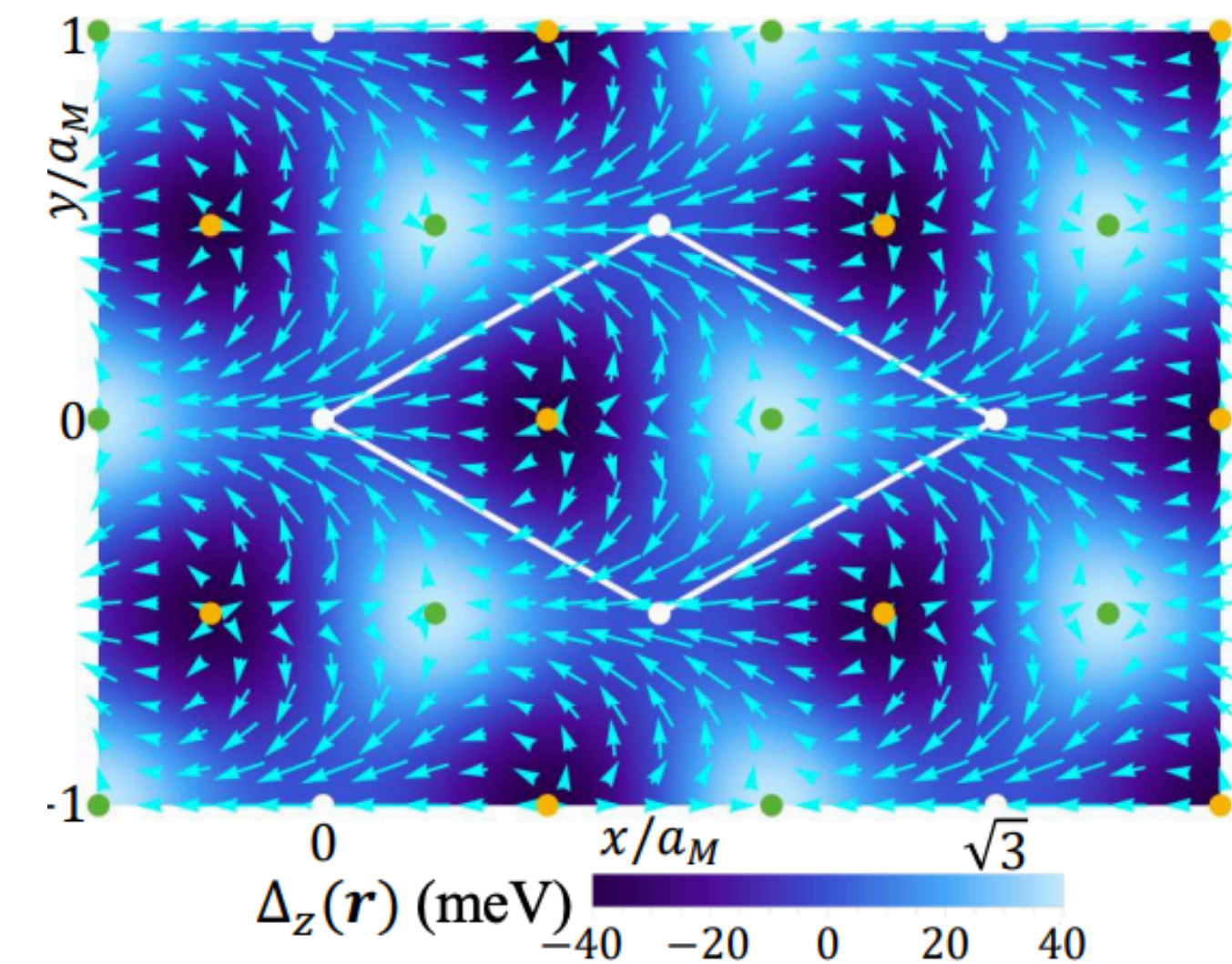
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Near special "magic" angles  $\Delta(\mathbf{r})$  forms a "skyrmion lattice"

What are the consequences for electrons?



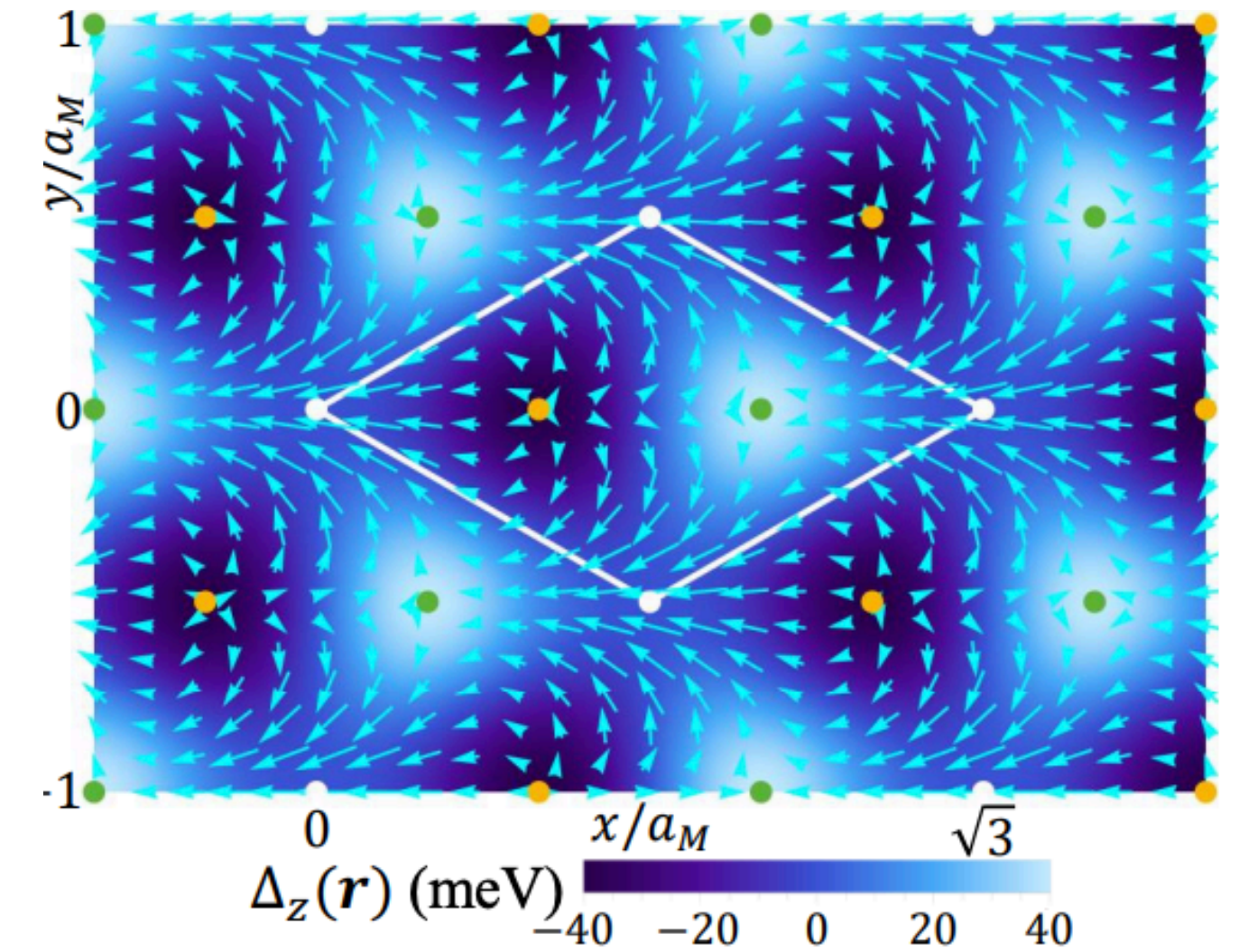
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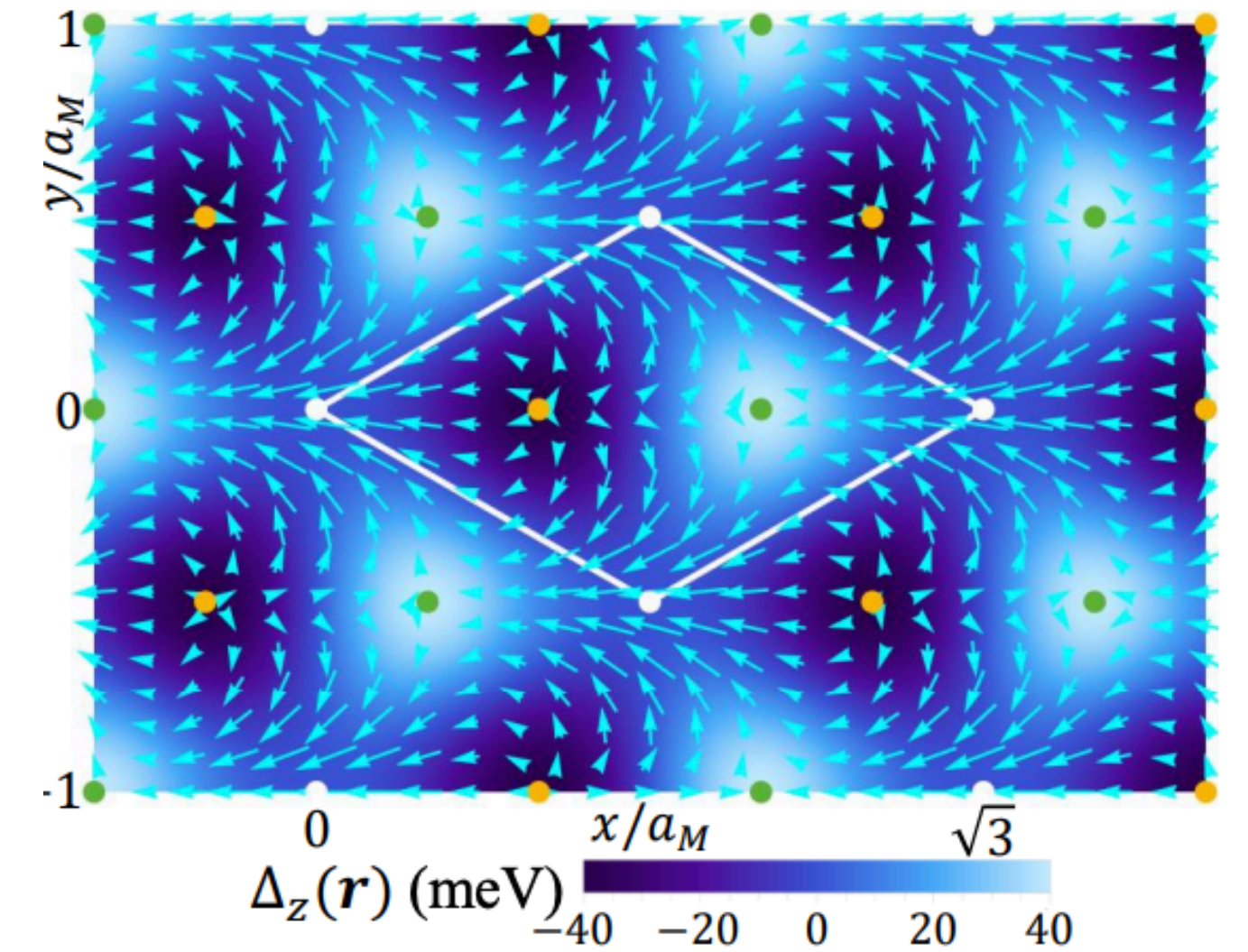
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Change the local axes so  $\boldsymbol{\sigma} \parallel \Delta(\mathbf{r})$

$$H \rightarrow H' = \frac{1}{2m^*} (\hbar \mathbf{k} + e\mathbf{A}(\mathbf{r}))^2 + V_{\text{eff}}(\mathbf{r})$$



[Wu et al '19; Pan et al '20; Devakul et al '21; Morales-Duran et al '24]



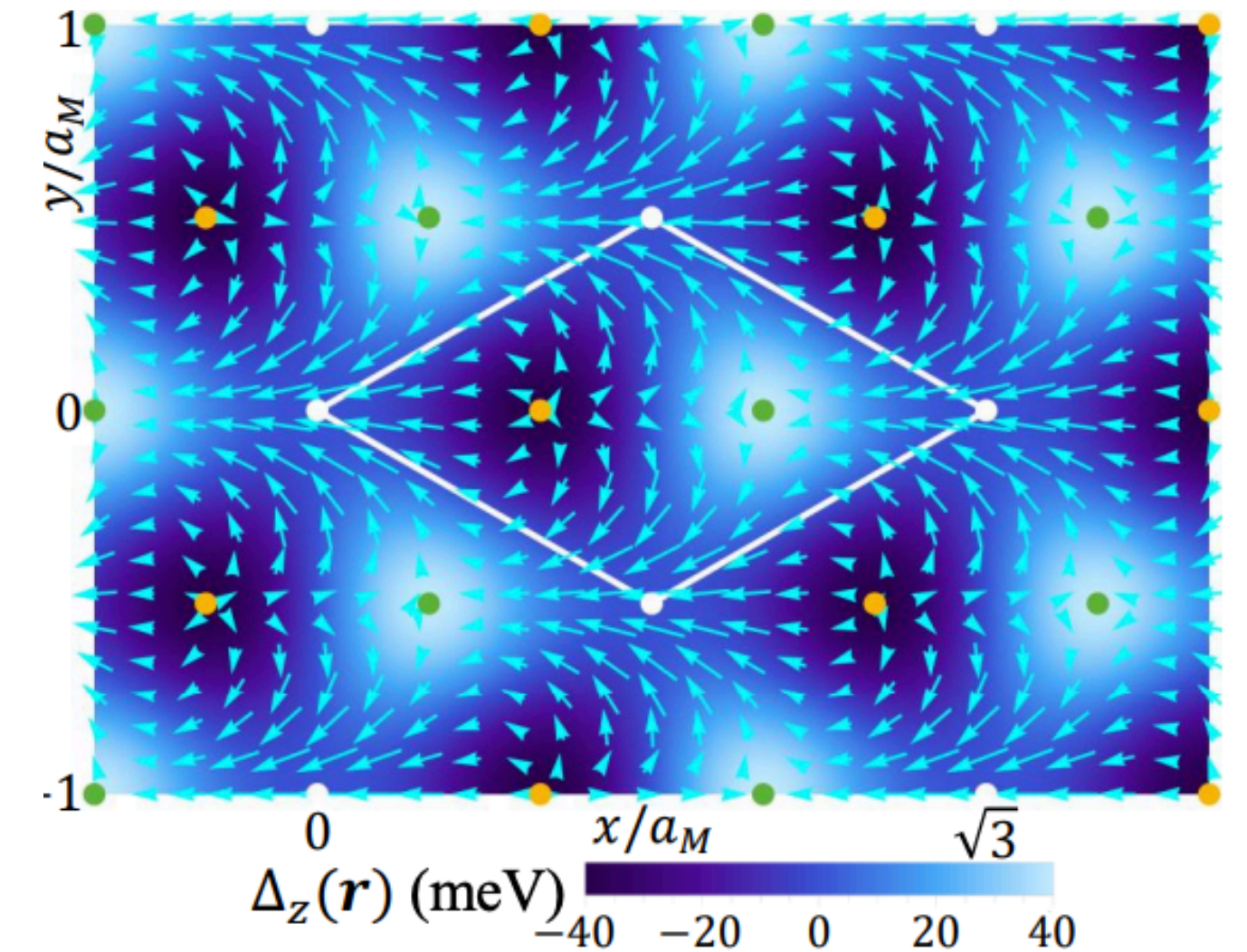
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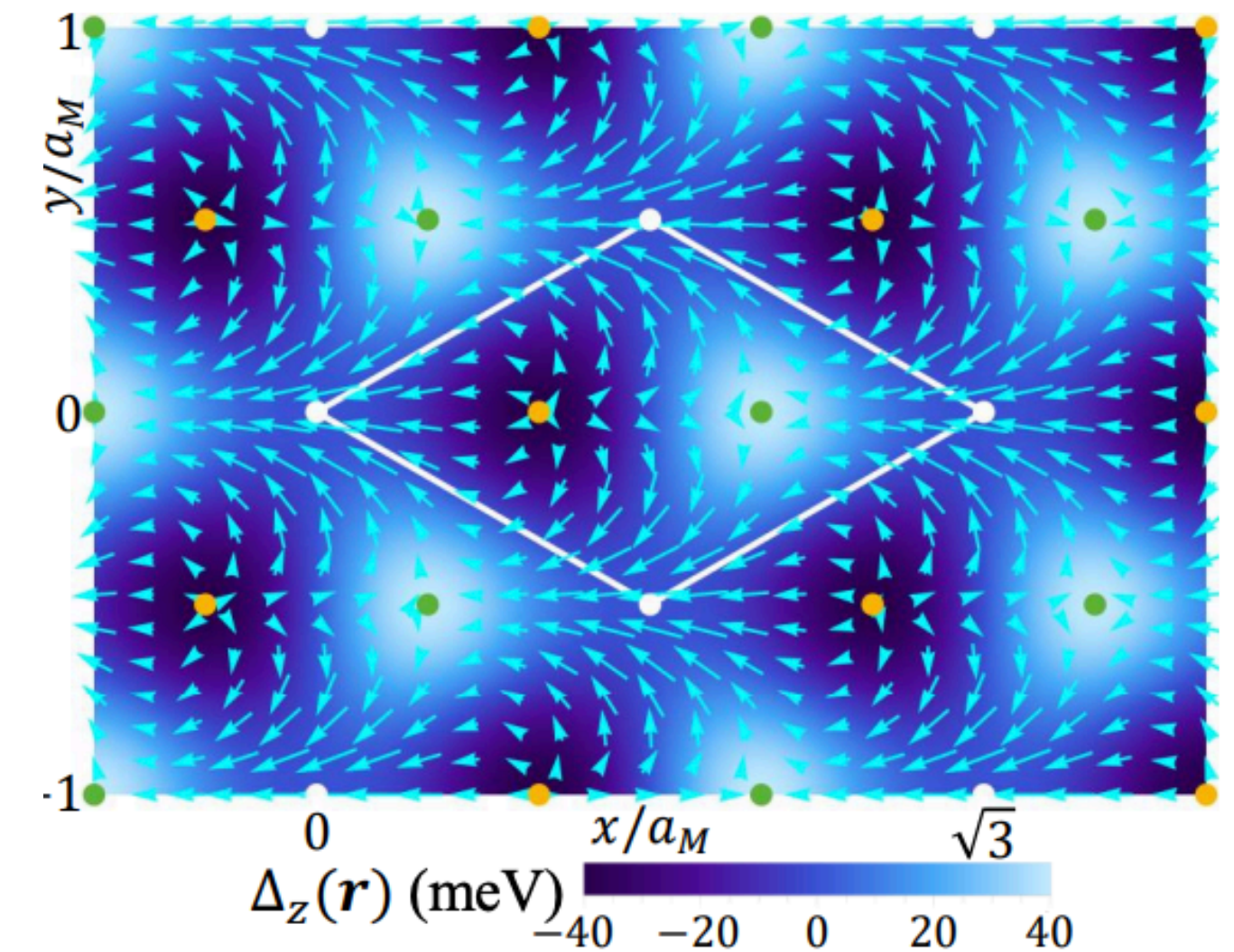
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If  $\Delta(\mathbf{r})$  has 1 skyrmion per unit cell,  $\mathbf{B}(\mathbf{r}) = \nabla \times \mathbf{A}(\mathbf{r})$  has 1 flux quantum per unit cell

**This gives a  $C = 1$  Chern band which is pretty flat!**  
( $\approx$  Landau level in weak periodic potential!)



[Wu et al '19; Pan et al '20; Devakul et al '21; Morales-Duran et al '24]

# Checking off our Wishlist

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**The system:** bilayers of MoTe<sub>2</sub> twisted to  $\theta \approx 3.7^\circ \approx 0.065$  rad



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**correlations**

- Lattice spacing  $a \sim 0.6$  nm  $\Rightarrow$  moiré length  $a_M \sim 10$  nm



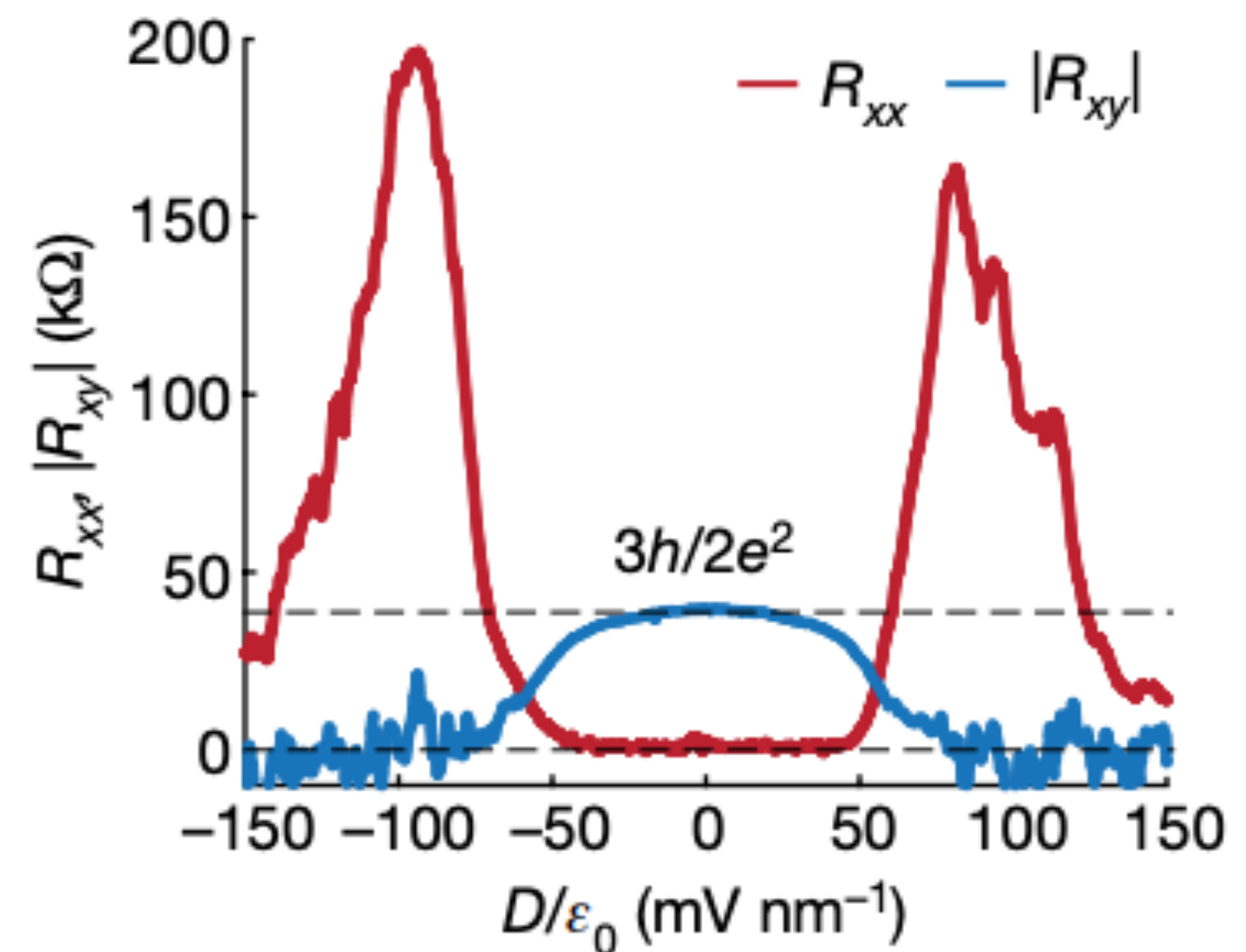
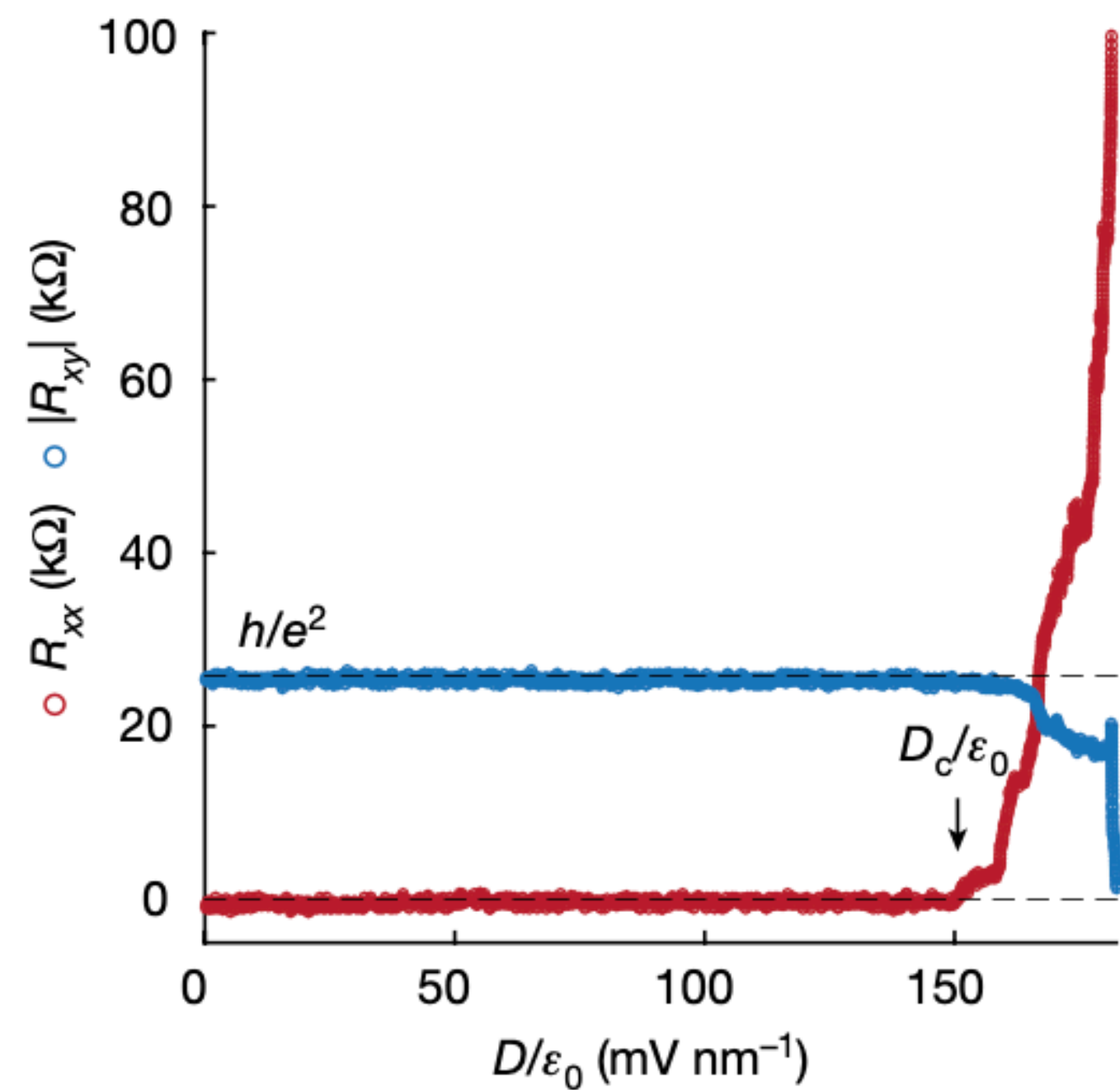
**tunability**

Bonus: interlayer potential ( $D \sim \Delta_z$ ) tunes skyrmion number  
(can use it to switch from  $C = 1$  to  $C = 0$  as a test)



# Experiments!

Transport experiments\* on tMoTe<sub>2</sub> at the appropriate densities shows quantization of the Hall response at integer and fractional values, switchable by tuning the interlayer potential!



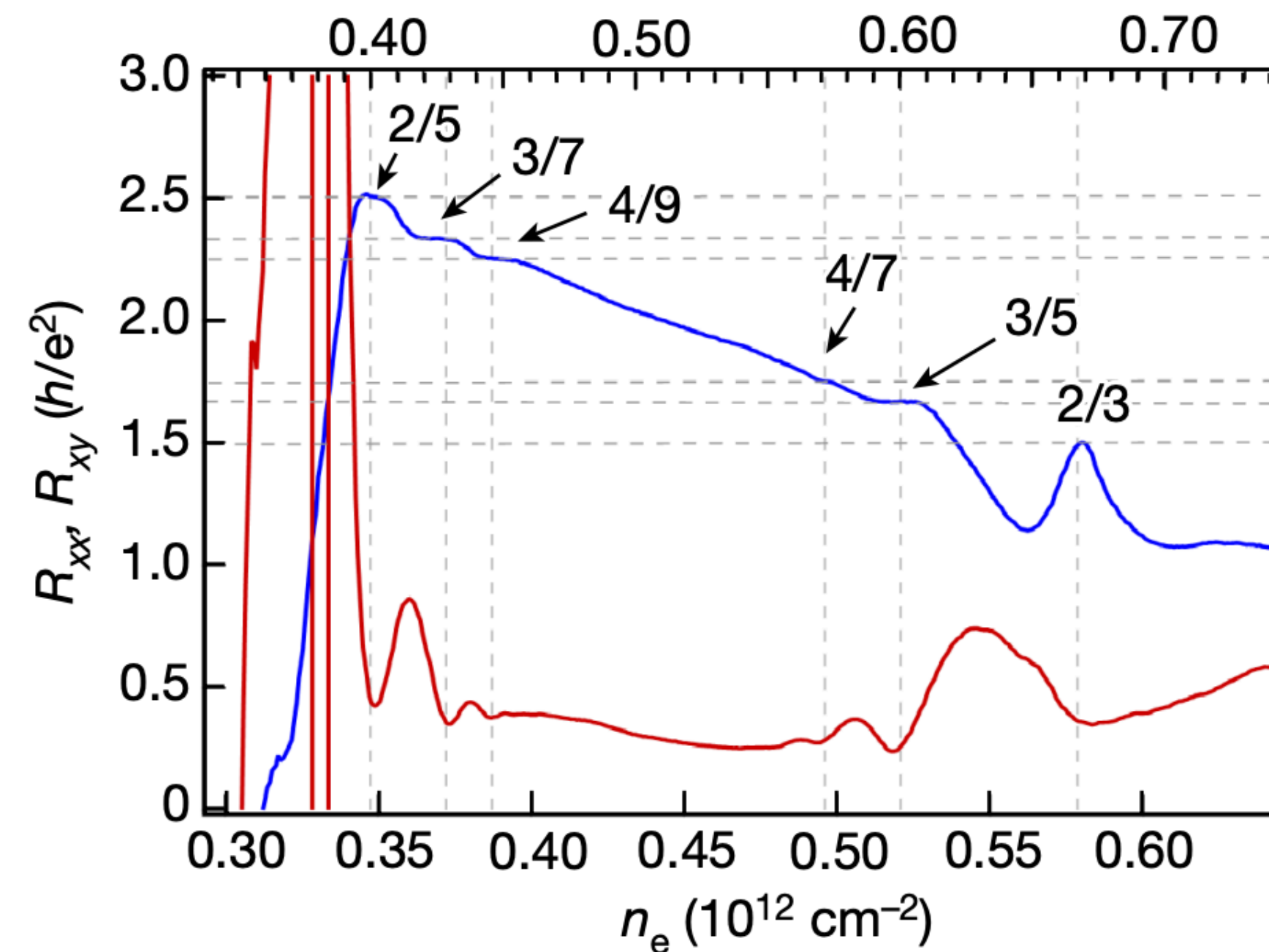
Active search for “fractional topological insulators”, non-Abelian anyons, ...

\*first experiments were indirect and involved optics — more in a moment

[Park et al Nature '23]

# New Surprises!

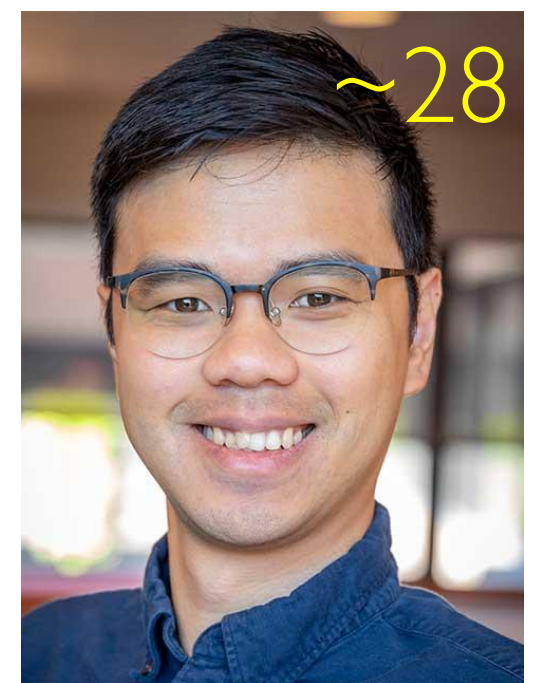
rhombohedral 5-layer graphene on hBN — second FCI system, a few months after tMoTe<sub>2</sub>



[Lu et al Nature '24 ]

- Rich physics but poorly understood
- Moiré effect is much weaker and seems to have a different role — stabilizing a state where interactions make electrons *spontaneously* crystallize into a Chern insulator, rather than simply filling existing Chern bands!

**Key Player:** Yves Kwan  
(Oxford DPhil '22 → Princeton Postdoc)



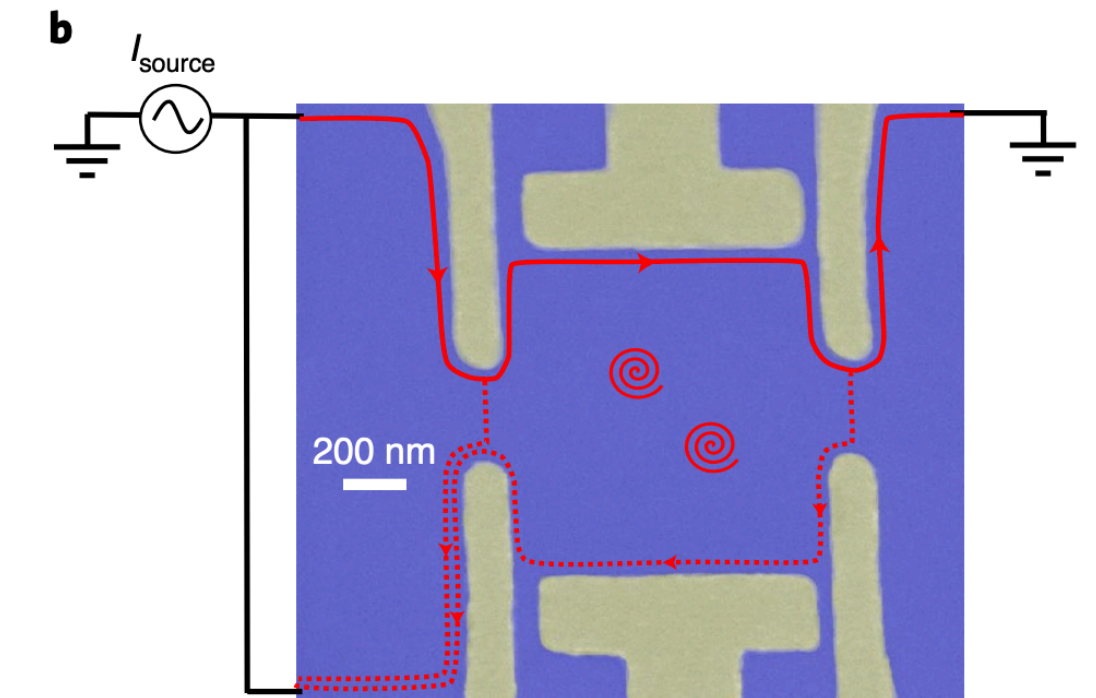
# The Future: “Seeing” Fractional Statistics?

Signature of FQHE: anyonic statistics  
(intermediate between bosons/fermions)

[Arovas et al PRL '84]

In Landau levels— “edge state interferometry” (cf Steve Simon’s talk)

[Proposal: Chamon, Sondhi, et al '97; Recent experiments: Nakamura et al Nat. Phys. '20] ▶





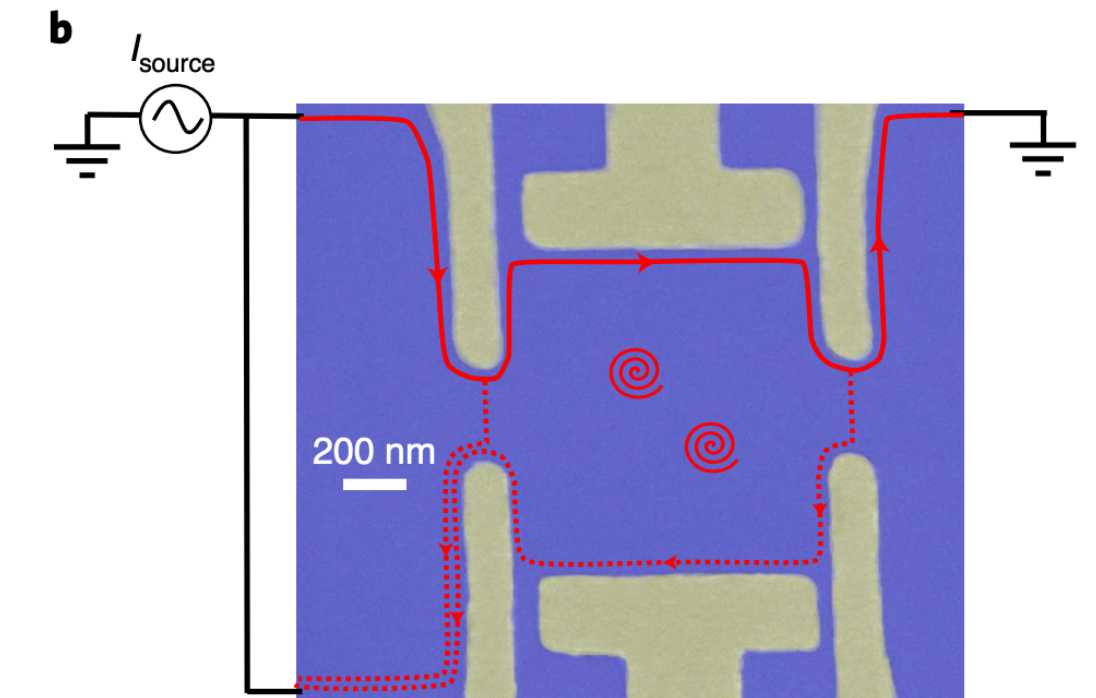
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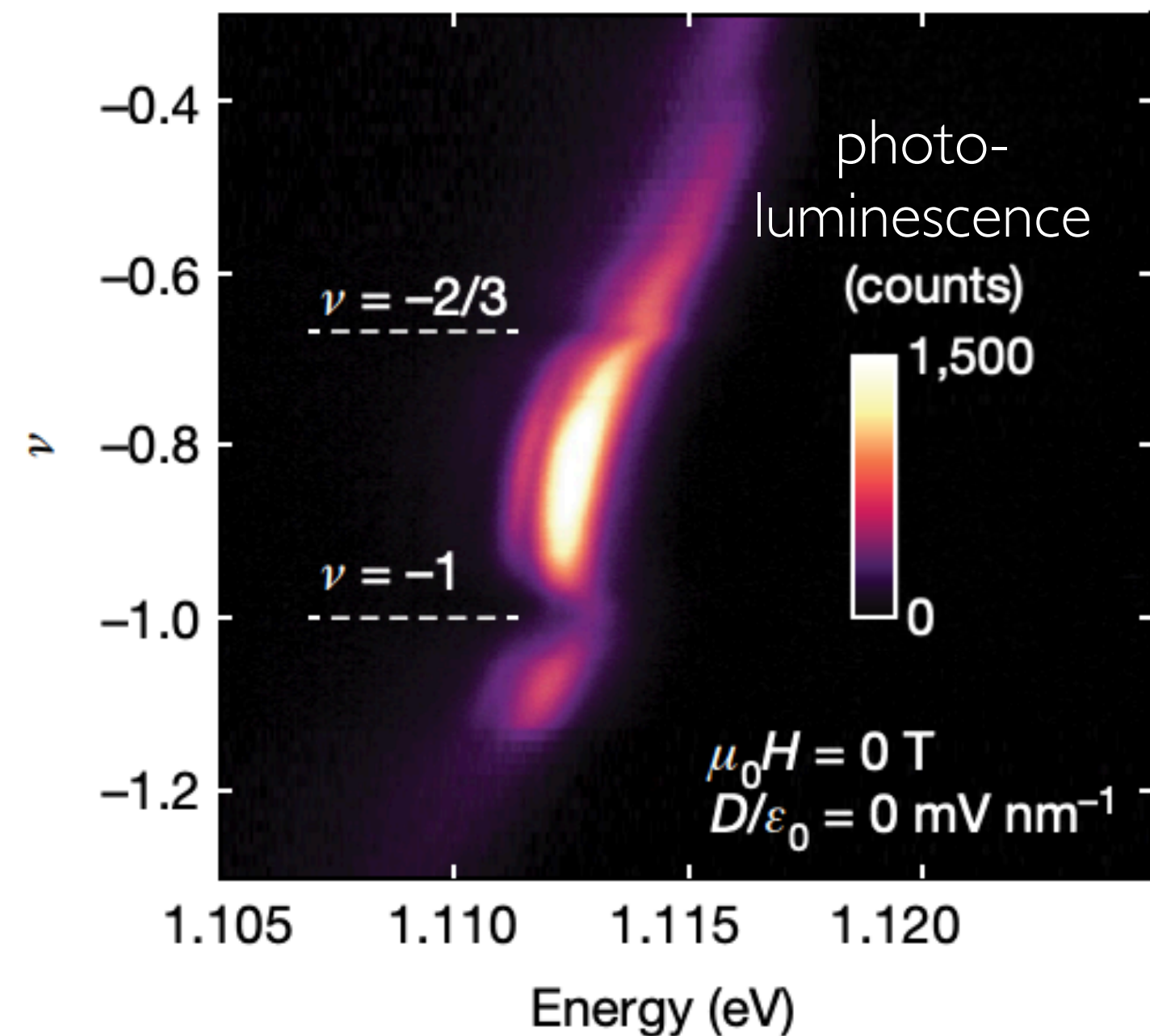
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How to detect statistics?



[Cai et al Nature '23]

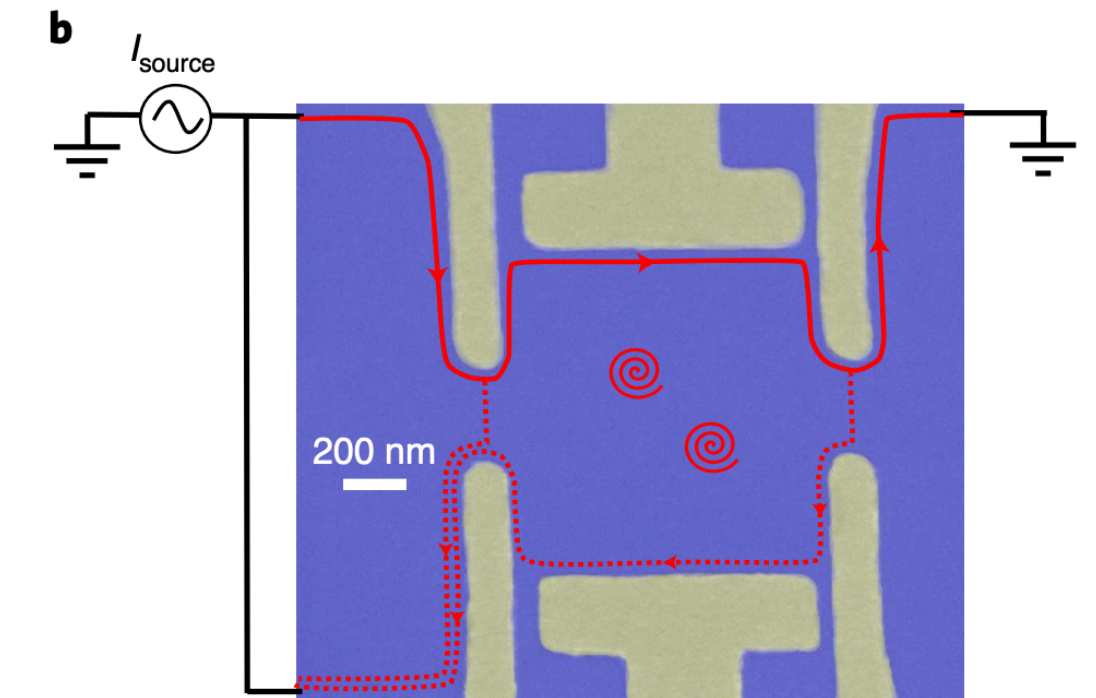
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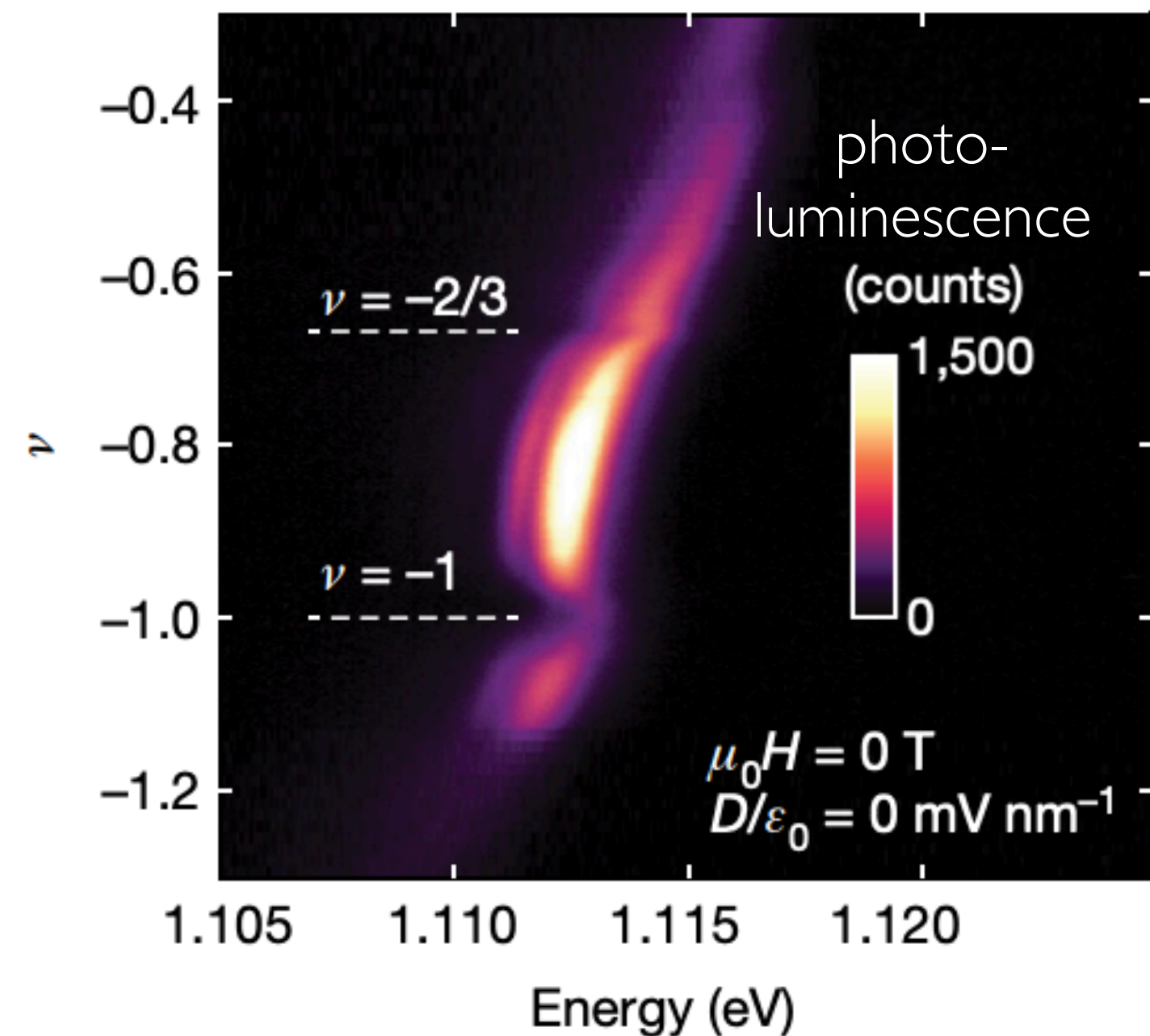
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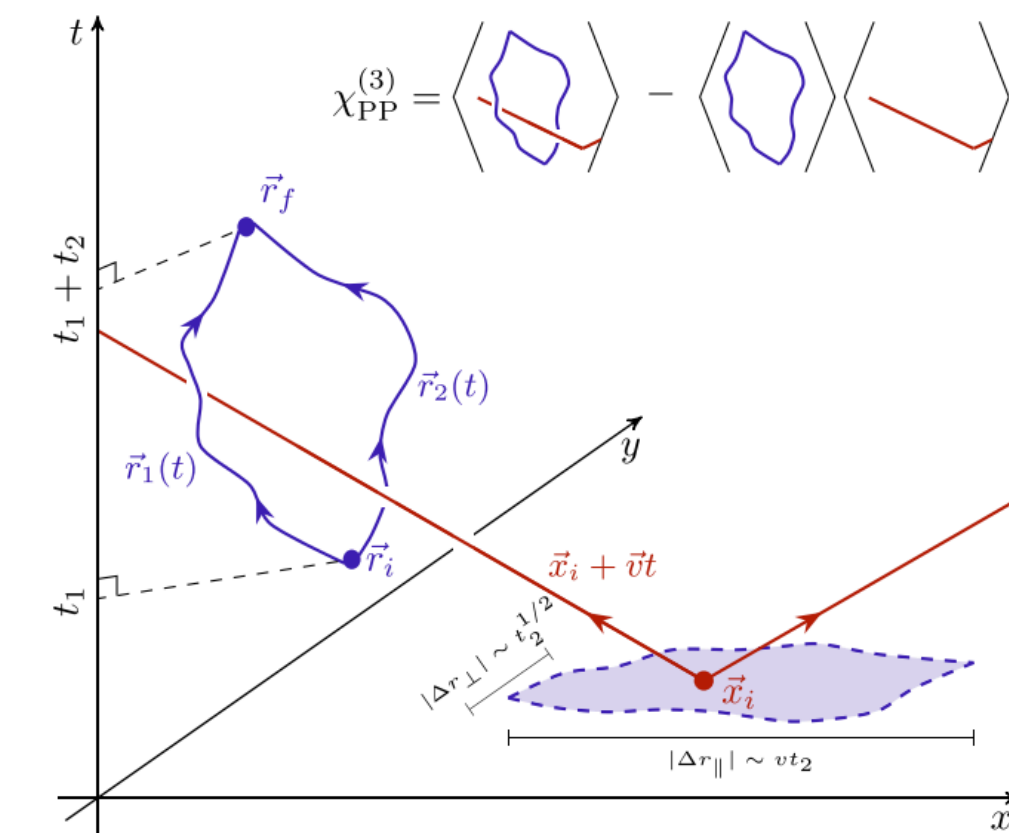
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**Idea:** use “pump-probe” spectroscopy?  
(nonlinear optical response)

“linking” of QP trajectories sensitive to statistics



[Cai et al Nature '23]



[McGinley-Fava-SP PRL+PRB '24]

... also applies to quantum spin liquids in magnets?

# Summary

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The “simple” expedient of twisting and stacking few-atom-thick 2D layers and leveraging the moiré effect achieves a confluence of 3 key routes to new physics

**topology**

**correlations**

**tunability**

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**Thanks for listening!**